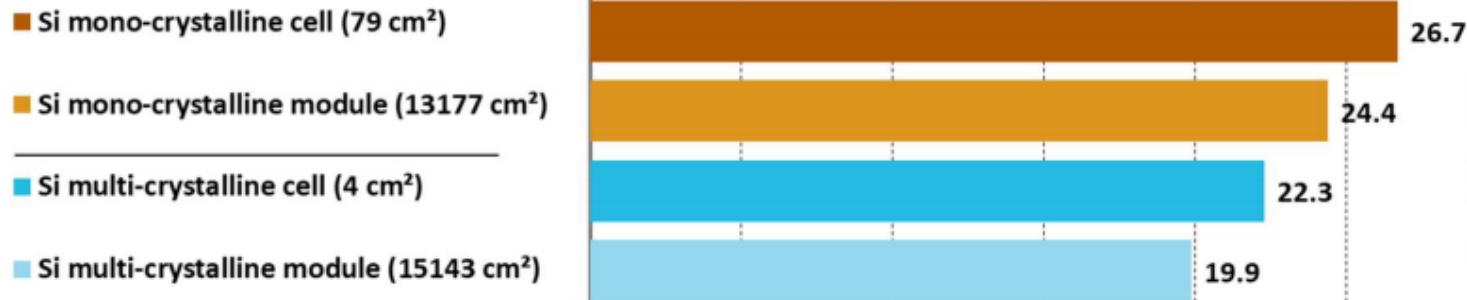
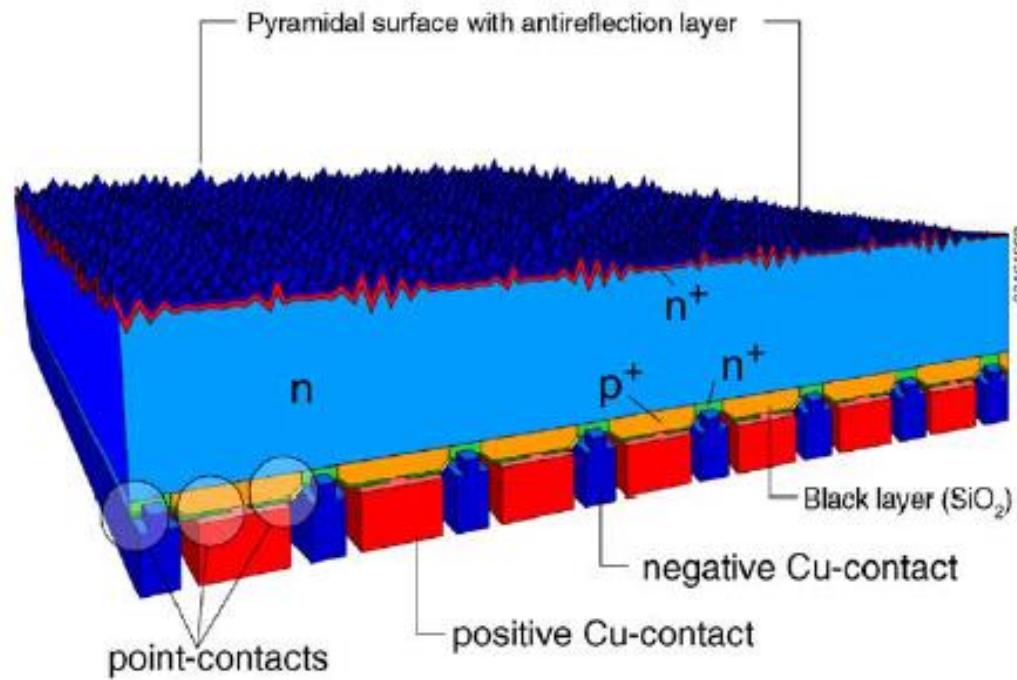
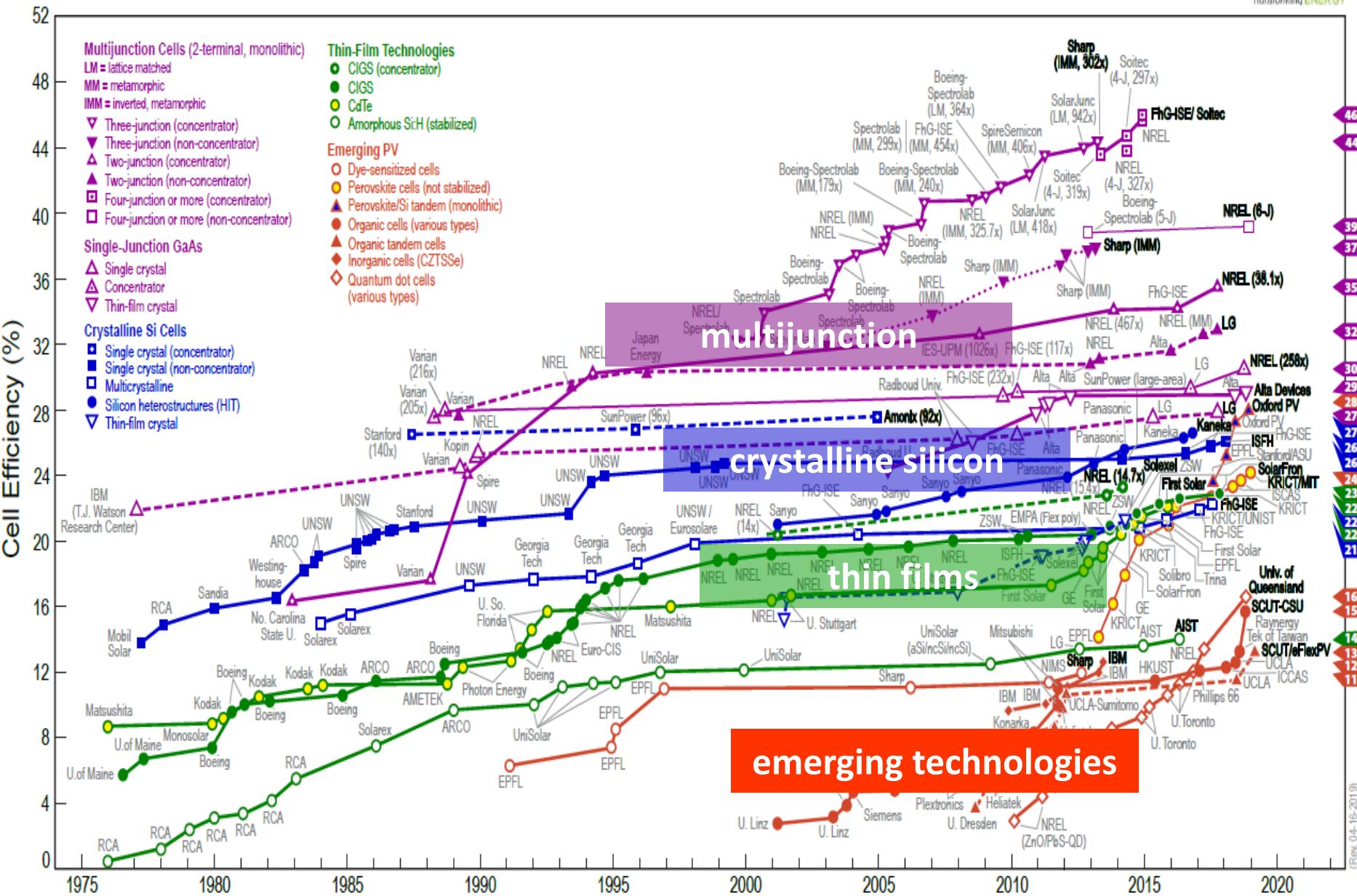


# Where are we?



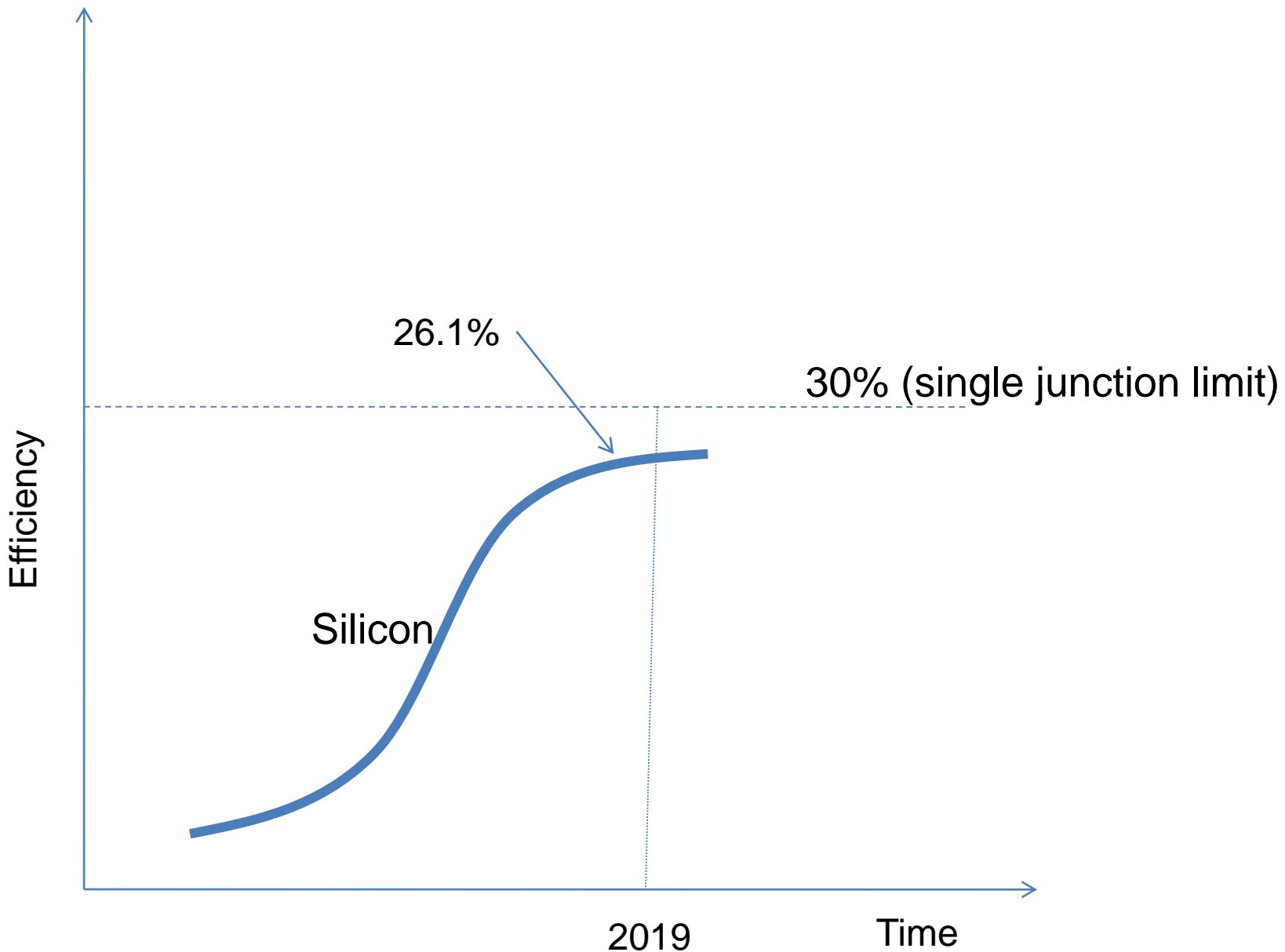
# Best Research-Cell Efficiencies



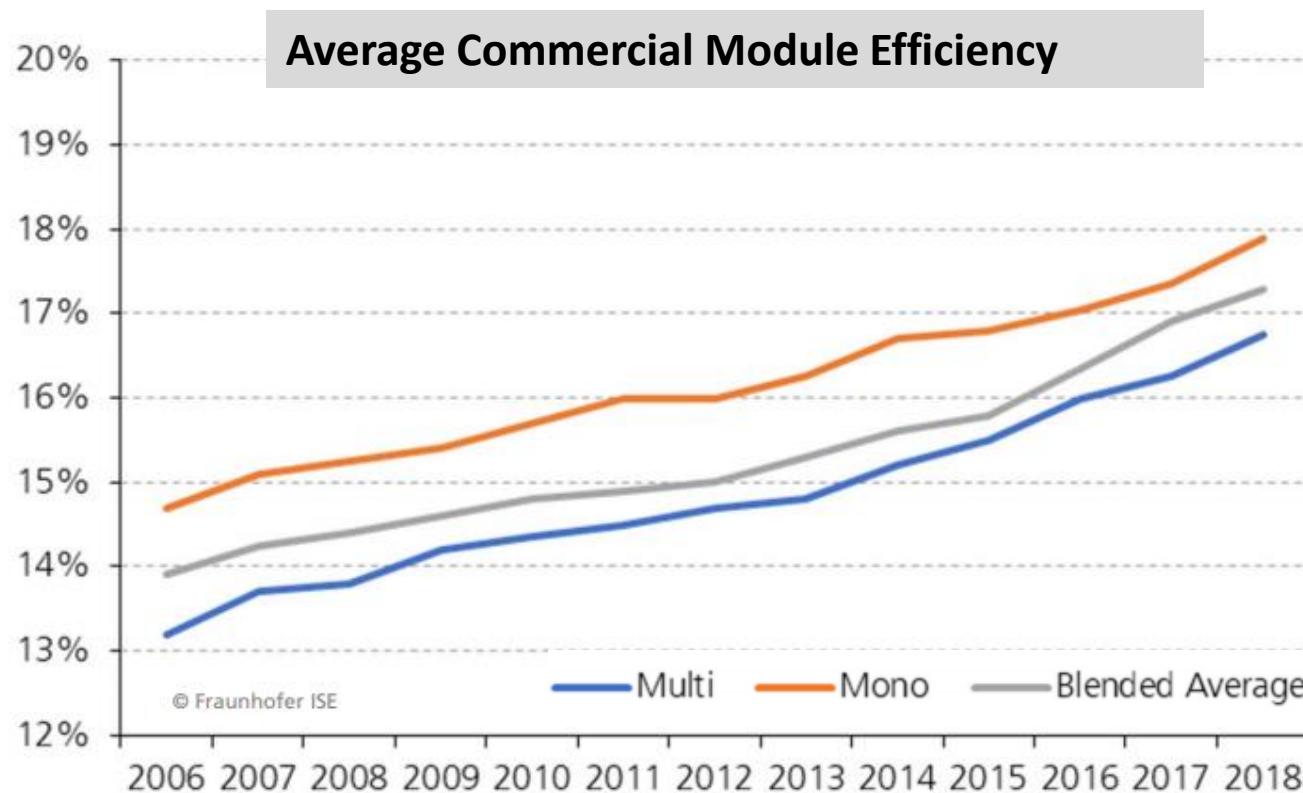
# Photovoltaic technologies: state of the art

## 1. Commercial technologies

# Technical evolution and growth potential

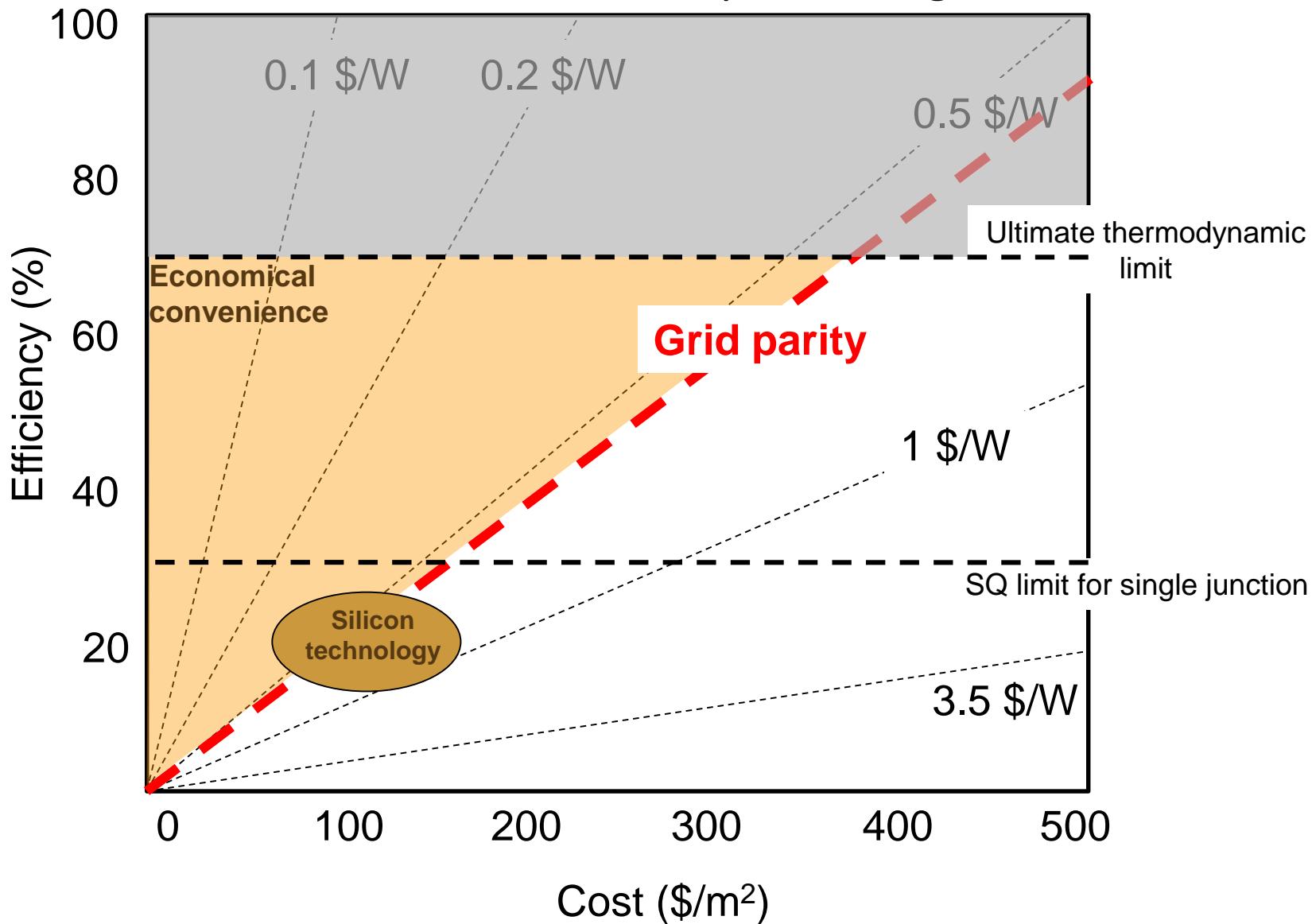


# Crystalline silicon modules

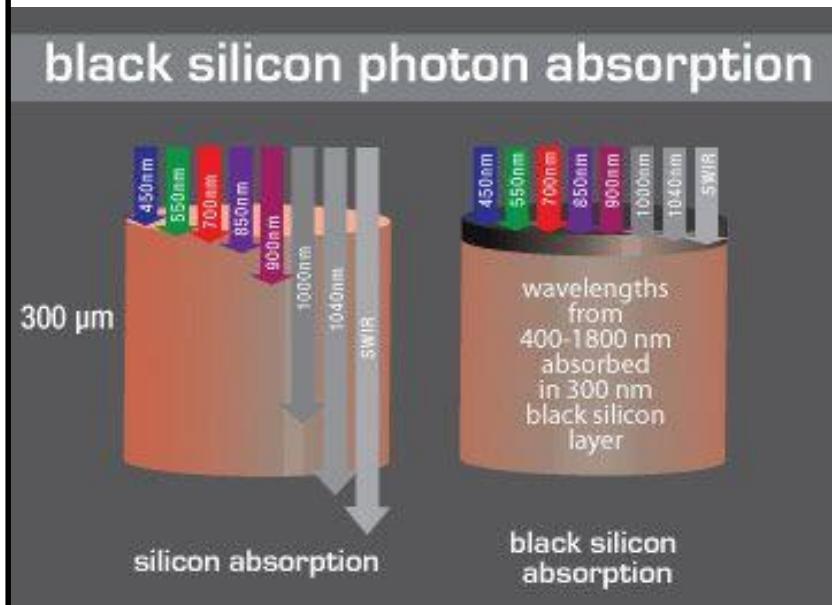
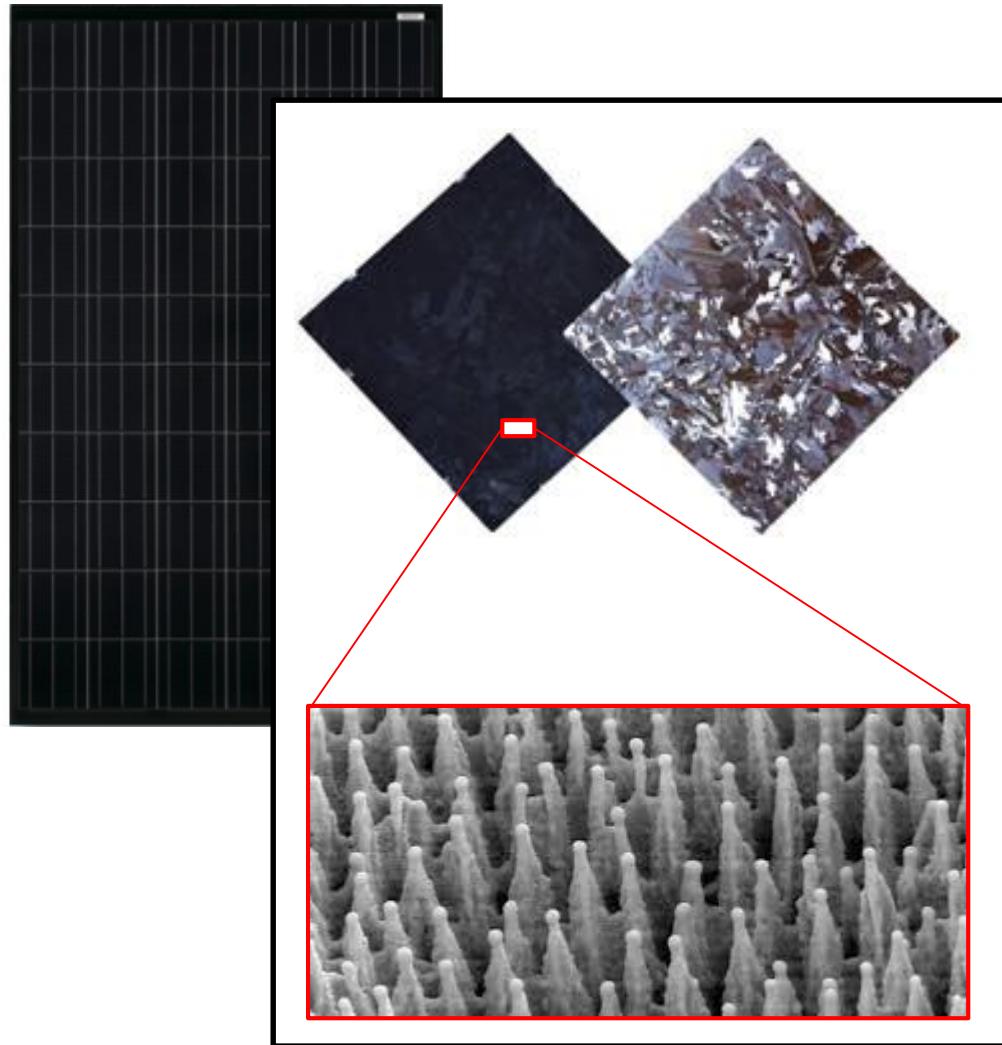


# Crystalline silicon modules

## - Techno-economic positioning -

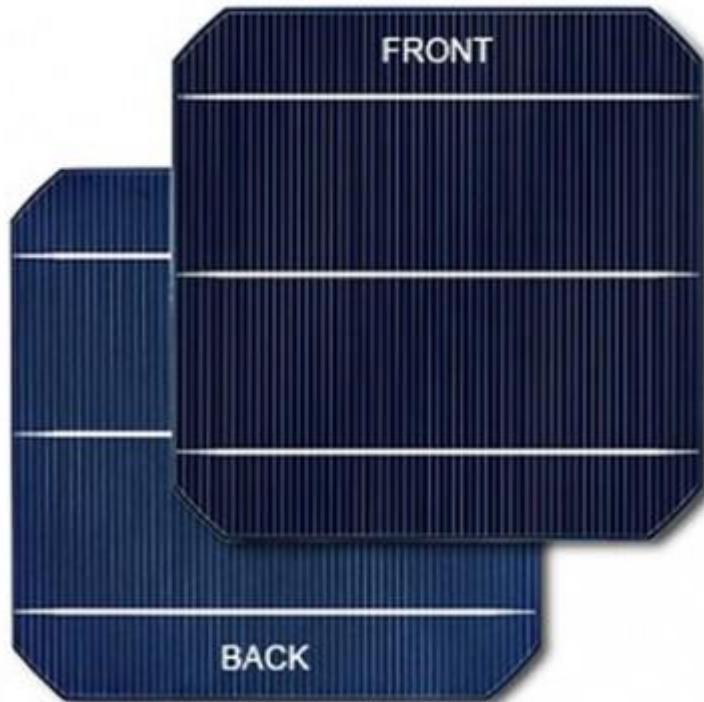


# New silicon-based commercial technologies: «Black» silicon



€/kWh reduction driver: higher efficiency at constant cost

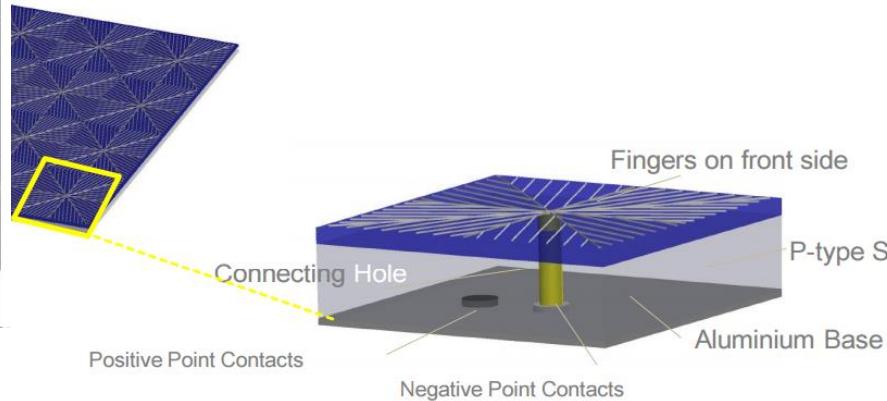
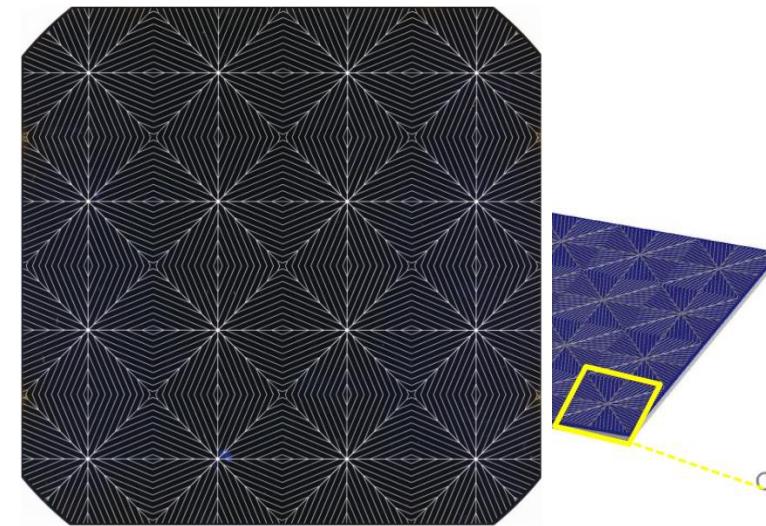
# New silicon-based commercial technologies: Bifacial technology



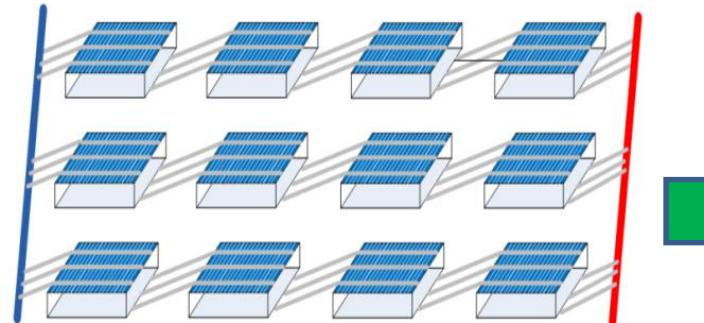
€/kWh reduction driver: higher collection area at constant cost

# New silicon-based commercial technologies: MWT Metal Wrap-Through

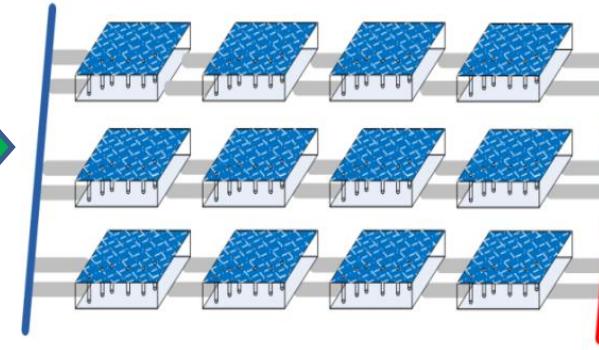
*Both electrical contacts in the back*



Standard module

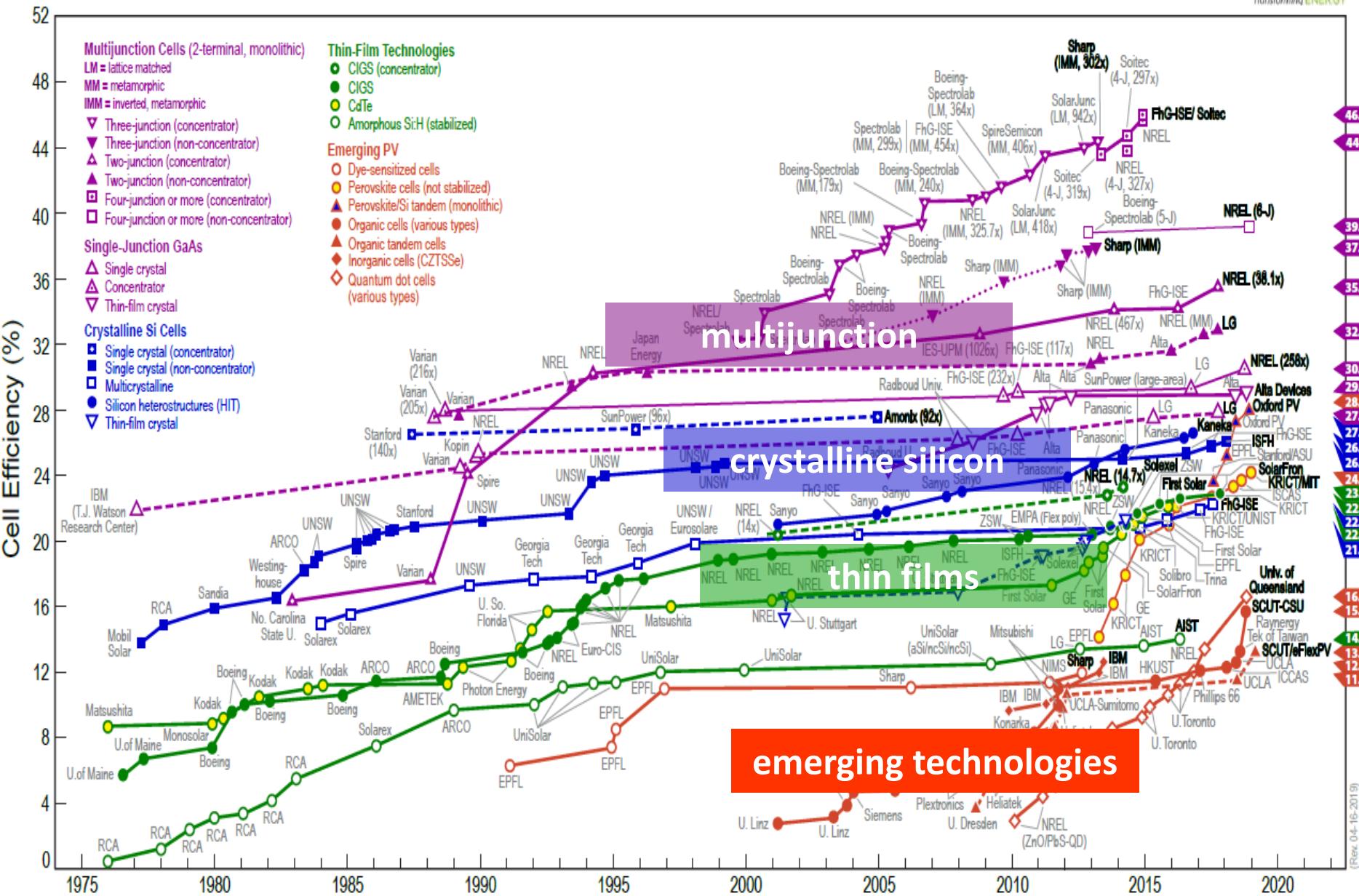


Module based on MWT

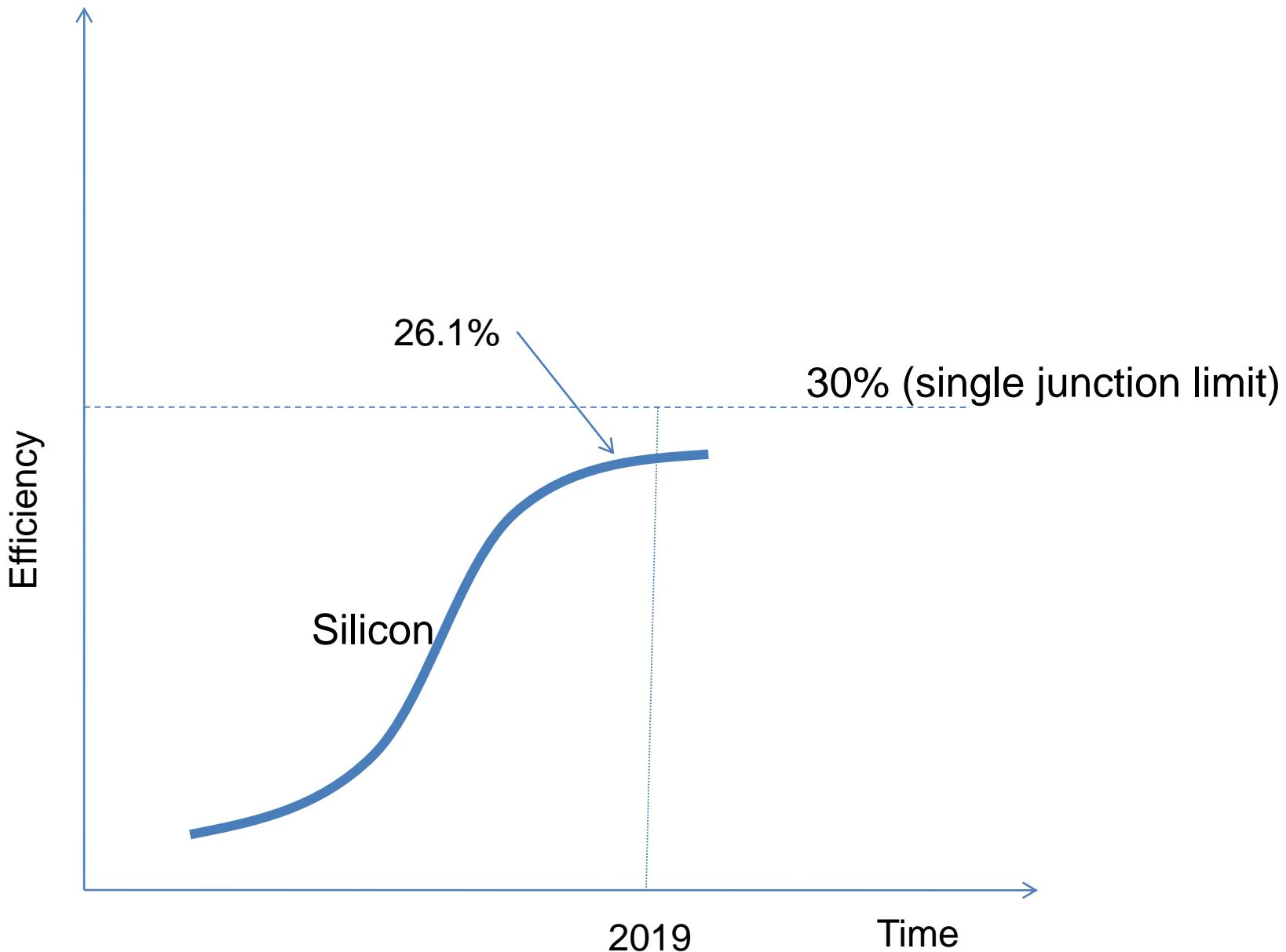


€/kWh reduction driver: lower manufacturing cost at constant efficiency

# Best Research-Cell Efficiencies



# Technical evolution and growth potential



# Downsides of Si-based modules

texturing and/or  
anti-reflection coating

front surface  
doping  
(emitter)

w

[www.pvcdrom.pveducation.org](http://www.pvcdrom.pveducation.org)

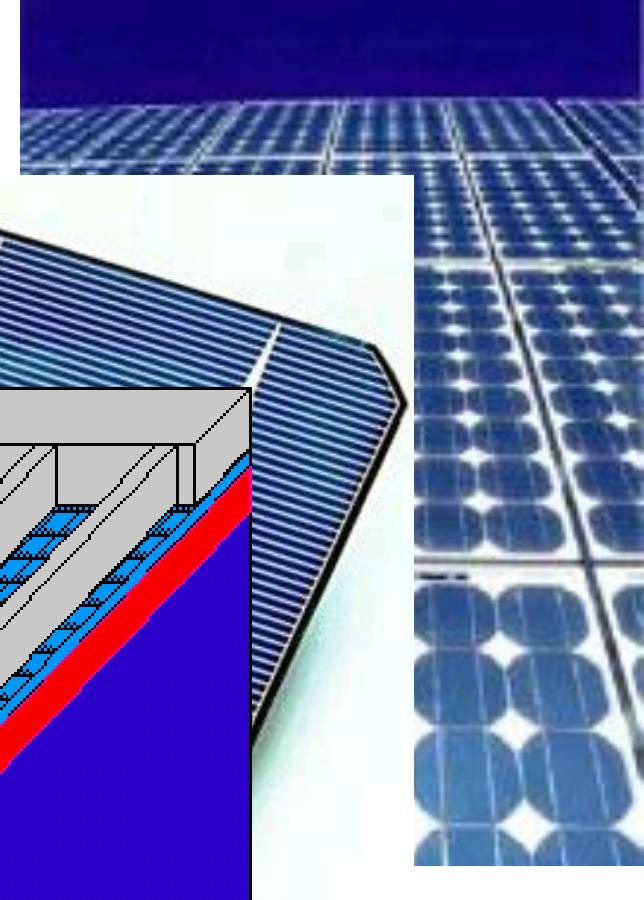
rear contact

fingers

busbar

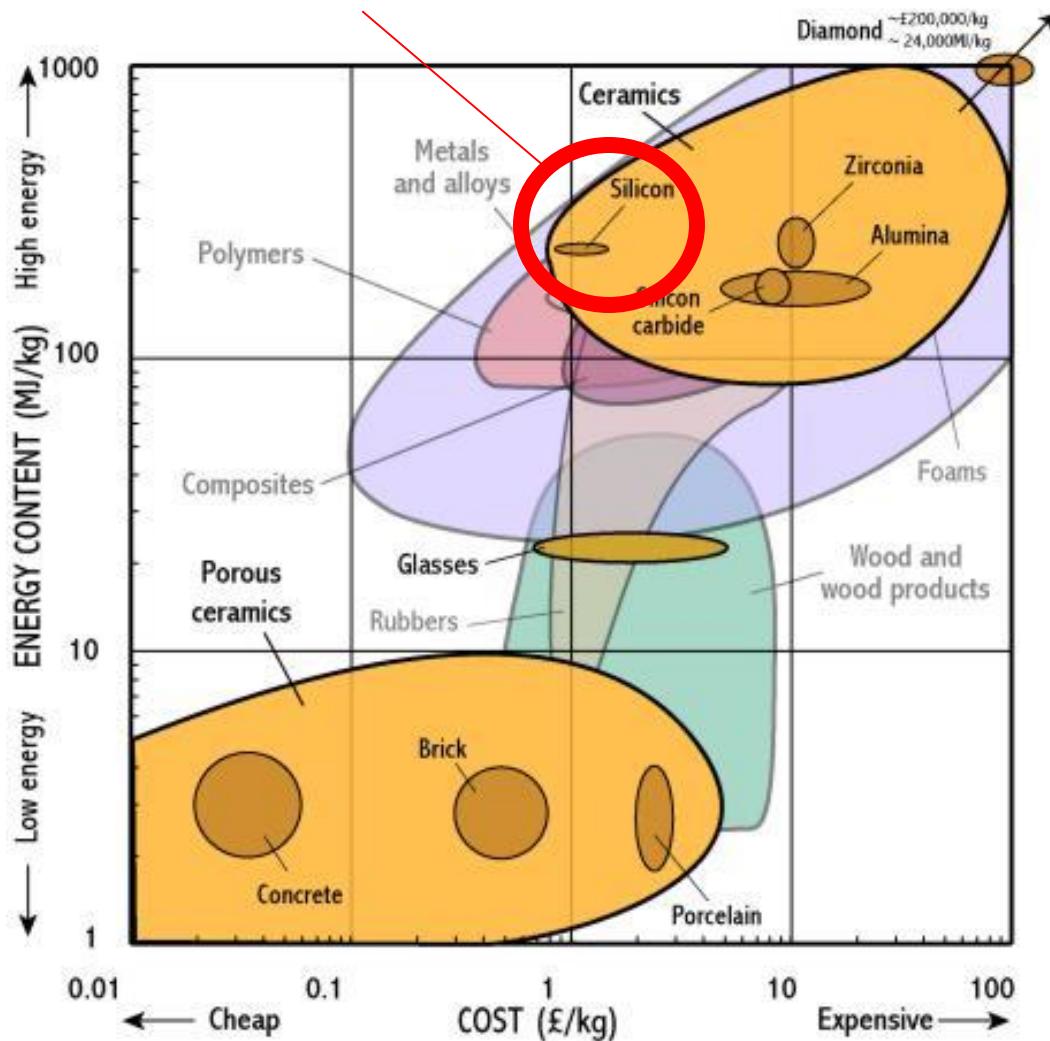
~200  $\mu\text{m}$

Silicon use:  
 $1.5 - 3 \text{ kg}_{\text{Si}}/\text{kW}_p$



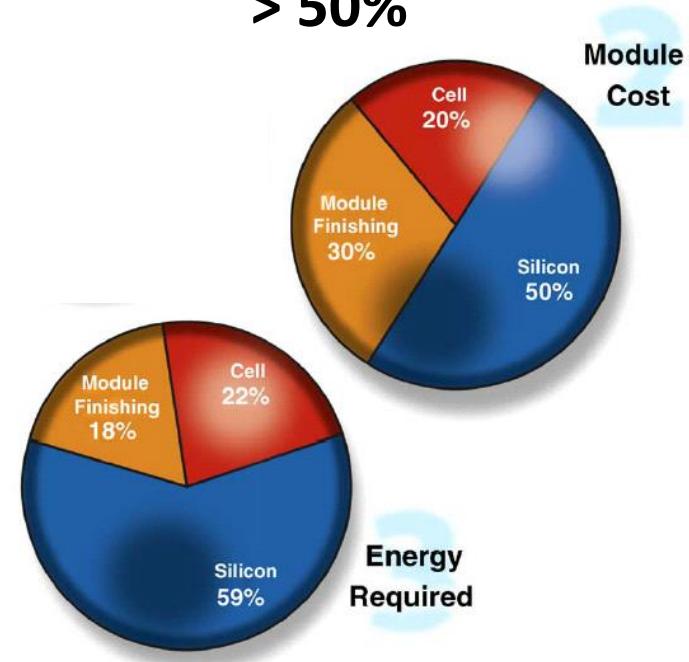
# Silicon costs money and energy

Energy cost is high!



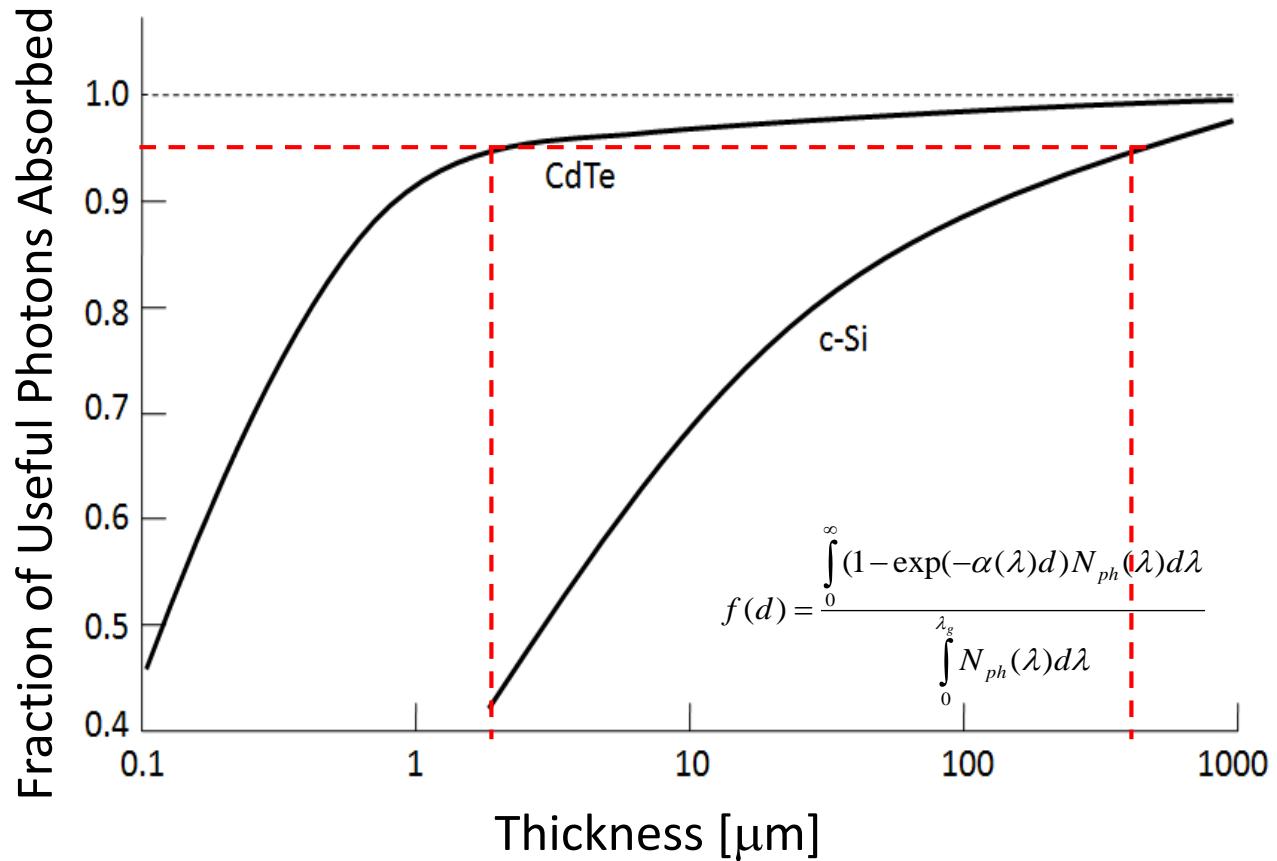
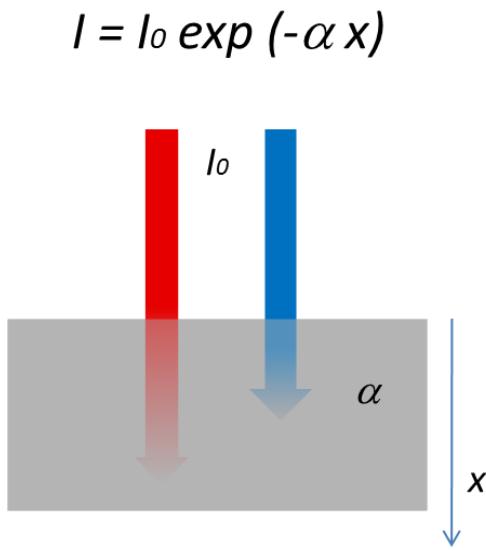
Incidence of silicon cost on the module energy and monetary cost:

> 50%

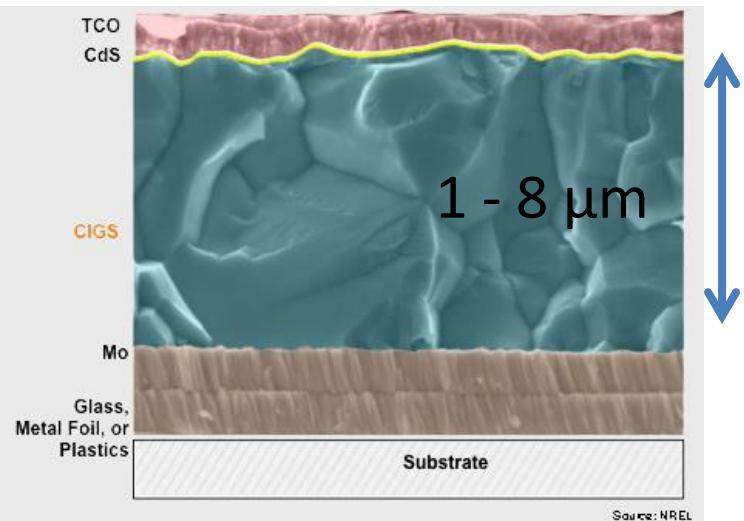
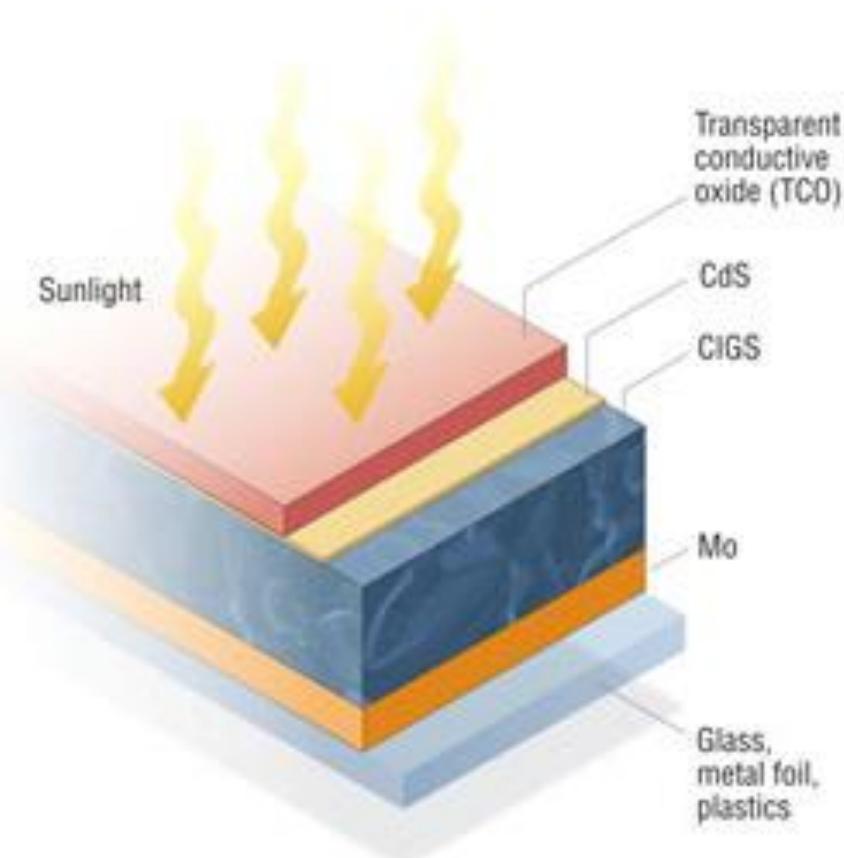


# Thin film technology

- Based on materials with better light absorption properties-



# Thin film technology: CIGS, a-Si, CdTe



## CIGS:

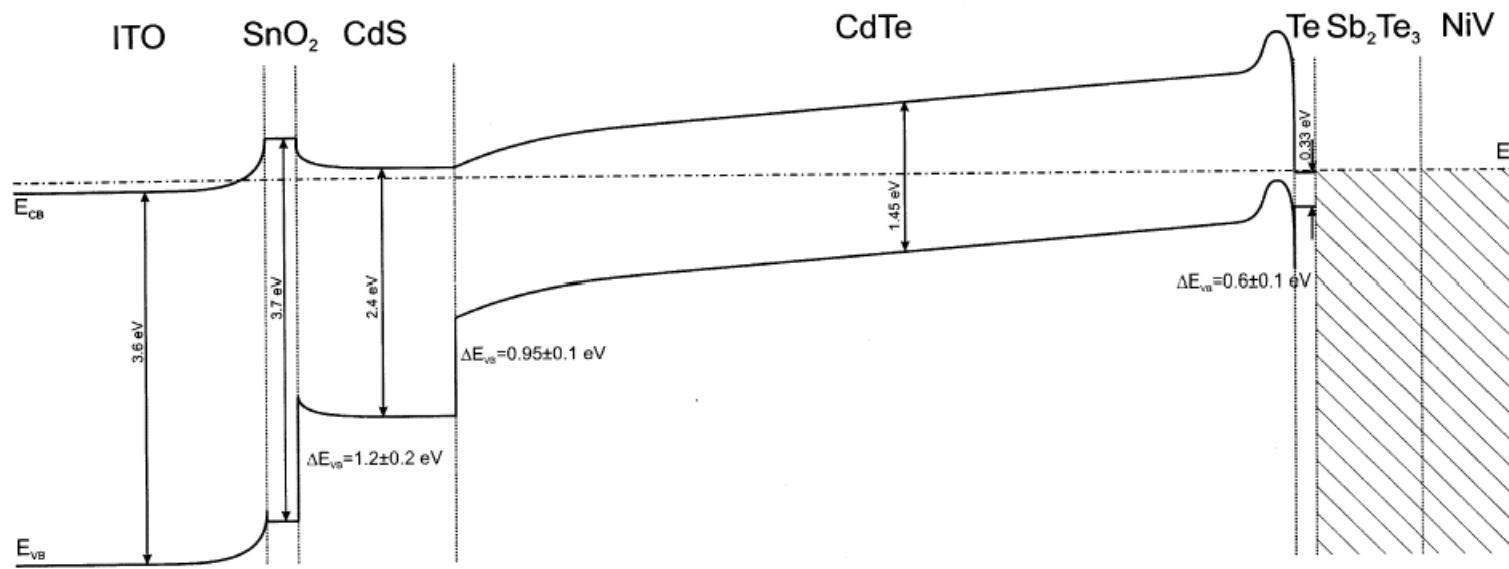
- Solar Frontier, inc.
- Solibro, GmbH
- Miasolé, Ltd.
- ... (several global companies)...

## CdTe:

- First Solar, inc.

## a-Si

- Sharp, inc.
- Sunerg, srl



# Thin film technology: aesthetics, building integration, reduction of installation cost



# Thin film technology: CIGS, a-Si, CdTe

## - cost comparison with silicon-based modules -

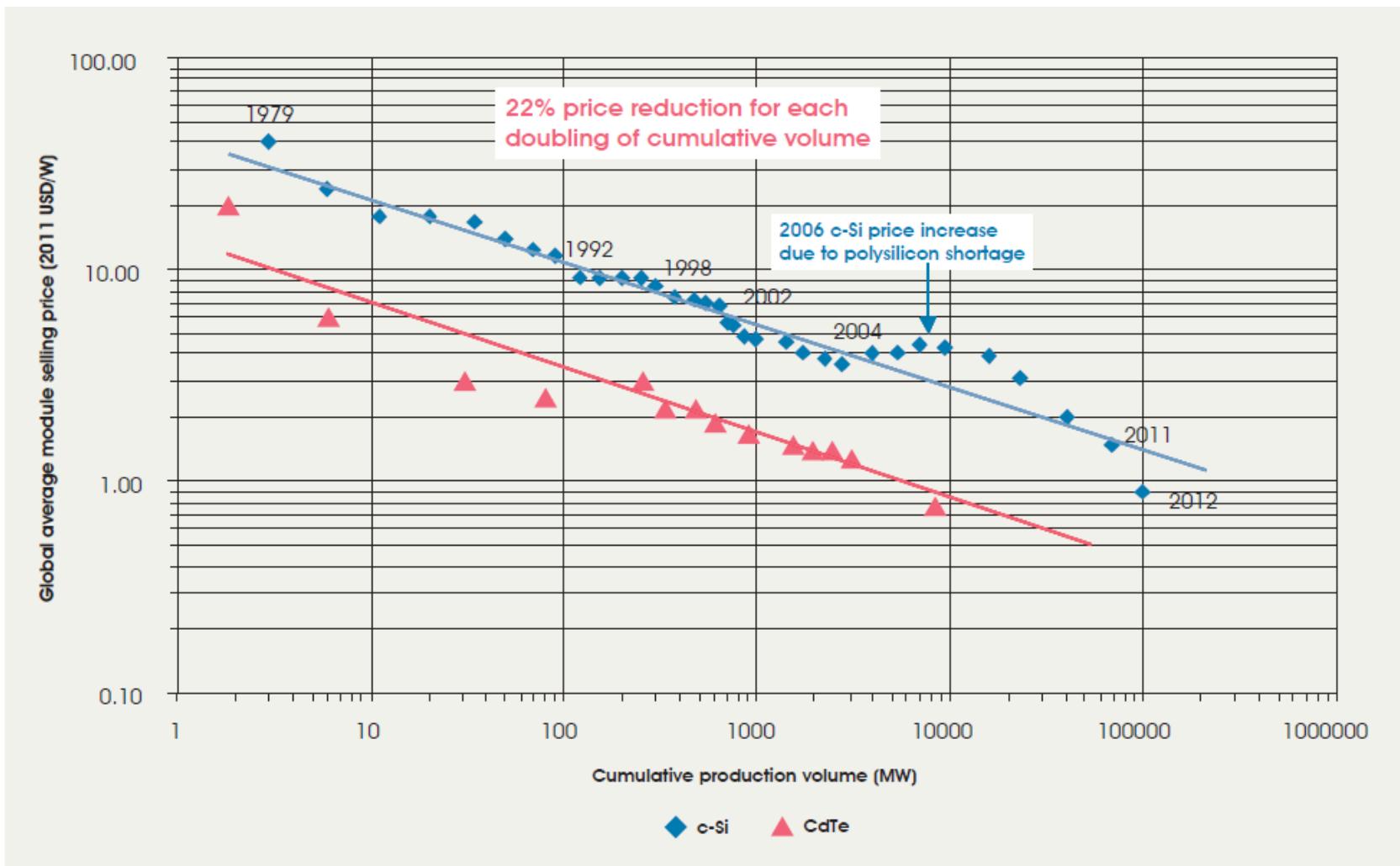
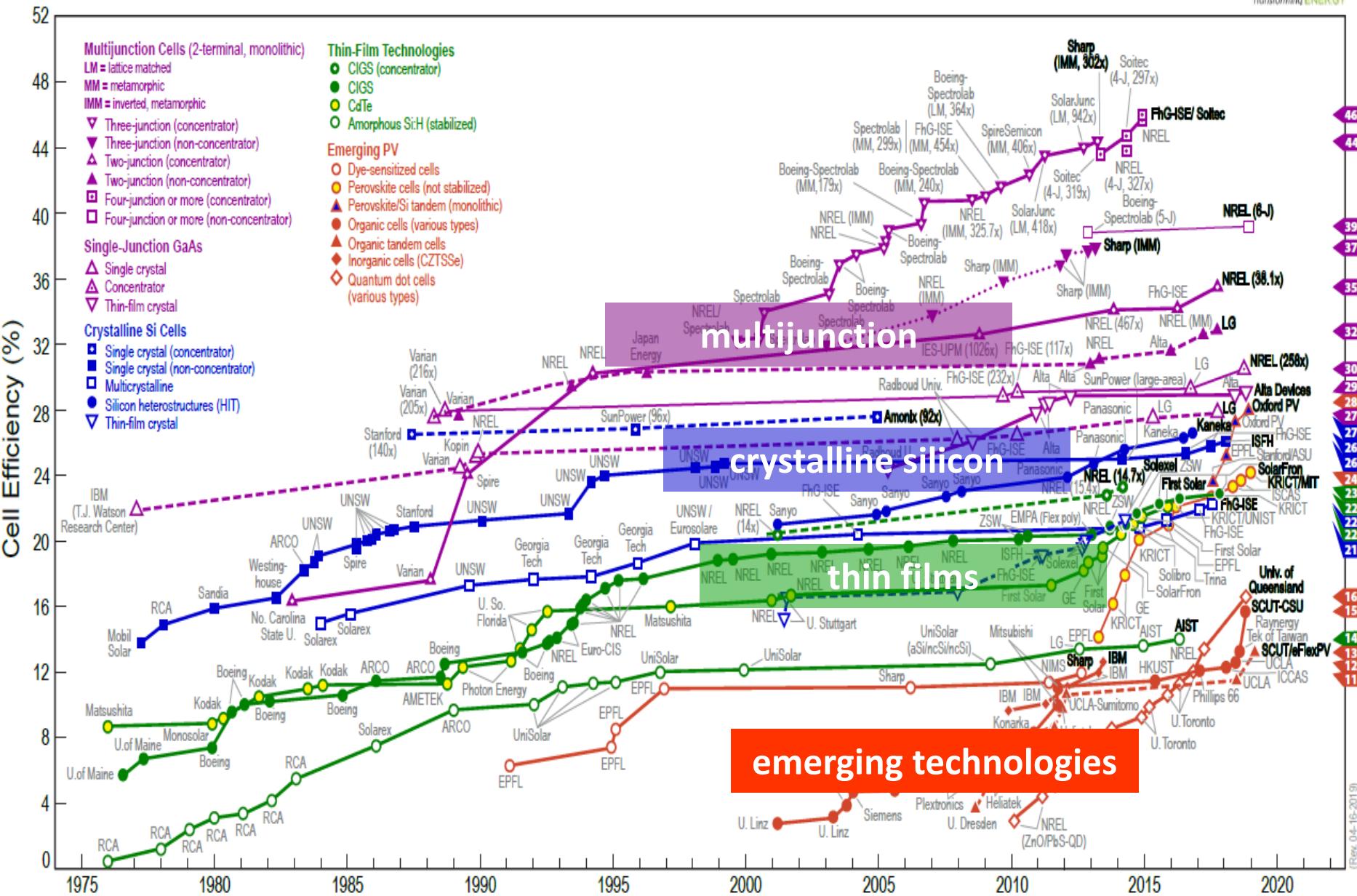


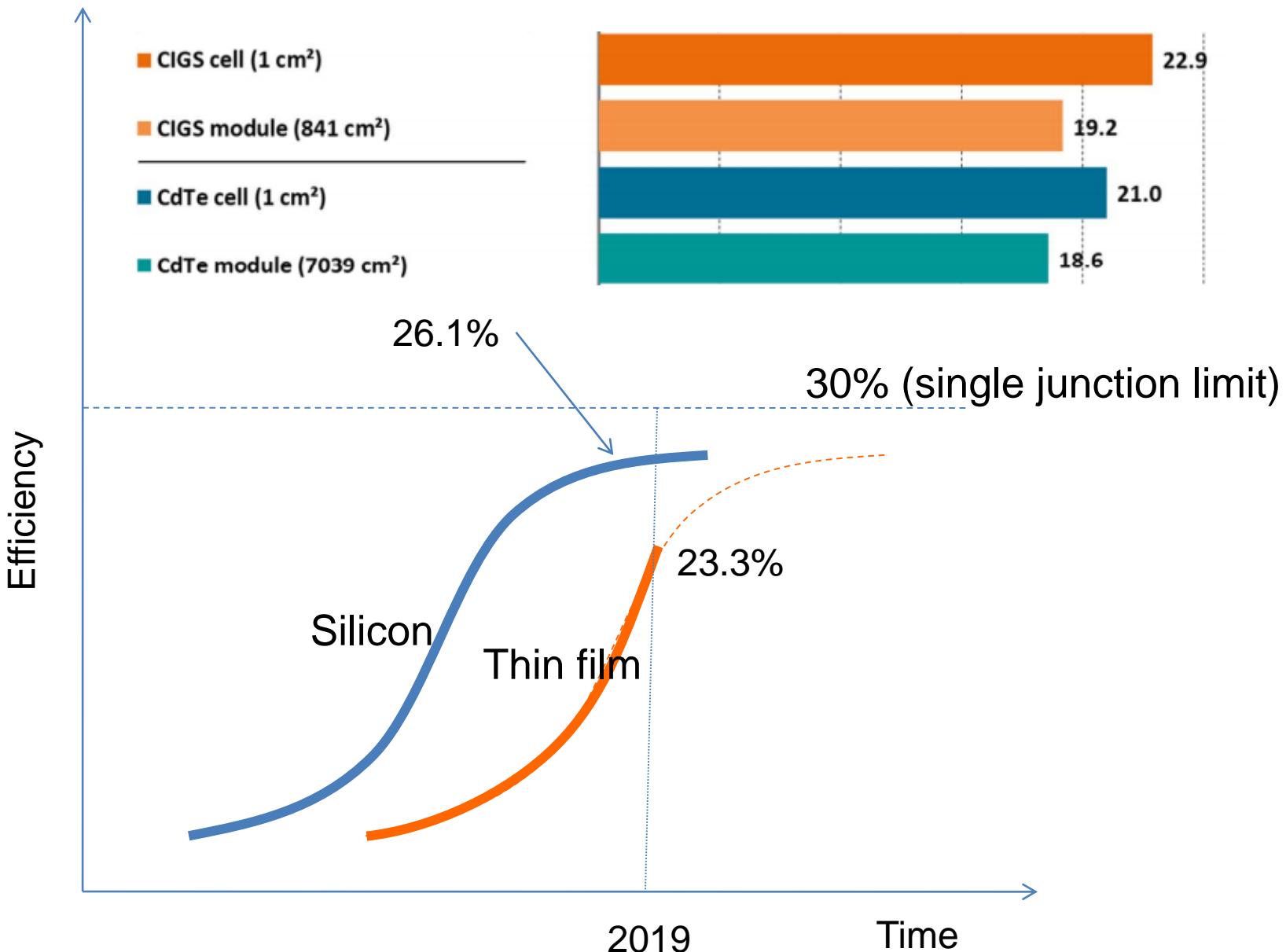
FIGURE 6.2: SOLAR PV MODULE COST LEARNING CURVE FOR CRYSTALLINE SILICON AND THIN-FILM

SOURCE: BASED ON DATA FROM EPIA AND PHOTOVOLTAIC TECHNOLOGY PLATFORM, 2011; LIEBREICH, 2011; SOLOGICO, 2012 AND IRENA ANALYSIS.

# Best Research-Cell Efficiencies

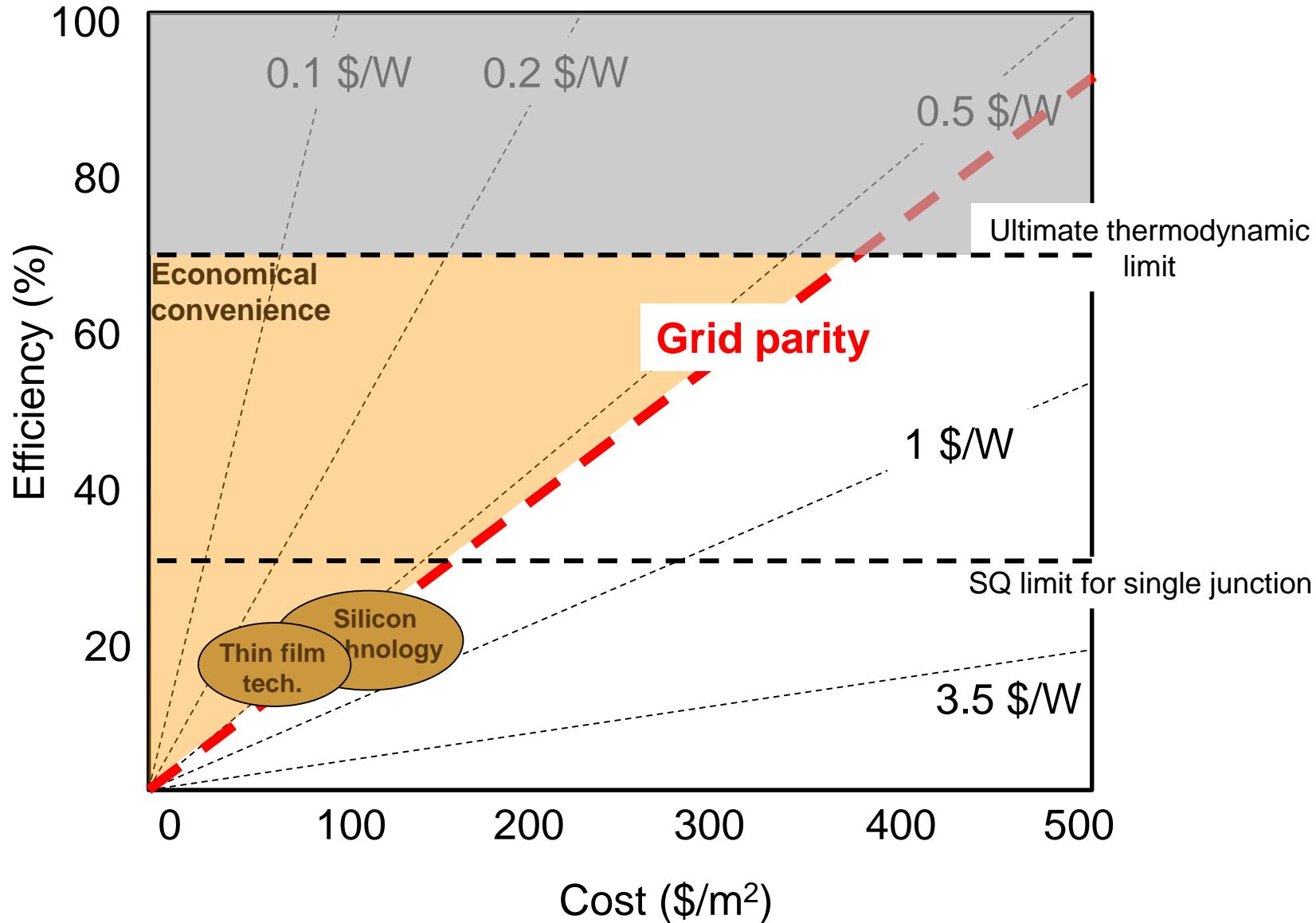


# Technical evolution and growth potential

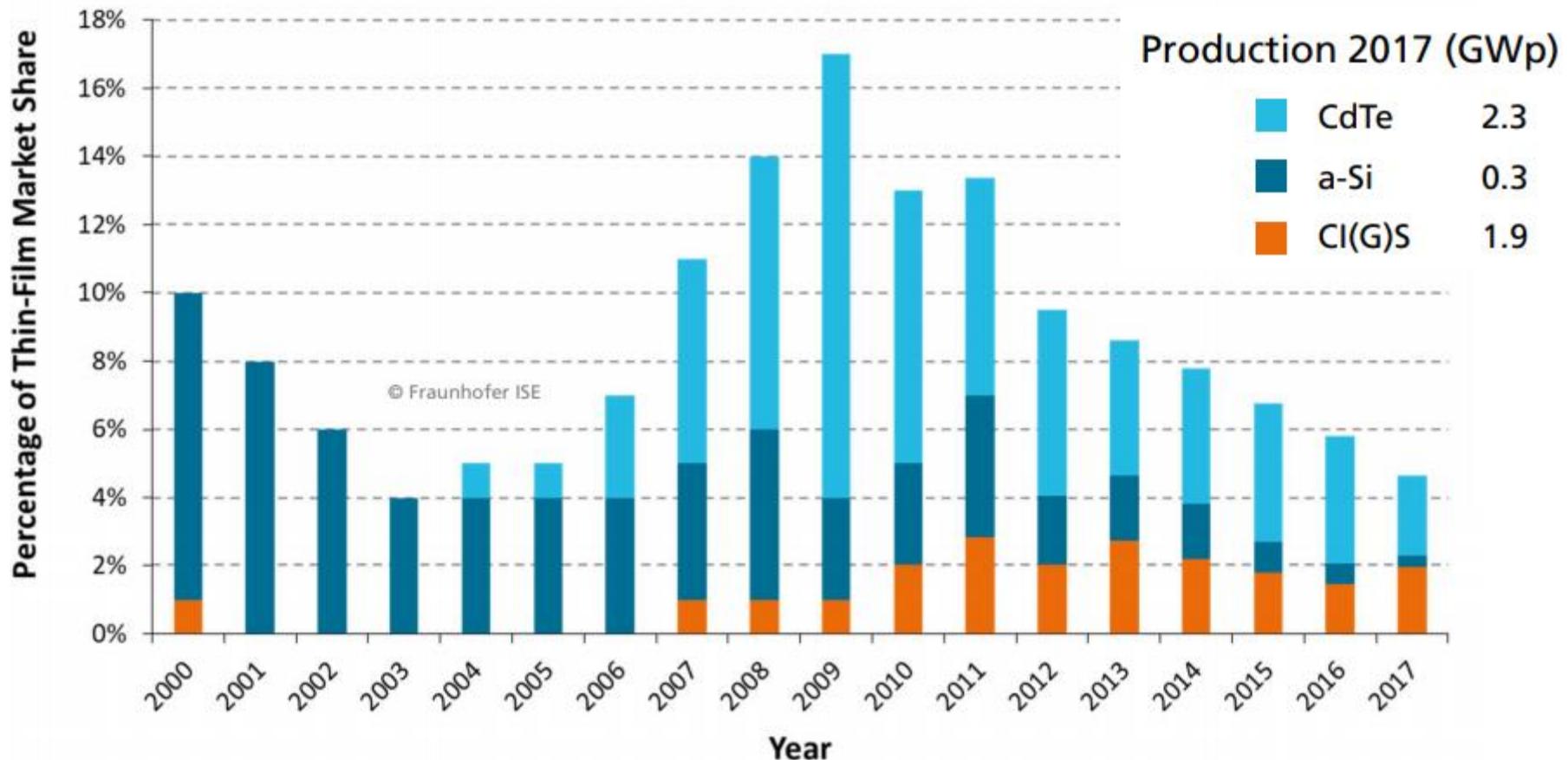


# Thin film PV modules

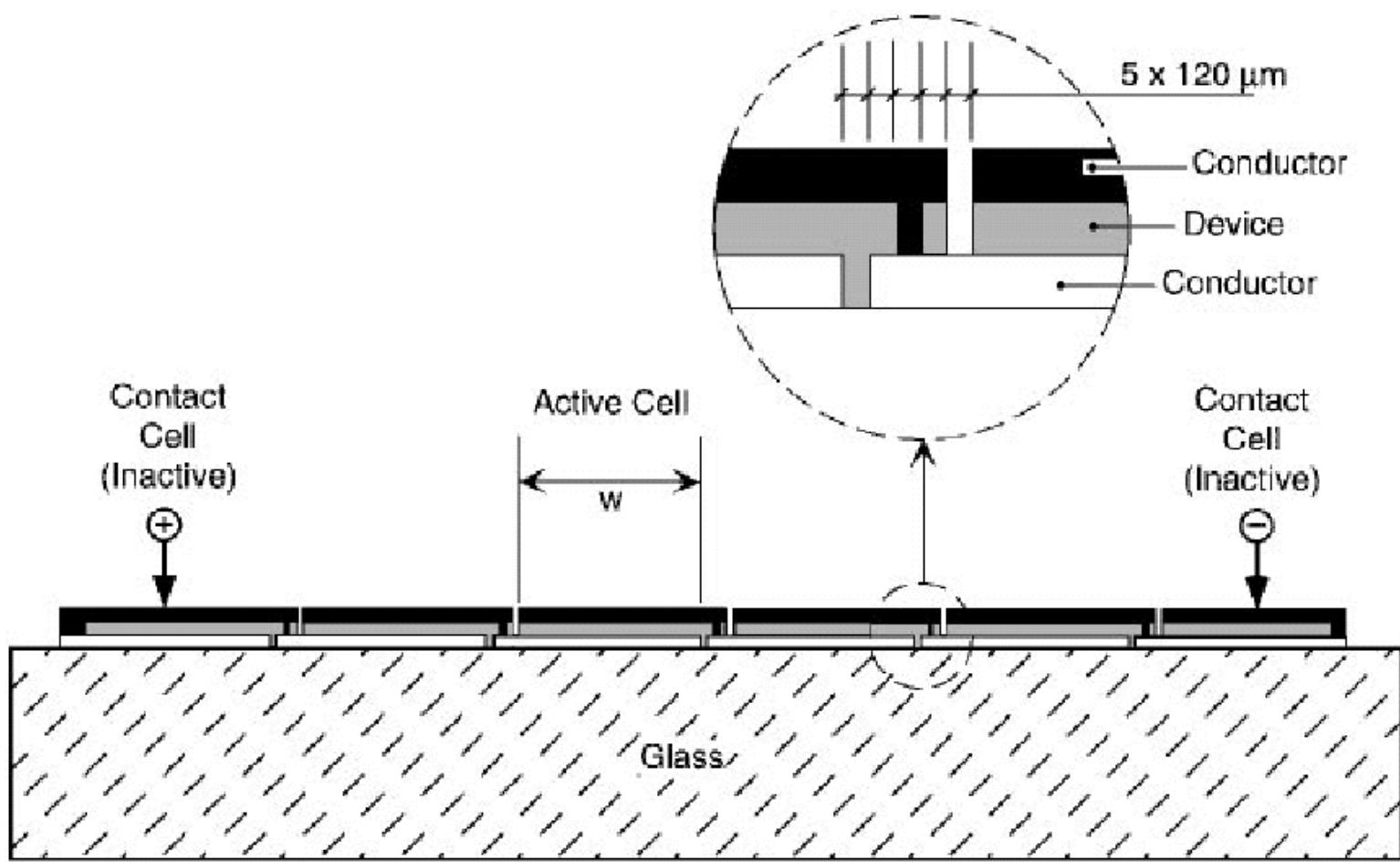
## - Techno-economic positioning -



# Impact of Thin Film Technology is Dropping



Data: from 2000 to 2010: Navigant; from 2011: IHS. Graph: PSE GmbH 2018



# Basic working principle of a PV cell

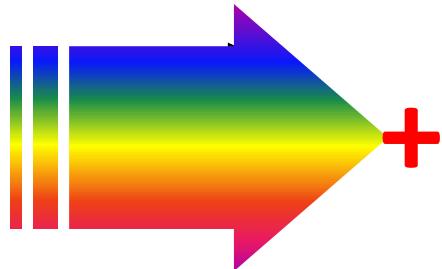
- an electron's perspective -

1.

**Absorption**  
of solar radiation



**Generation**  
of electrical charges

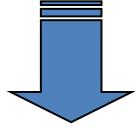


-

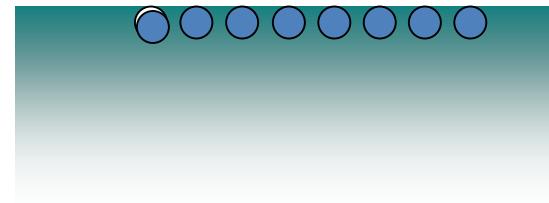
Energy  
↑

2.

**Extraction**  
of electrical charges

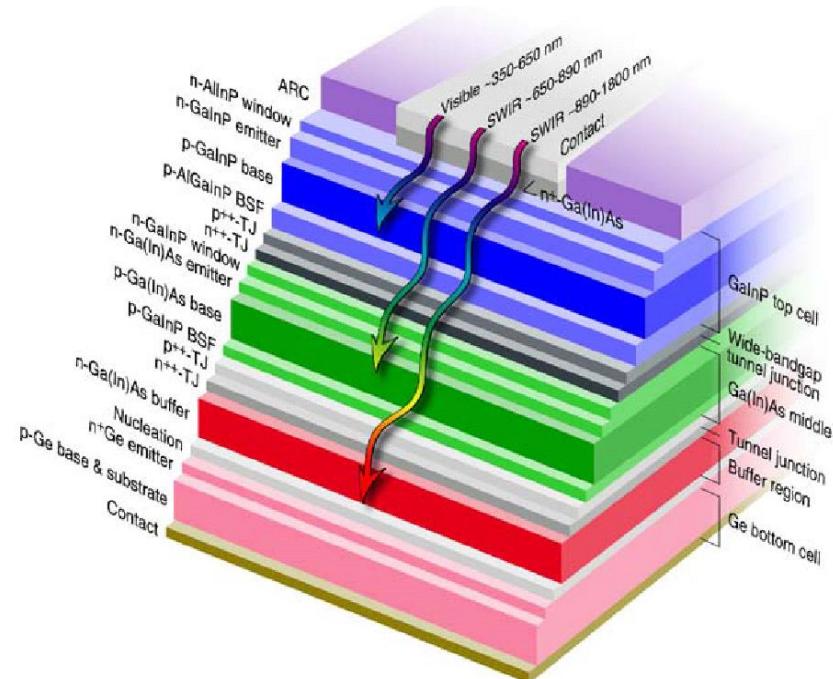
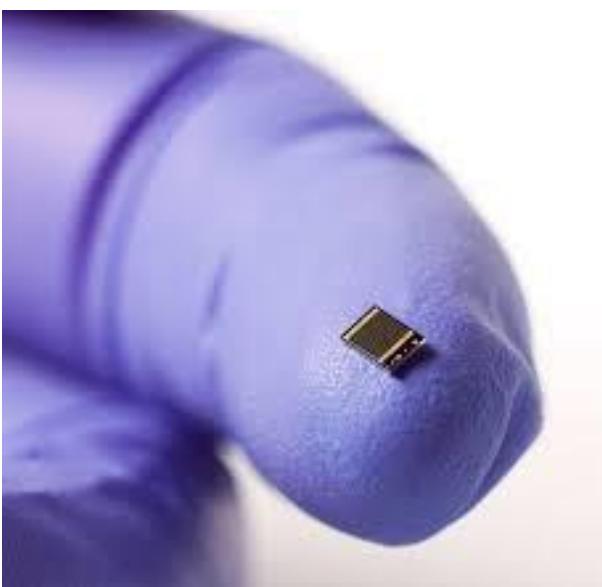
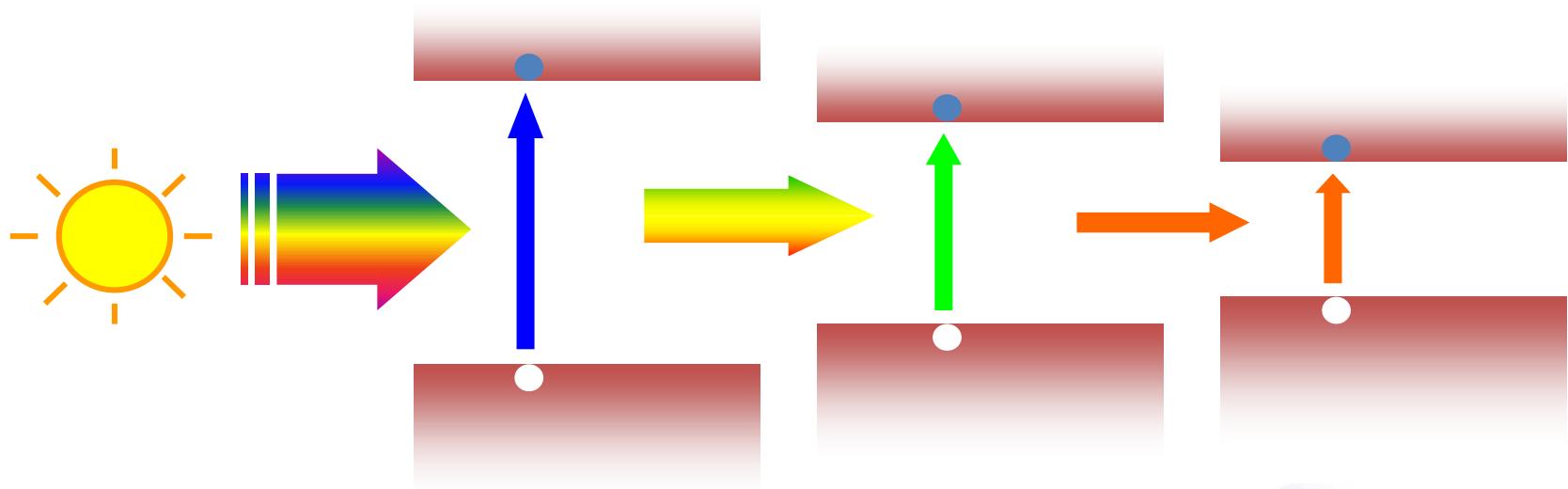


**Electrical energy**

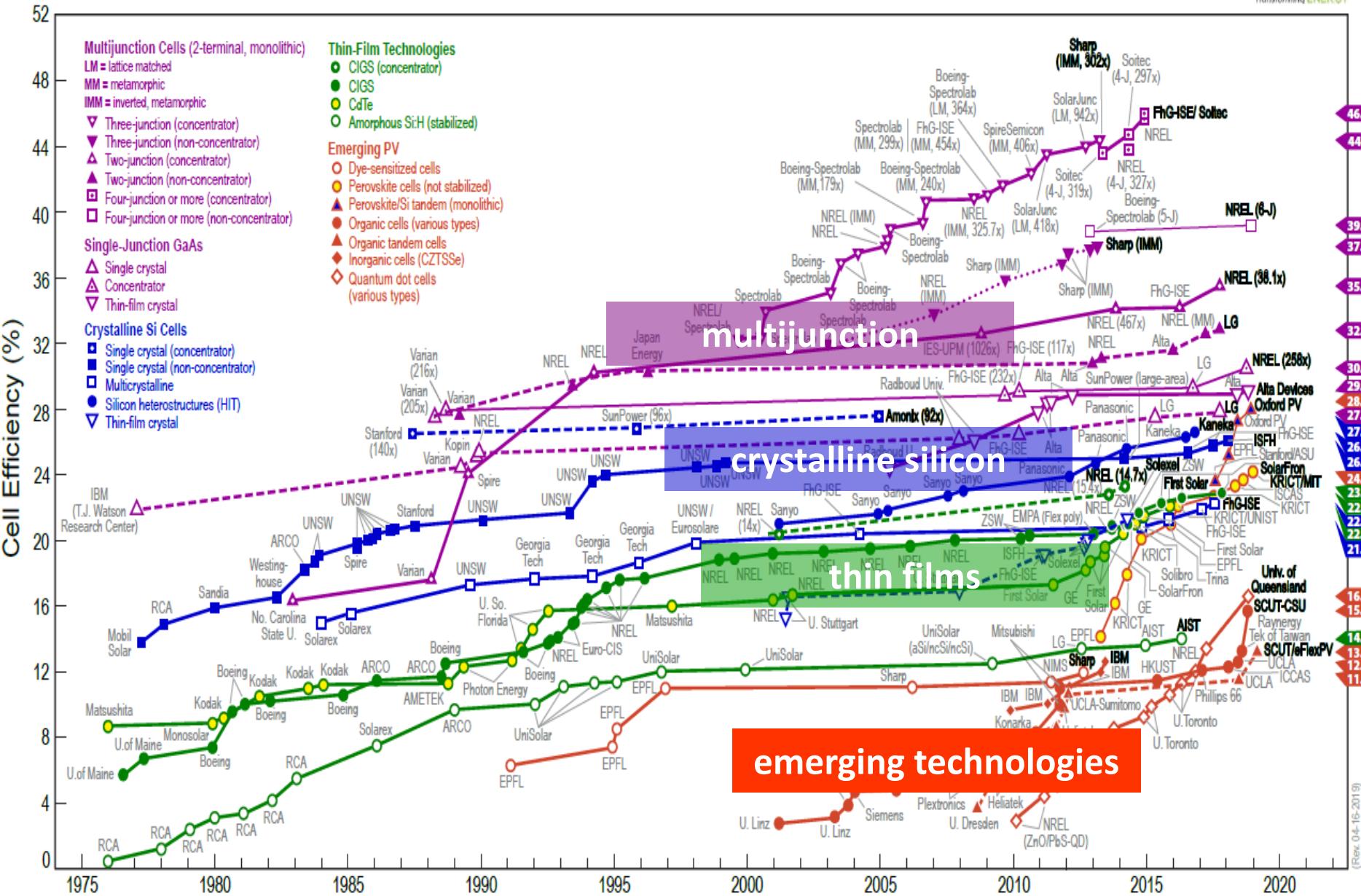


# Multijunction («tandem») cells

- A more efficient use of the solar radiation -

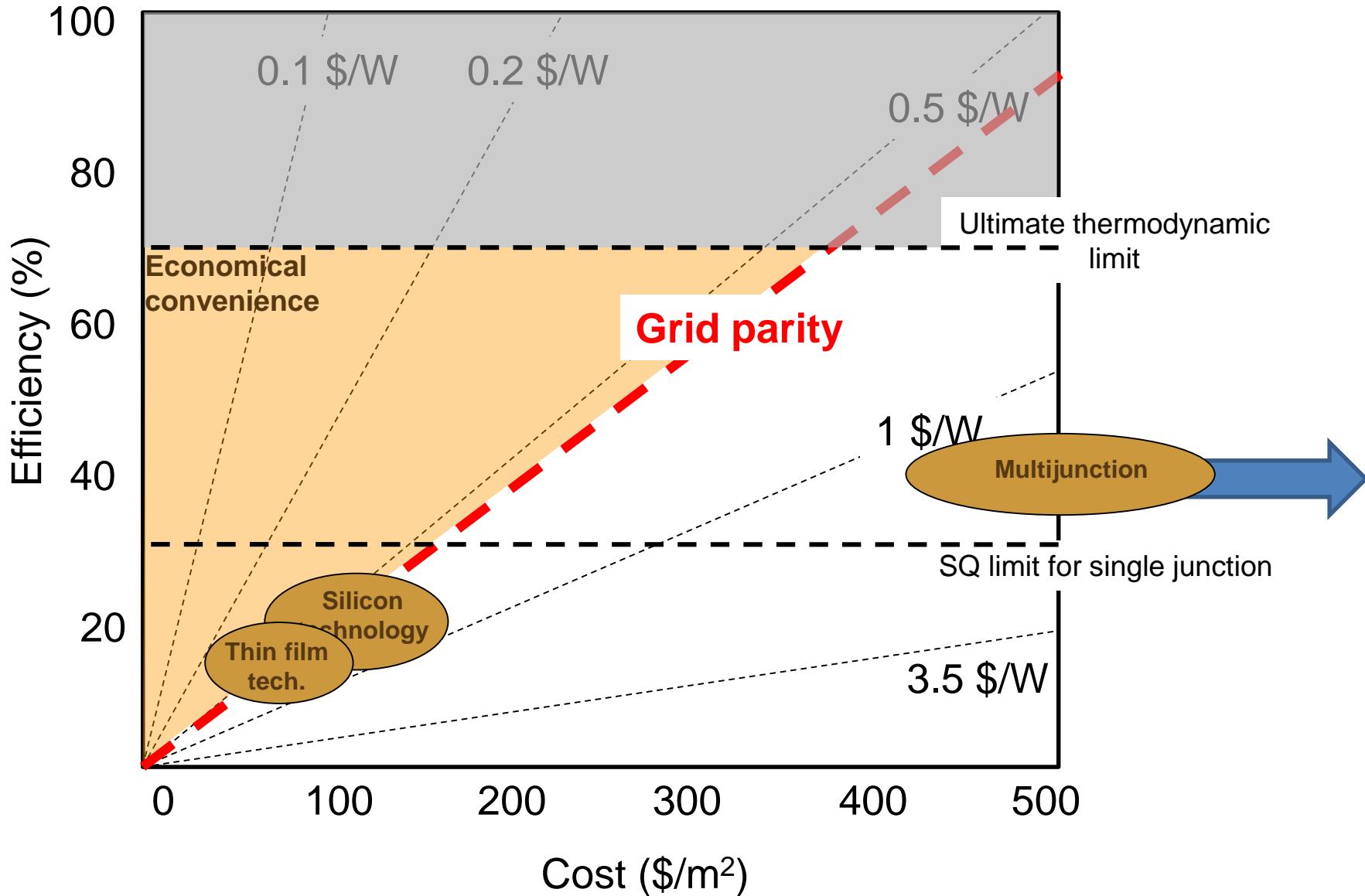


# Best Research-Cell Efficiencies



# Multijunction cells

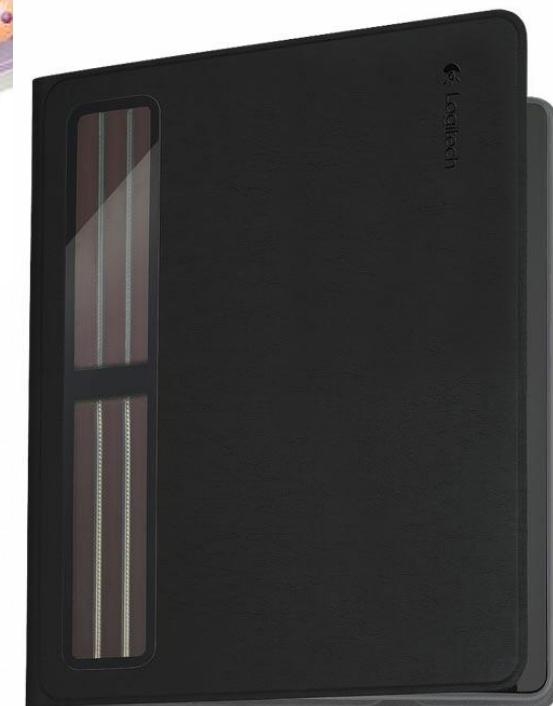
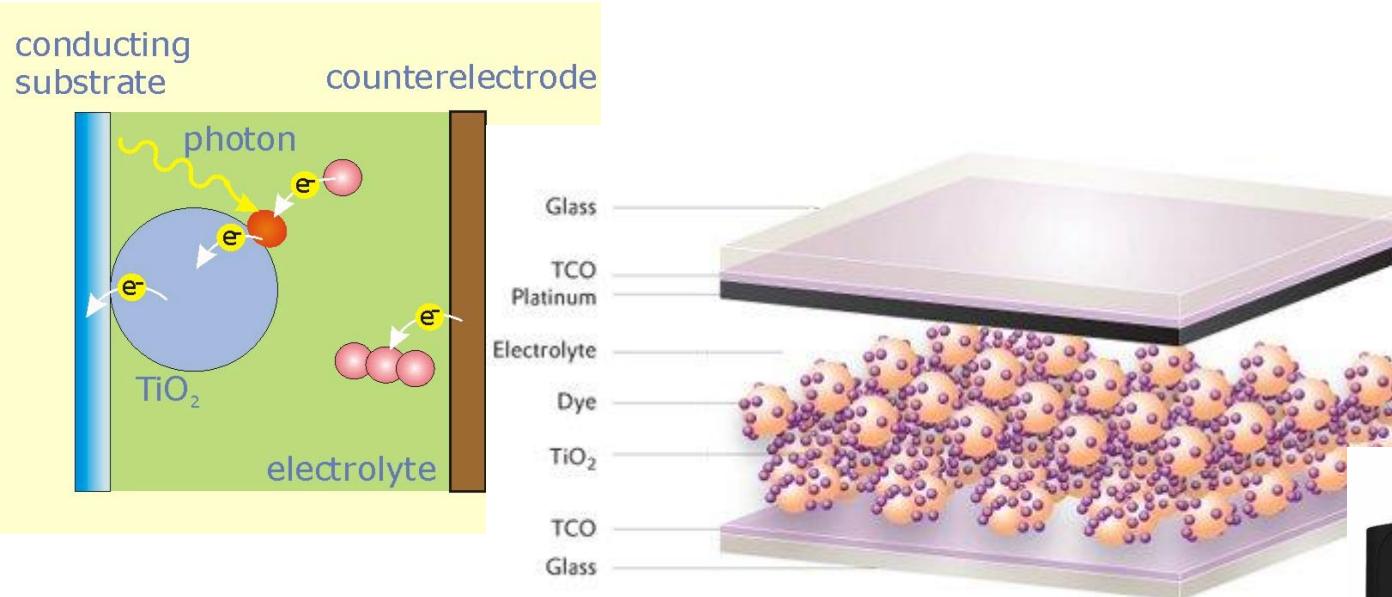
## - Techno-economic positioning -



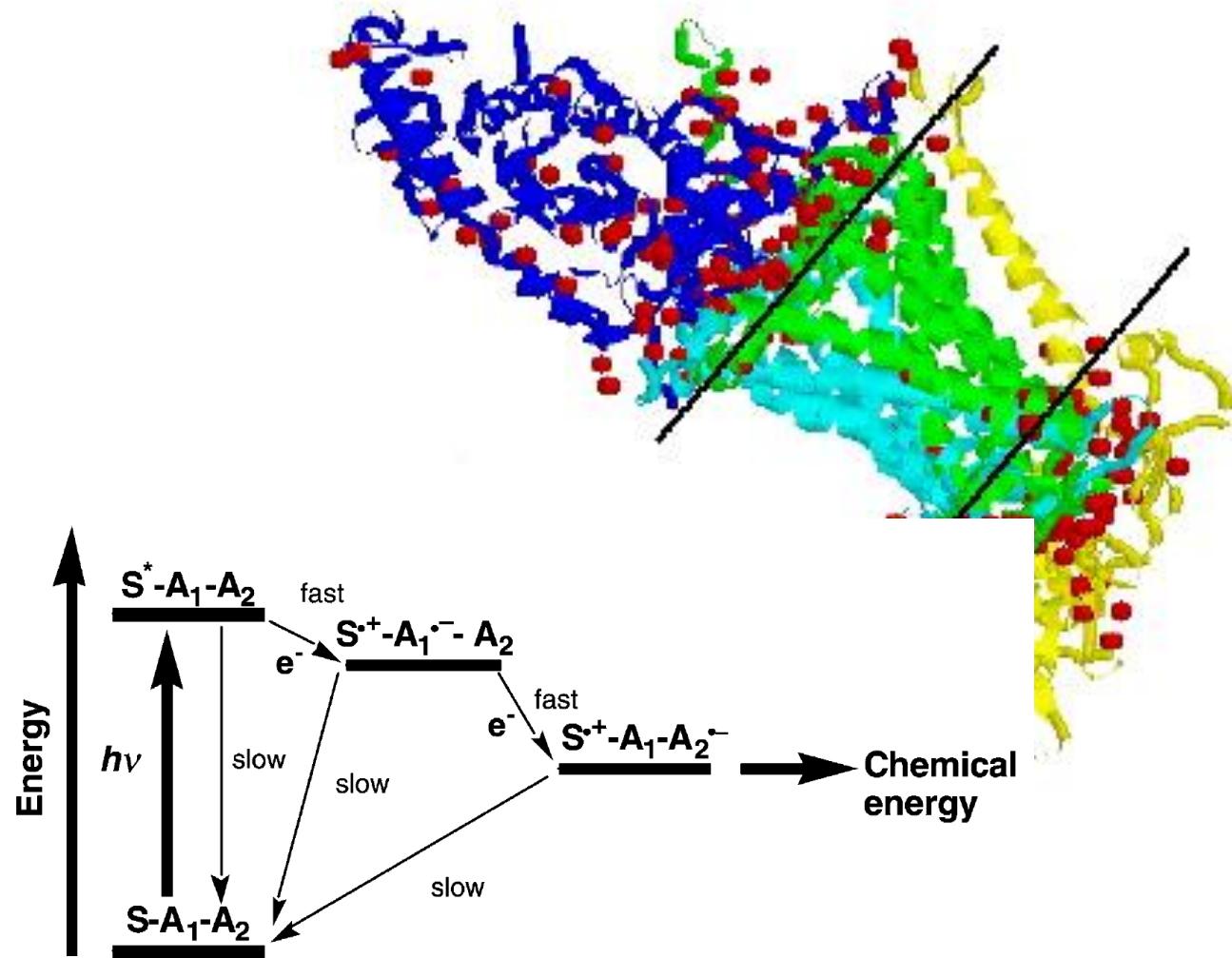
# Photovoltaic technologies: state of the art

## 2. Frontier technologies

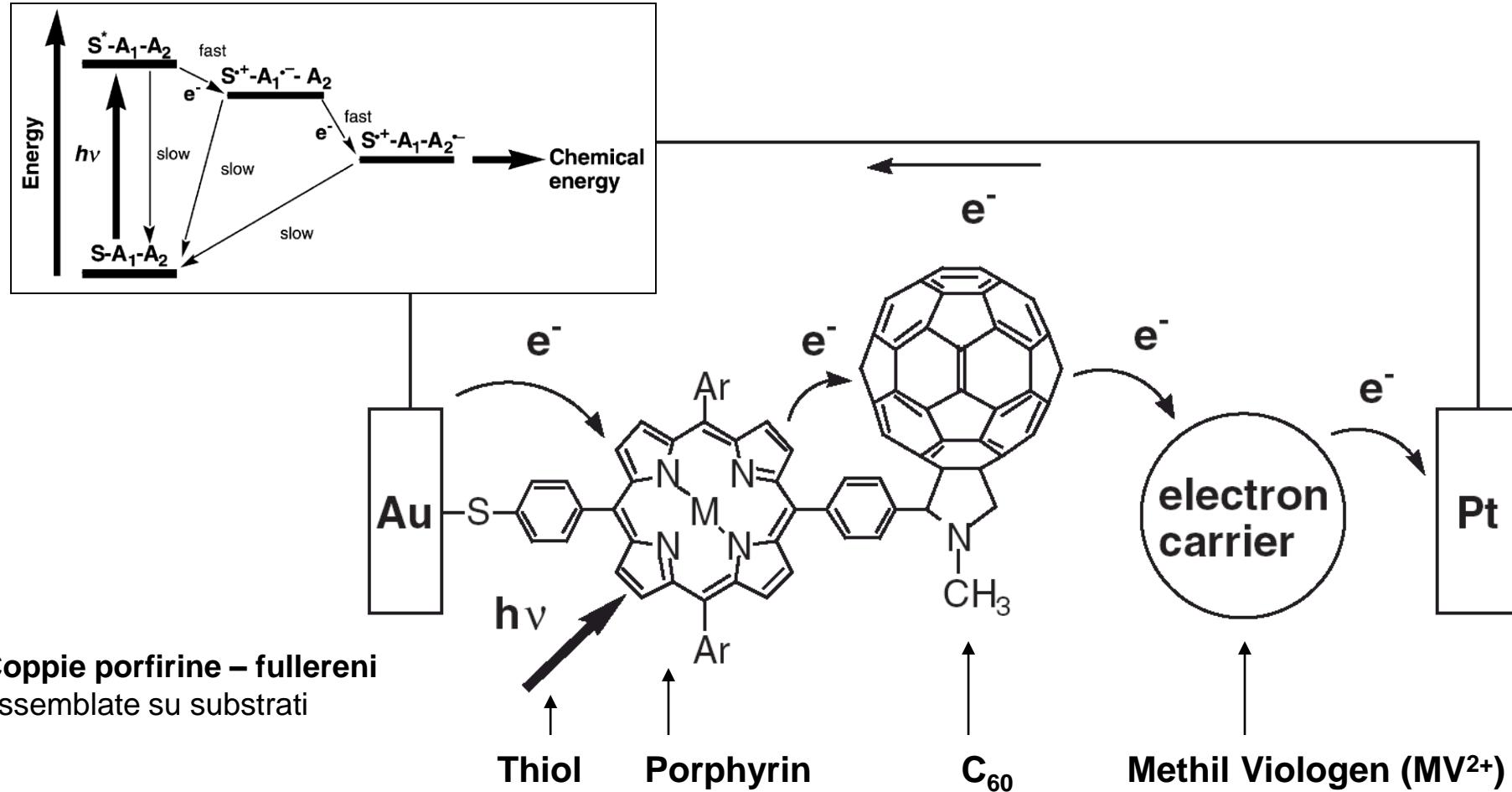
# Dye Sensitized Solar Cell - DSSC



# Fotosintesi



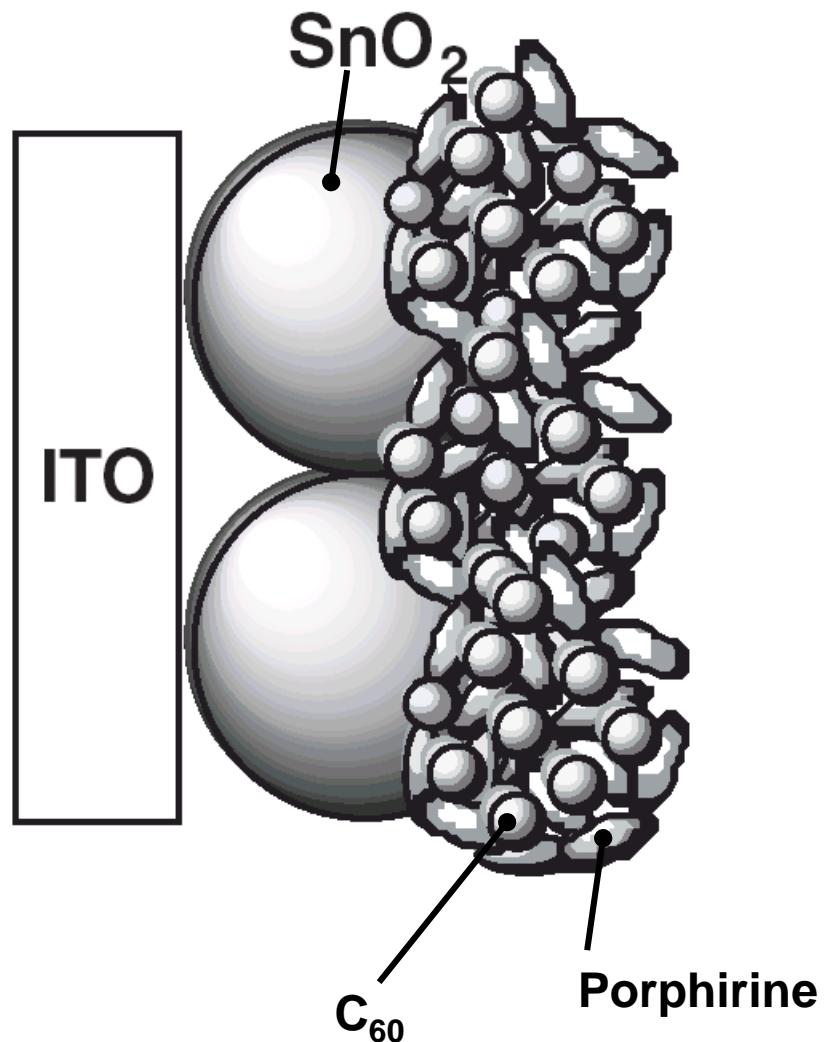
# Fotosintesi artificiale



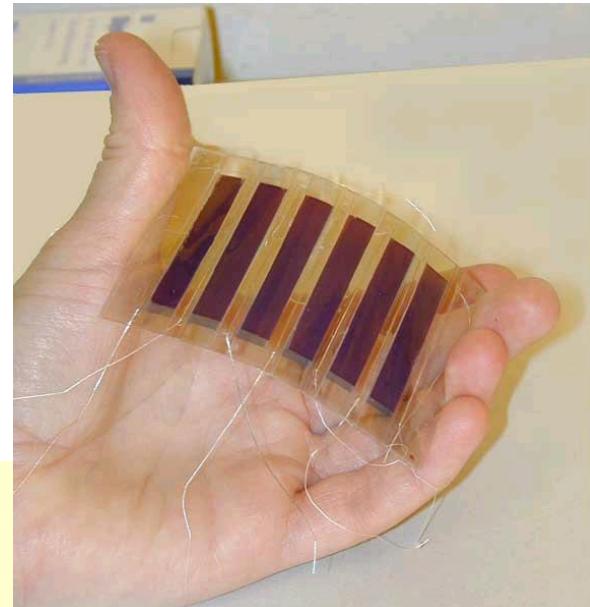
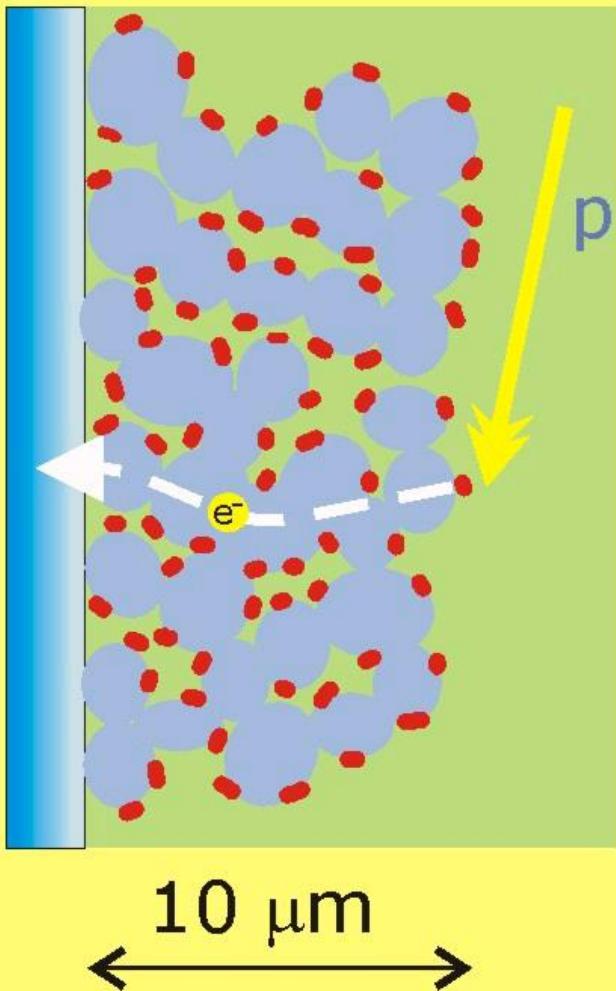
- Quantum yield: 0.5%
- Lifetime 0.77  $\mu$ s
- Loose packaging on the surface

# Fotosintesi artificiale

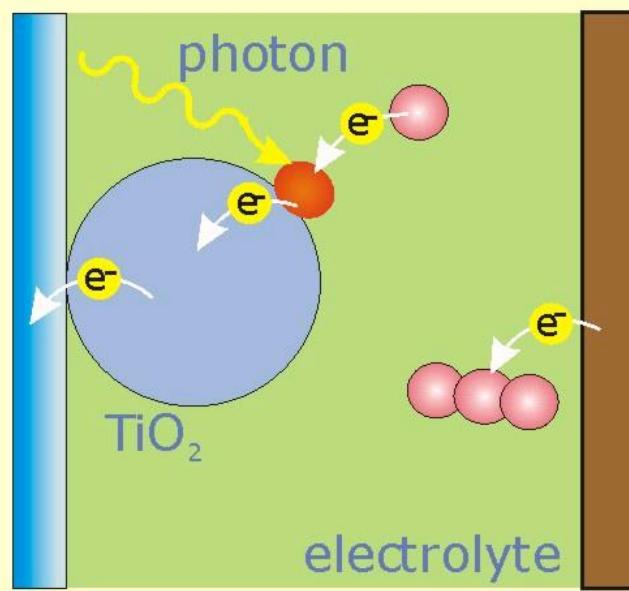
## Assemblaggio gerarchico per un migliore assorbimento



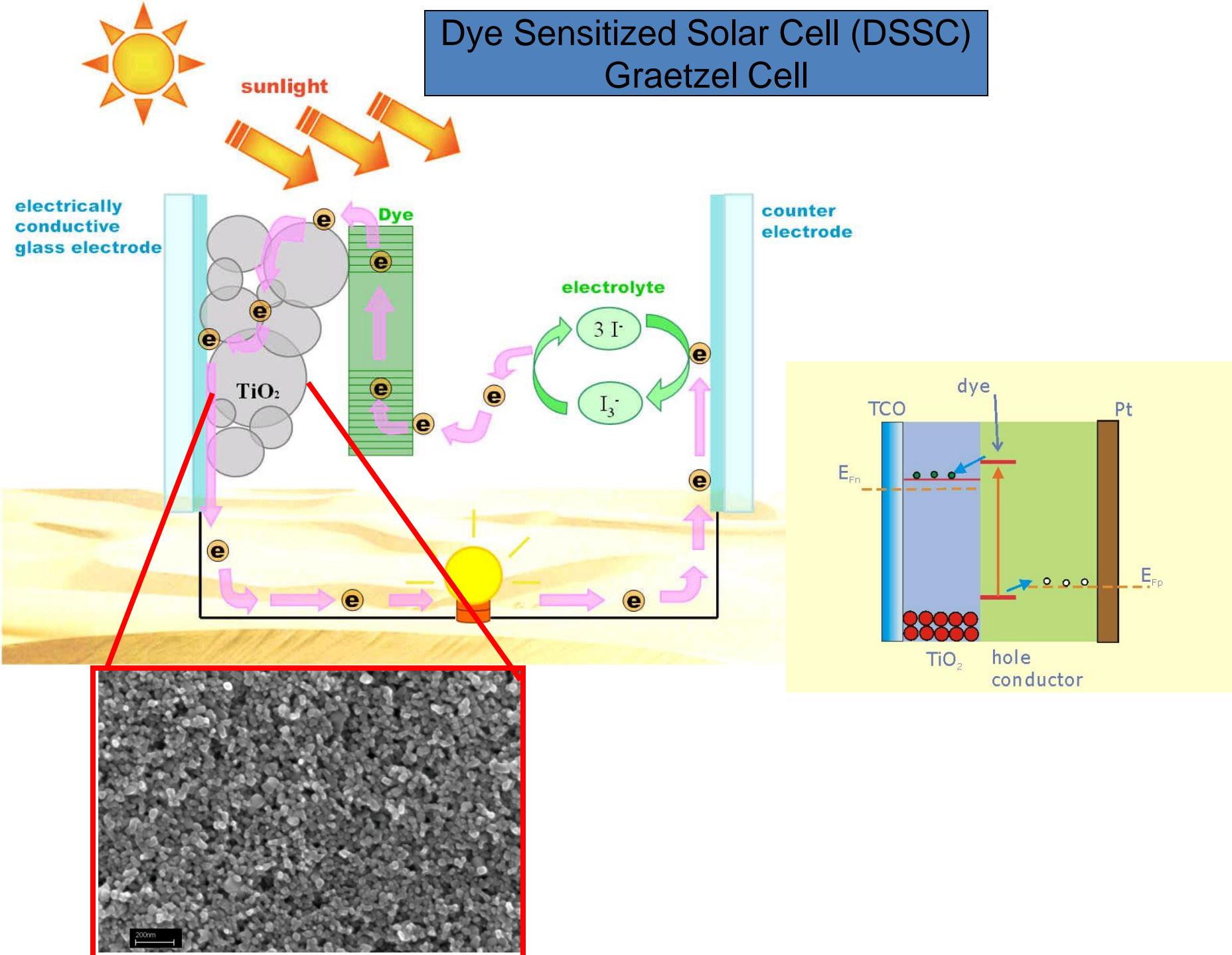
# Dye Sensitized Solar Cell (DSSC) Graetzel Cell



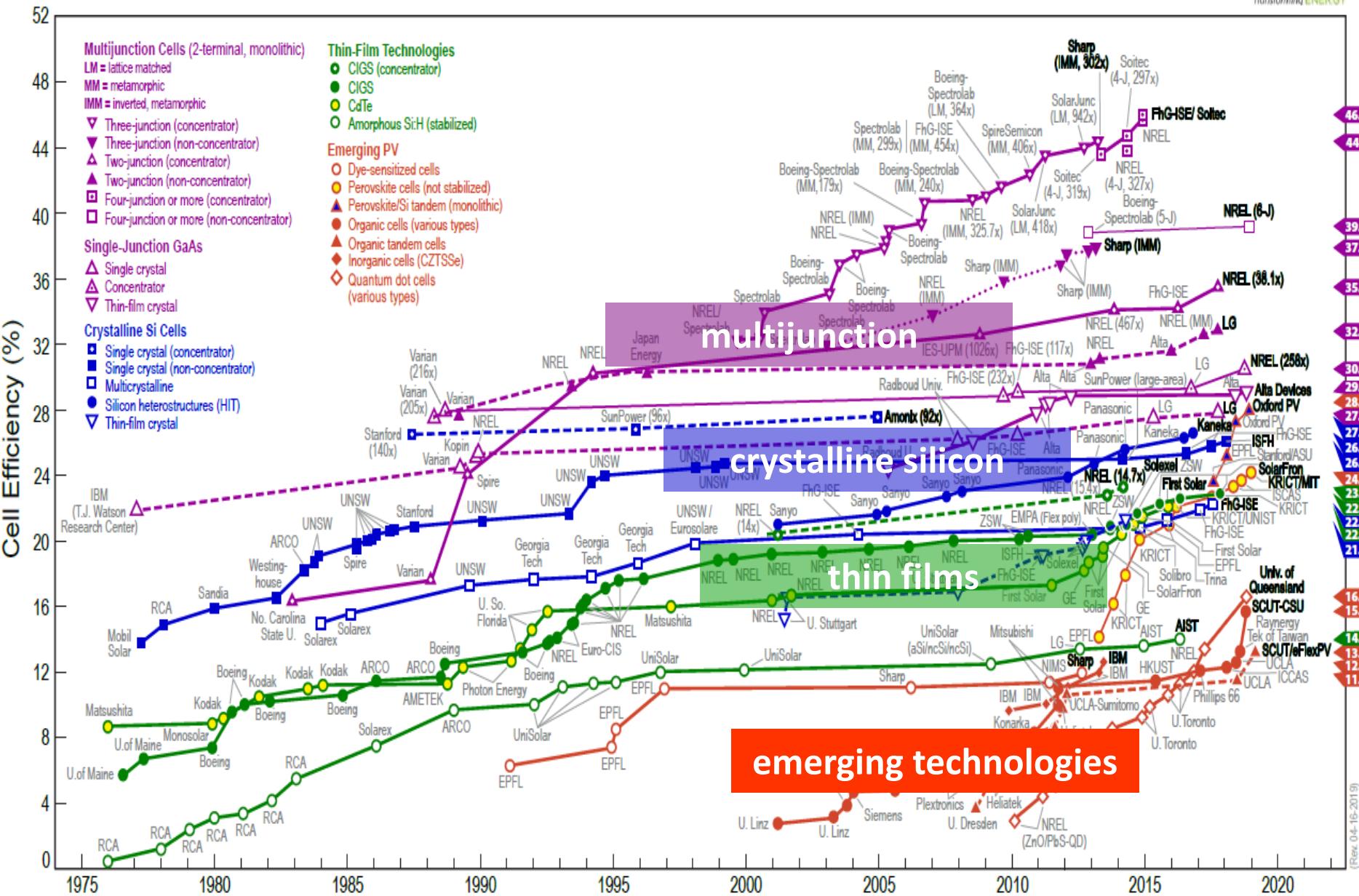
conducting  
substrate



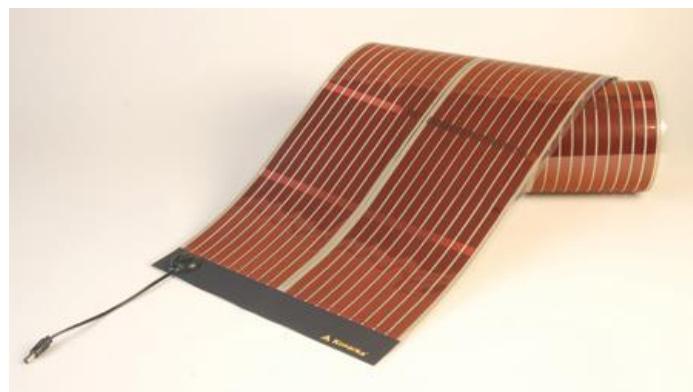
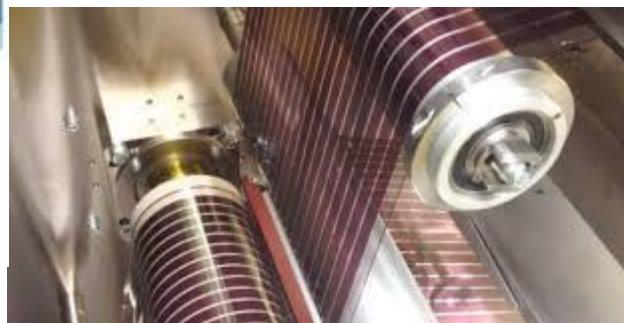
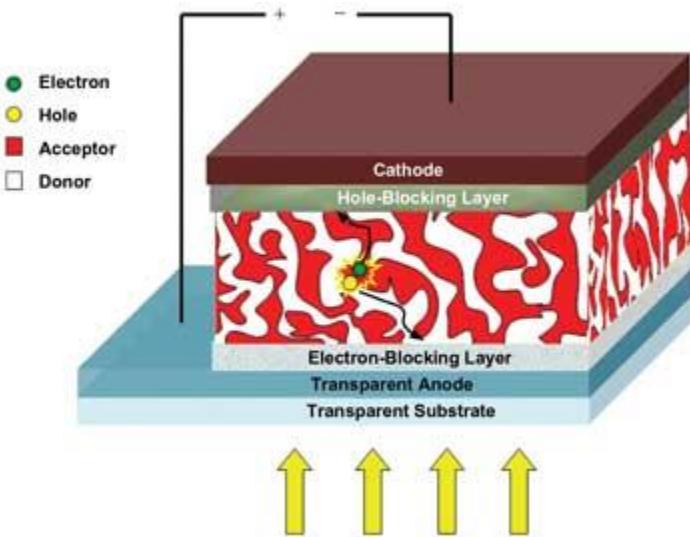
# Dye Sensitized Solar Cell (DSSC) Graetzel Cell



# Best Research-Cell Efficiencies



# Organic photovoltaics - OPV

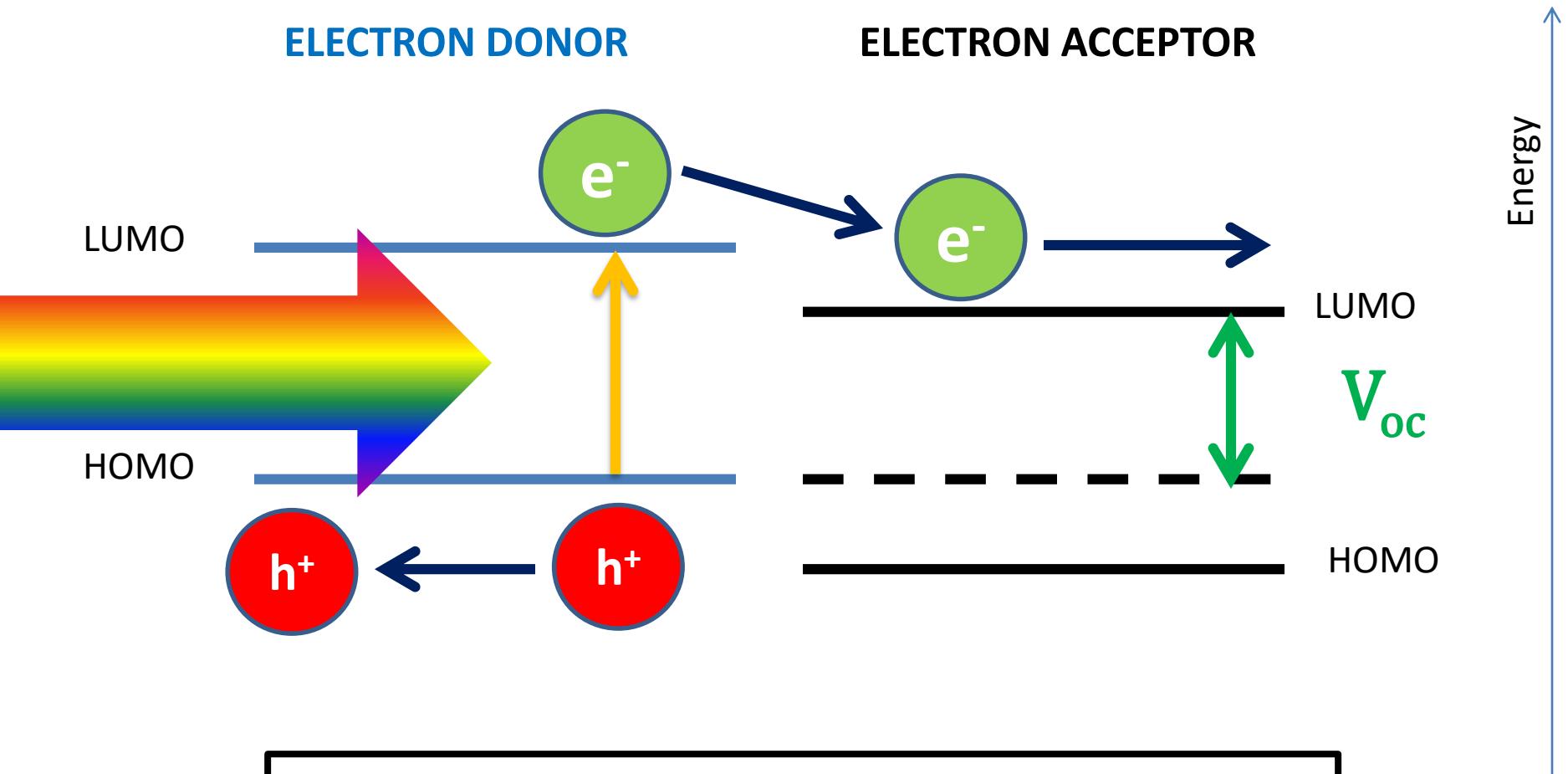


# Why Organic Cells?

- Low cost
- High throughput production
- Flexibility

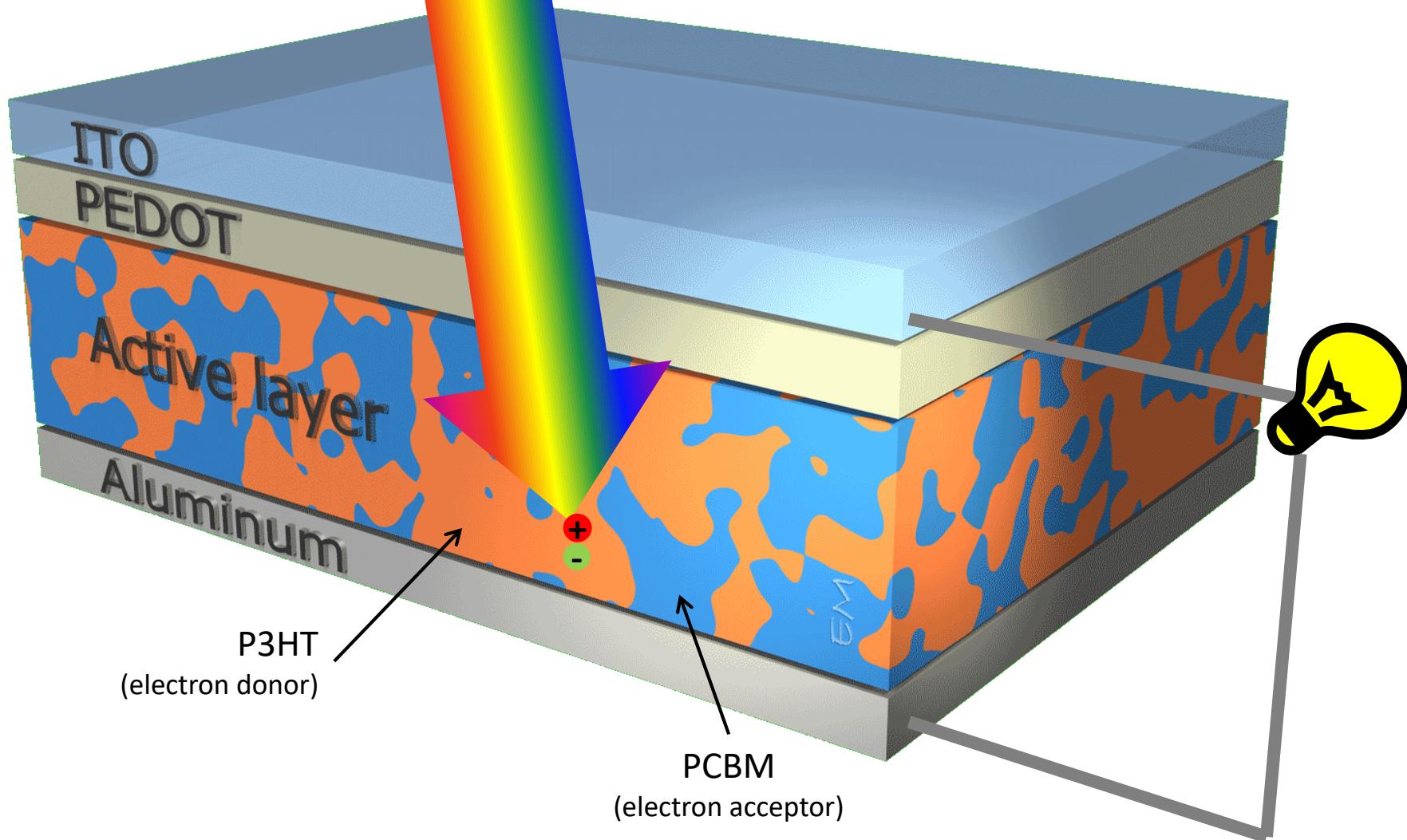


# Physics of Organic Solar Cells

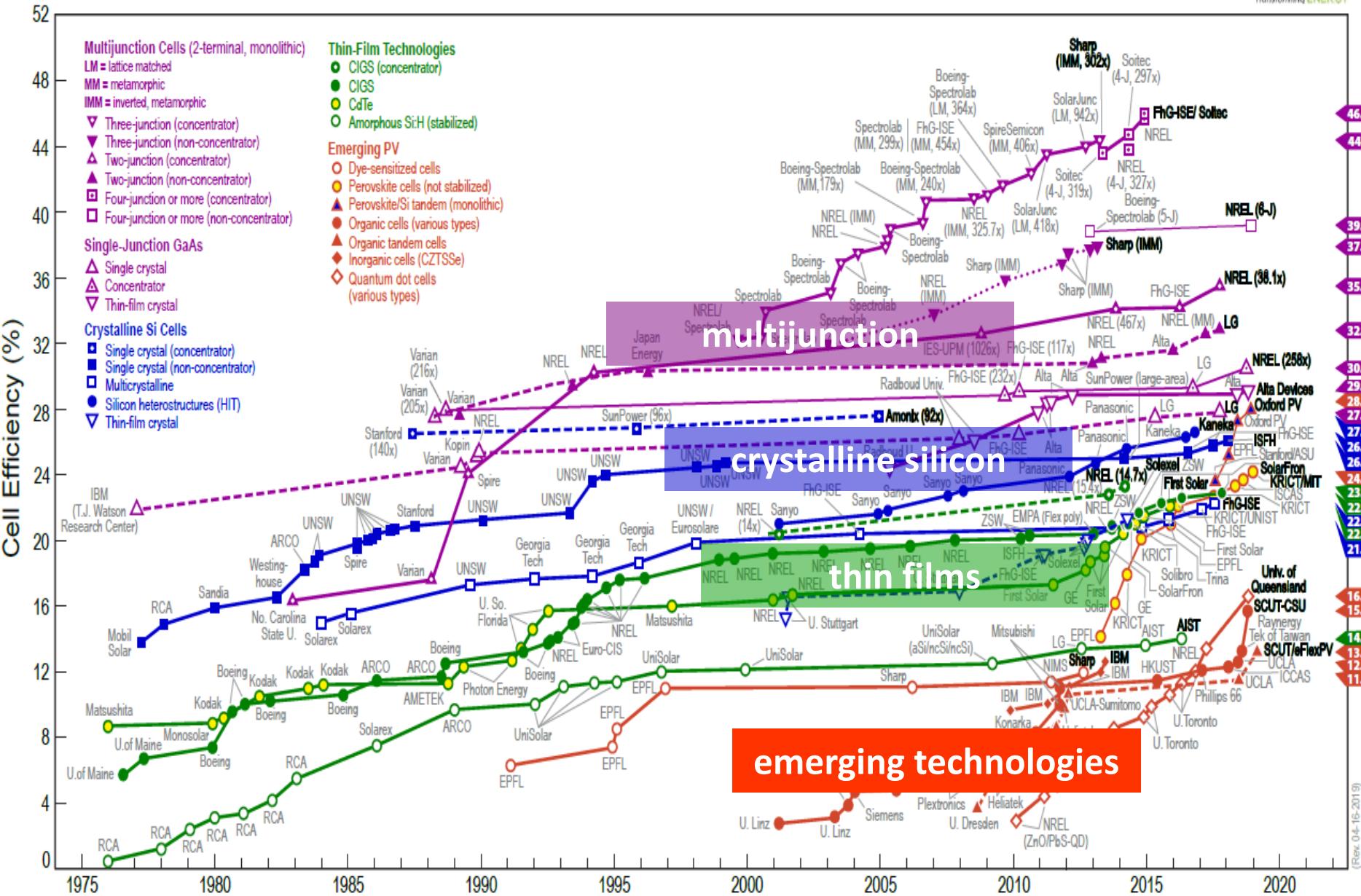


$$V_{oc} = (LUMO_A - HOMO_D) - 0.3 \text{ eV}$$

# Bulk Heterojunction Solar Cells

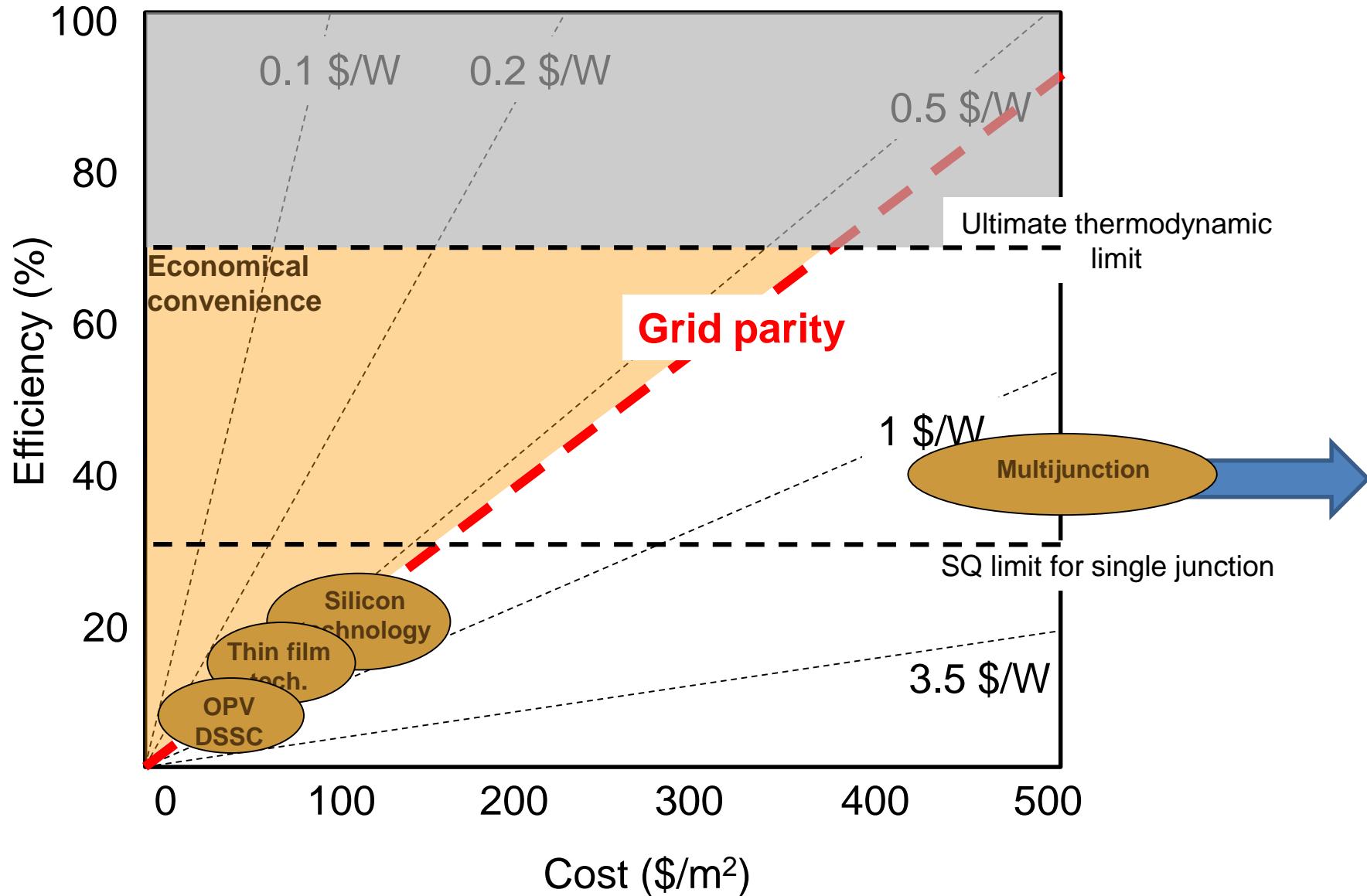


# Best Research-Cell Efficiencies



# DSSC e OPV

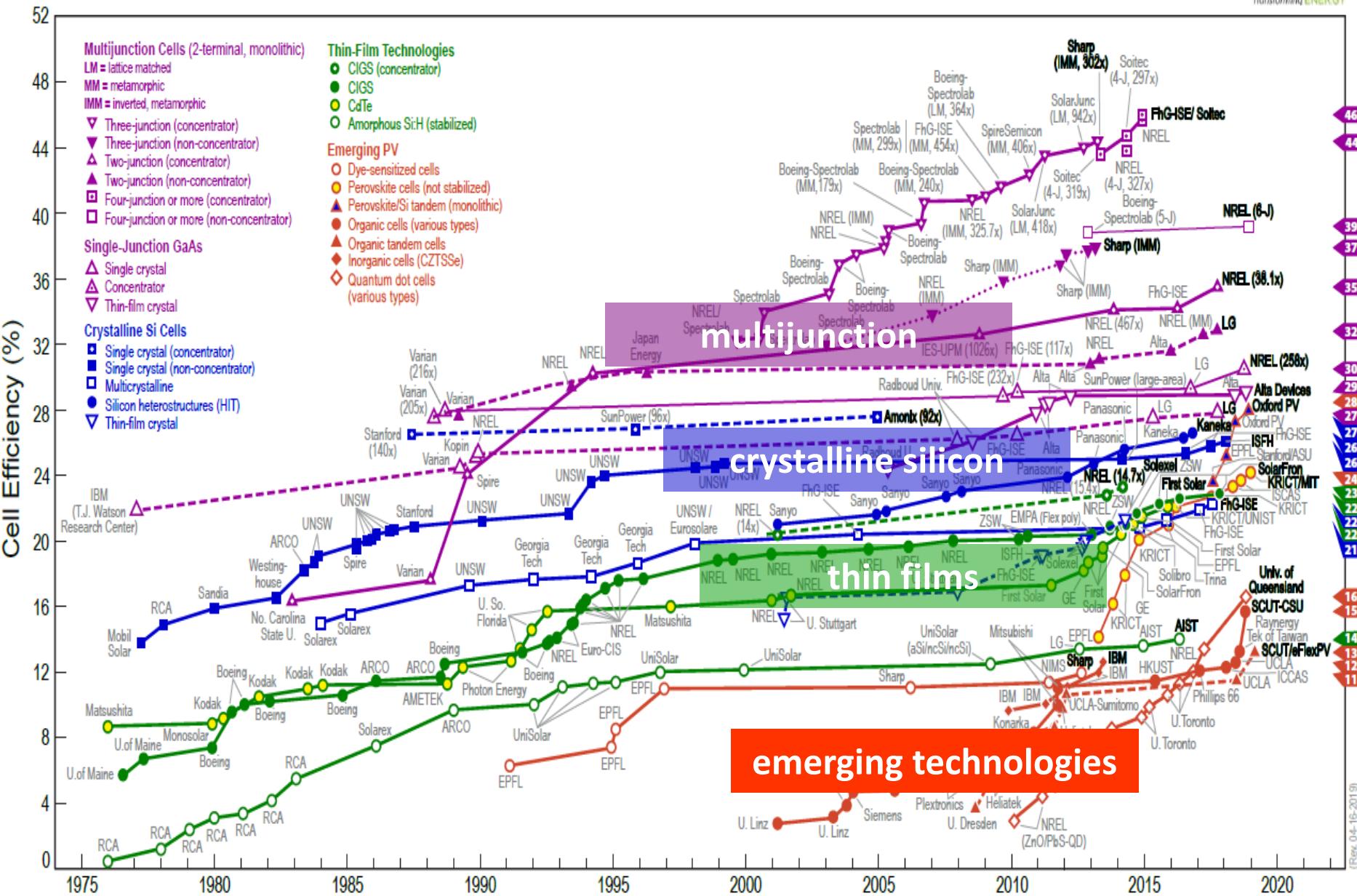
## - Techno-economic positioning -



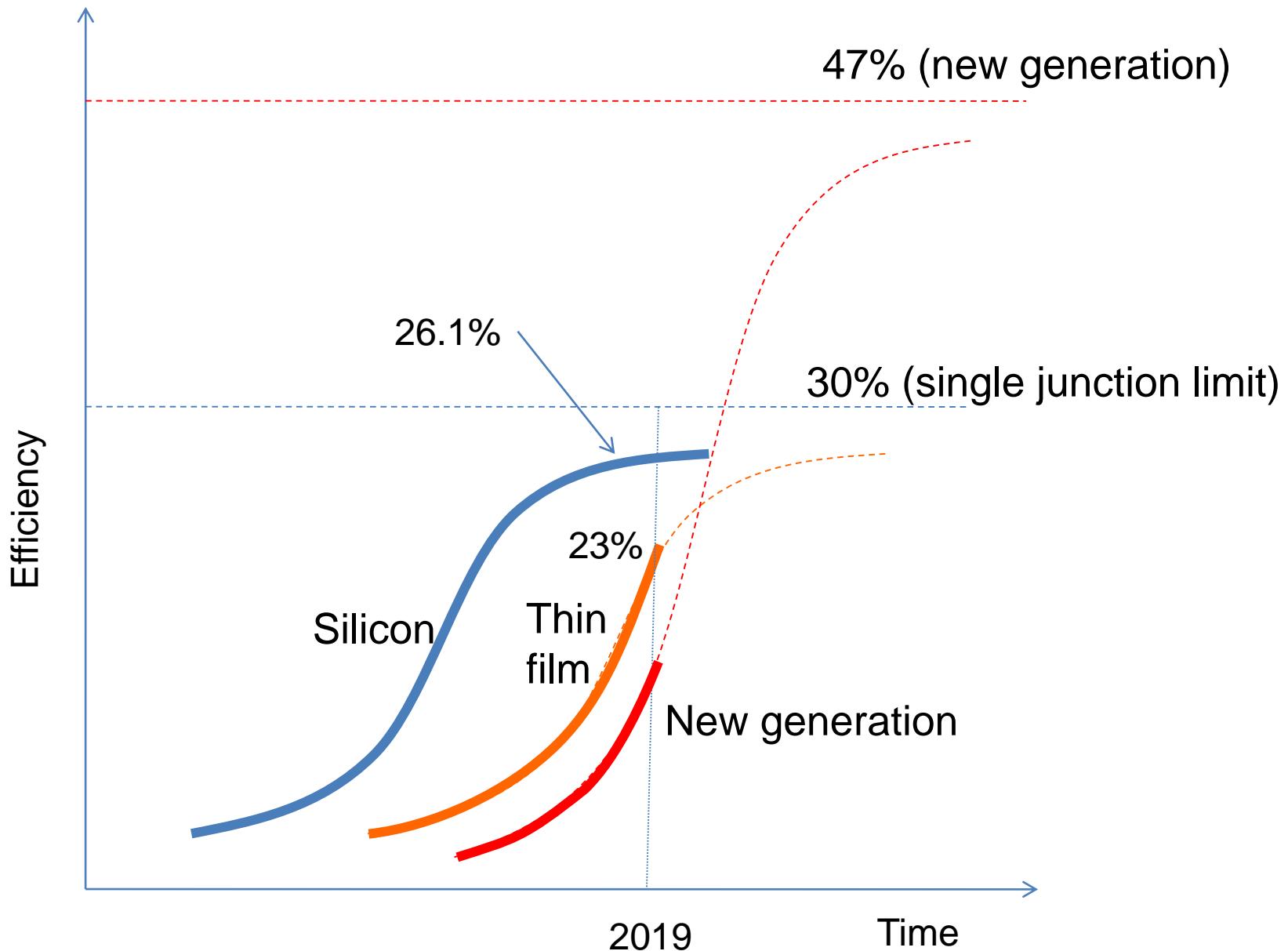
# Photovoltaic technologies: state of the art

## 3. Beyond the frontier - nanotechnology

# Best Research-Cell Efficiencies

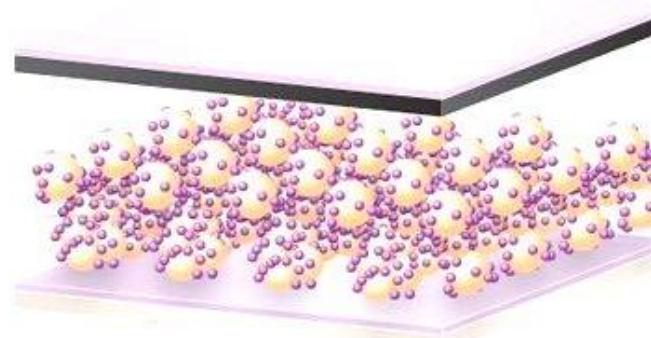


# Enhancement potential

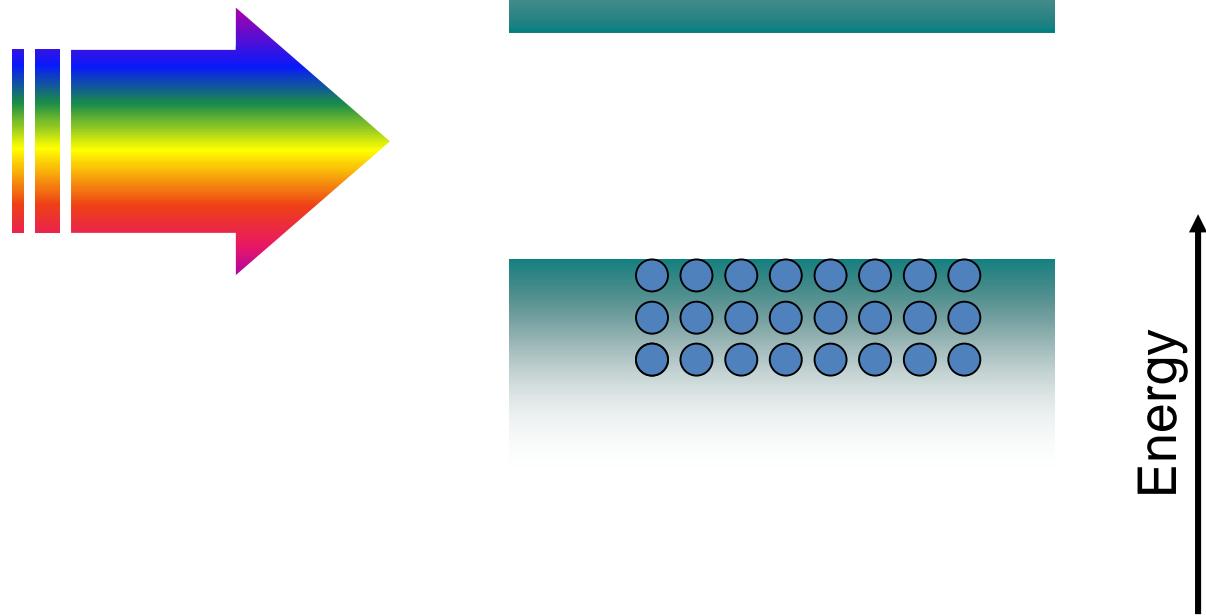


# Nanotechnology and PV: Why?

- Morphologic advantages: nanometric structures have a lot of surface area (e.g. *DSSC*)
- The optoelectronic properties of materials are dominated by phenomena occurring at the nanoscale → we need to engineer the nanostructure of materials
- Nanoscale phenomena are governed by quantum mechanics → nanomaterials can exploit untapped physics at the macroscale (e.g. *intermediate band*)

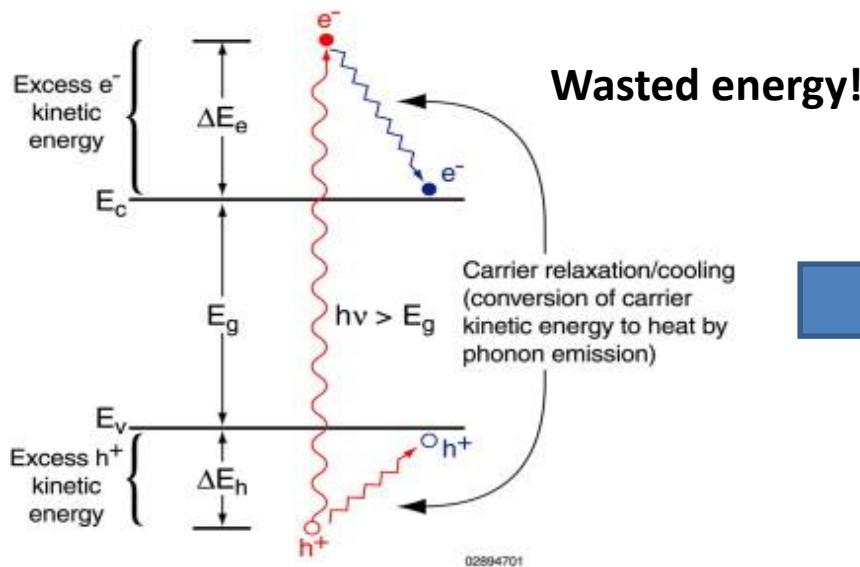


# Thermalization of electrons: wasted energy!



# Nanotech and Photovoltaics:

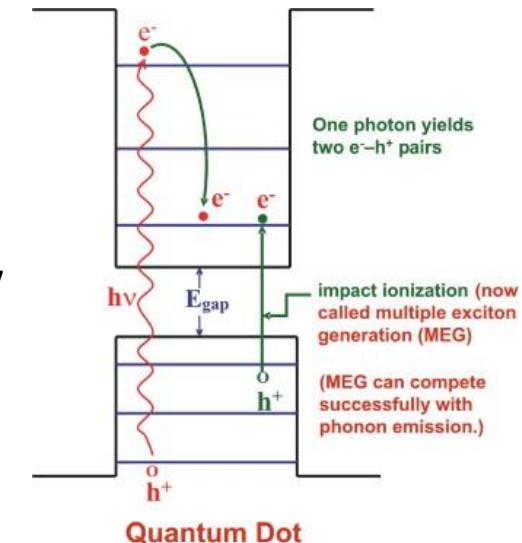
- Better use of high-energy photons: MEG (Multiple Exciton Generation) -



Wasted energy!

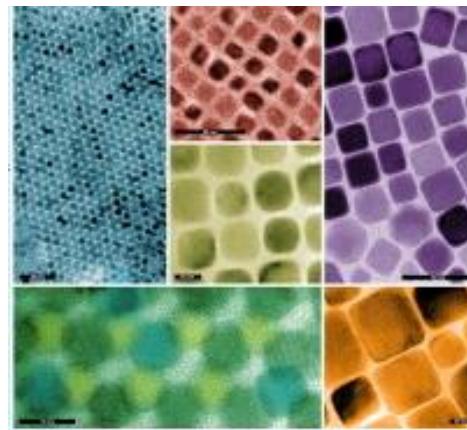
Carrier relaxation/cooling  
(conversion of carrier  
kinetic energy to heat by  
phonon emission)

Exploiting  
high-energy  
photons

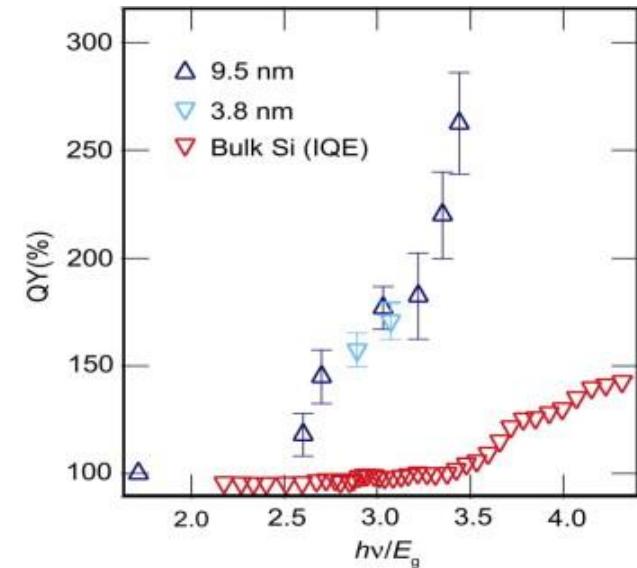


Quantum Dot

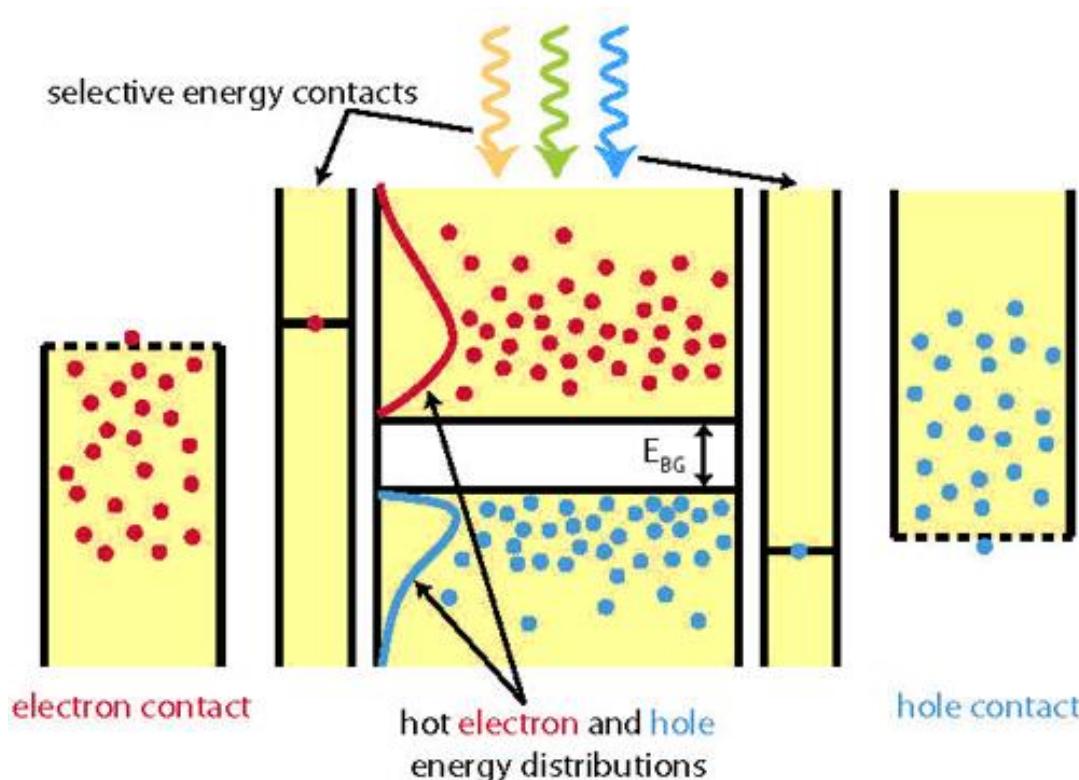
Limiting efficiency: 45%  
(86.6% under concentration)



Special nanoparticles (quantum dots) favor the  
generation of more than one electron per photon



# Using High Energy Photons: Hot Electron Extraction

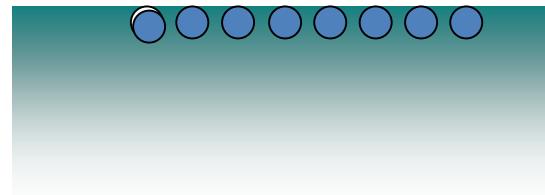
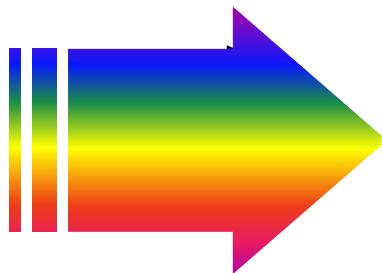


PV Kamat, Nature Chemistry 2 p809 (2010)

A. Pandey, P. Guyot-Sionnest\*, J. Phys. Chem. Lett. 1 p45–47 (2010)

JA McGuire et al., ACS Nano 4, p6087 (2010)

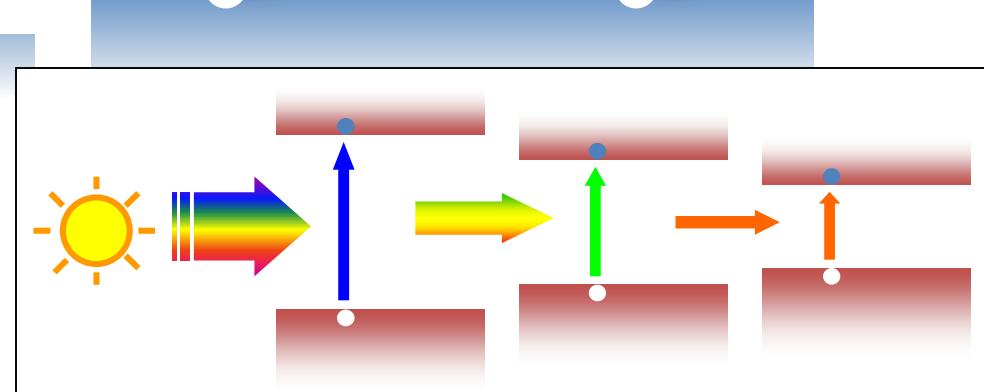
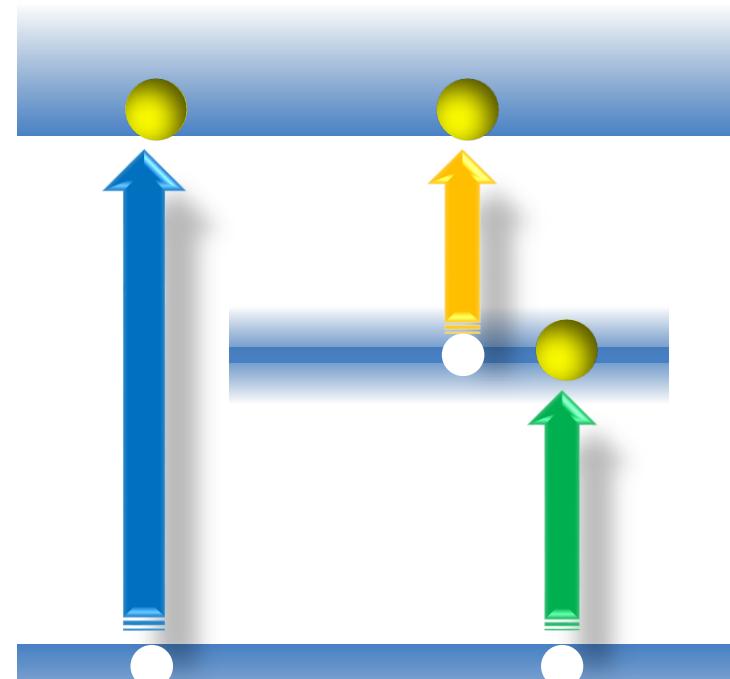
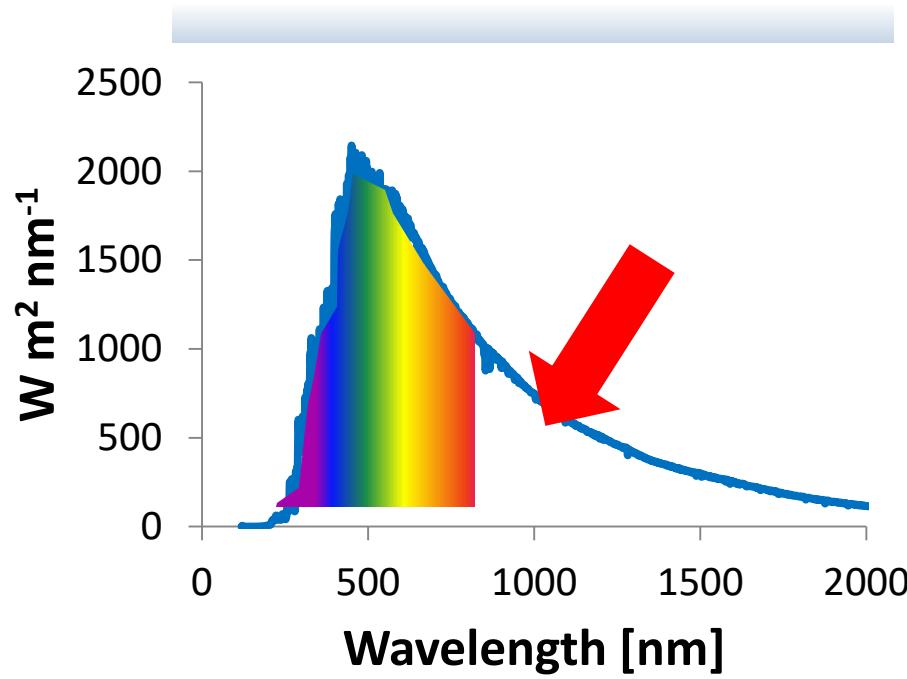
# Low energy photons are lost



Energy ↑

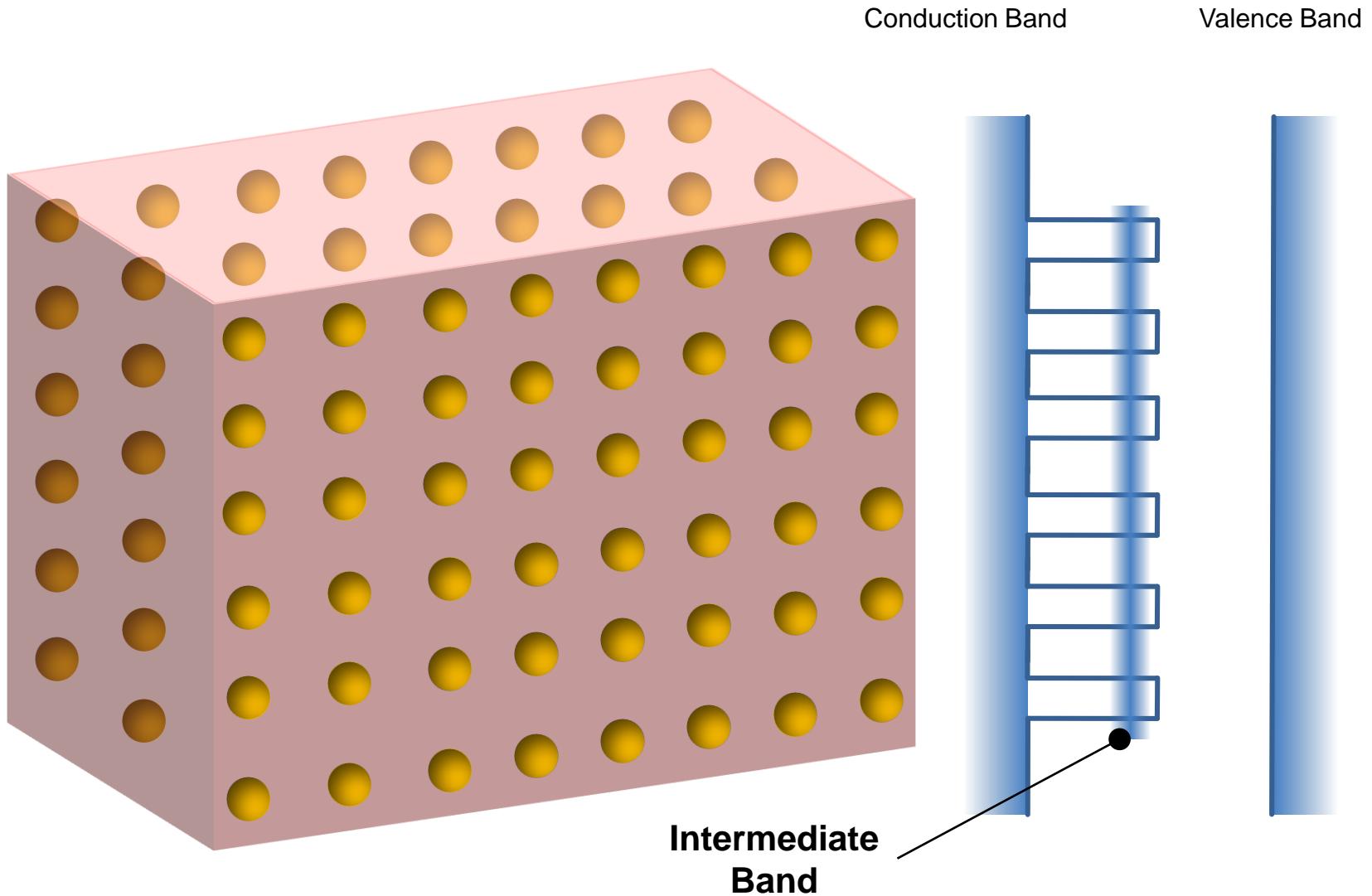
# Beyond the single junction limit

- Intermediate Band Materials: Using Low Energy Phonons-

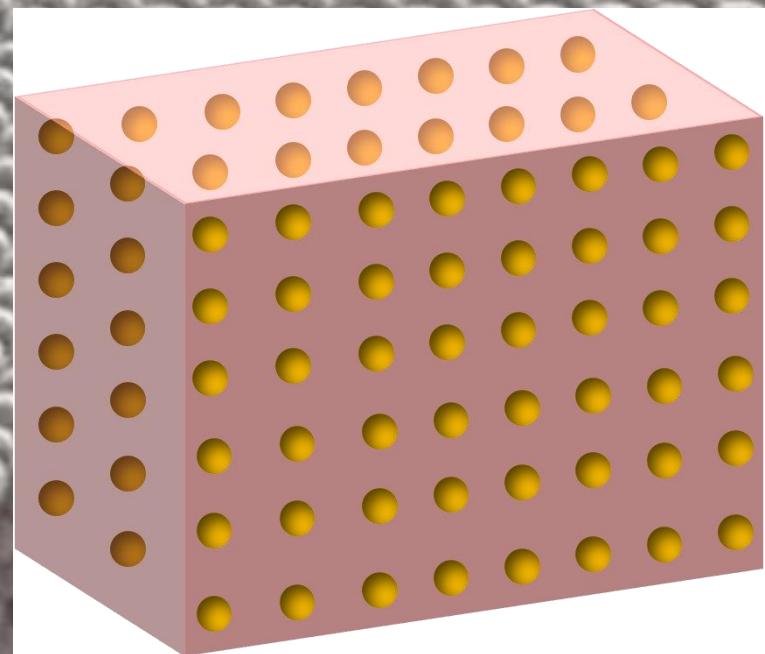
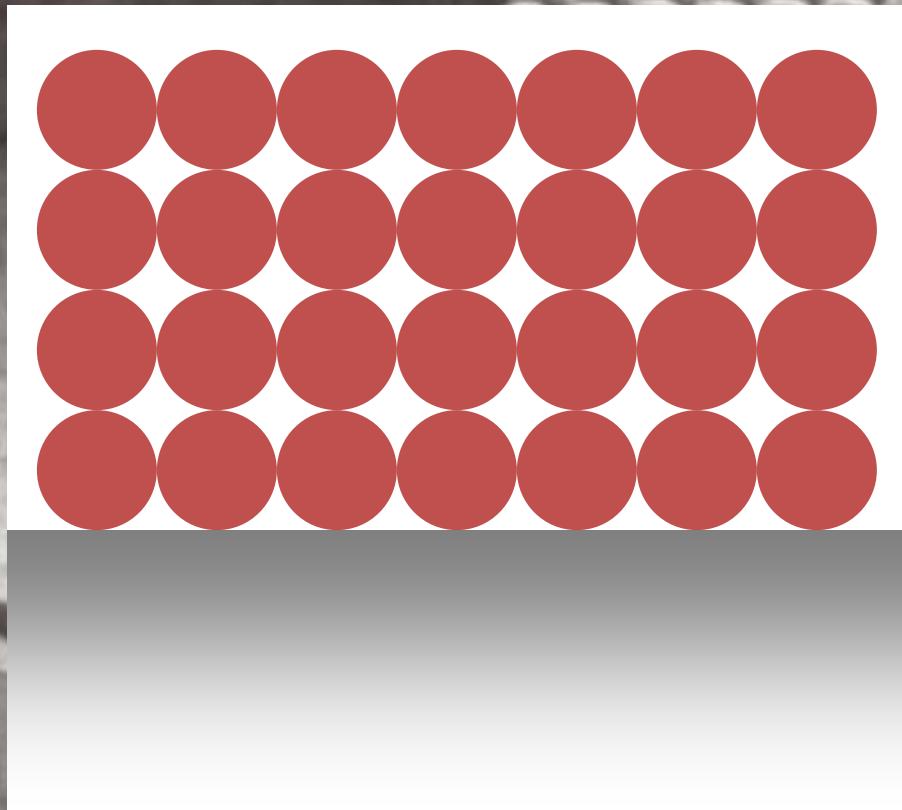


# Making an Intermediate Band Material

Quantum dots embedded in a semiconductor



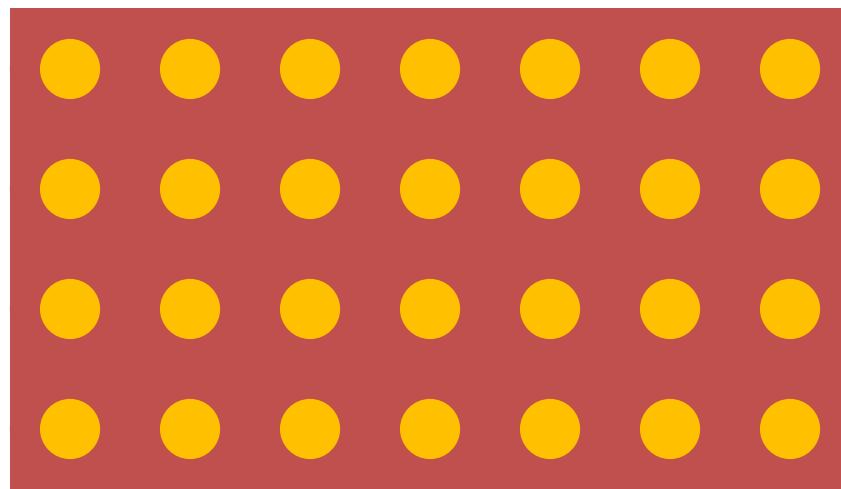
# Assemblying Quantum Dots into Colloidal Solid Films



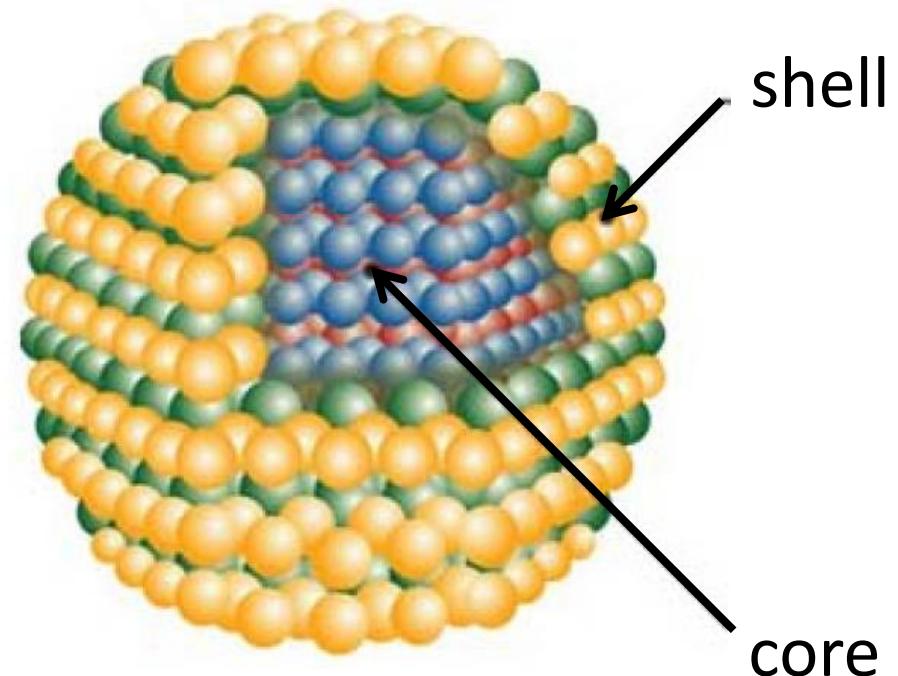
5  $\mu\text{m}$

# From a Colloidal Solid to a Dense Nanostructured Film

Use Core/Shell Nanocrystals

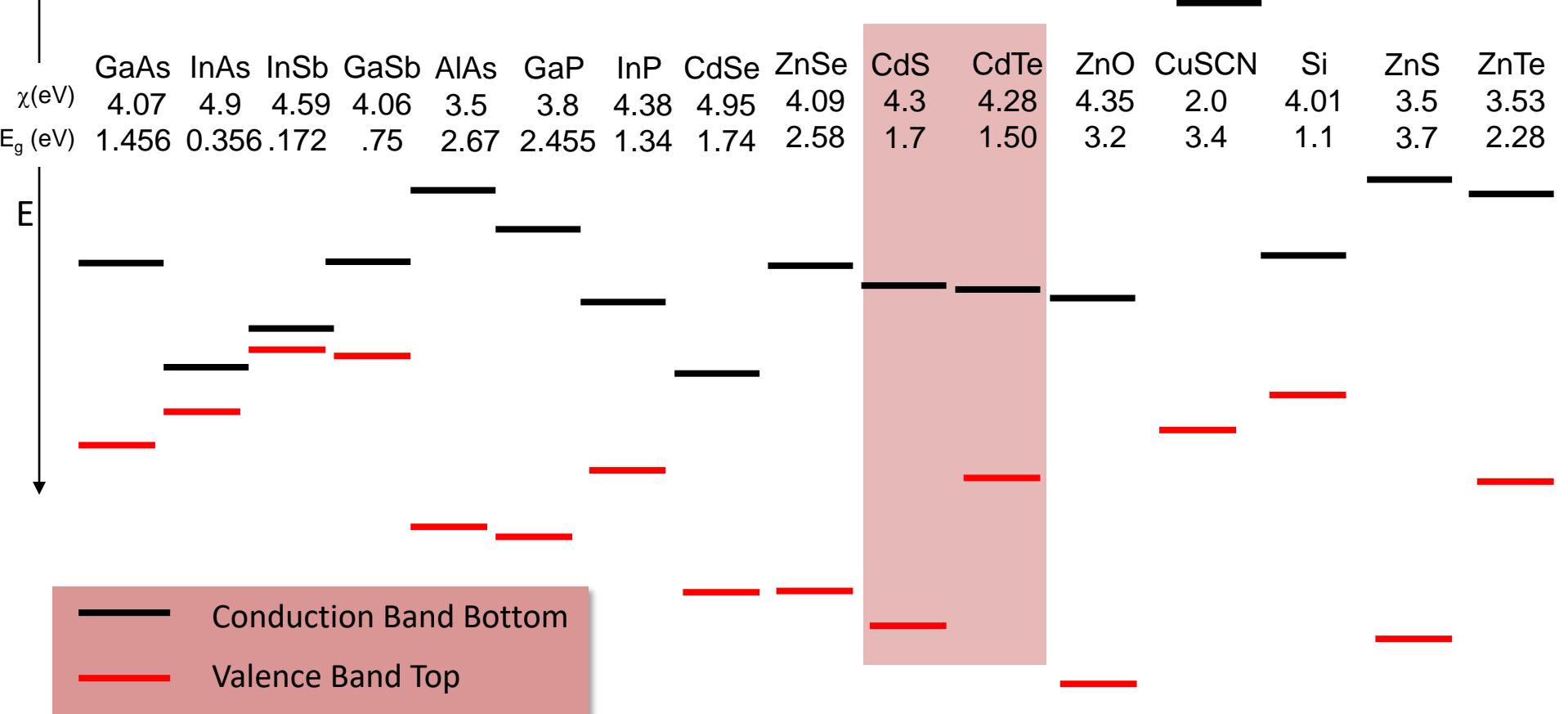


Thermal Treatment



# Materials System Selection

$E=0$



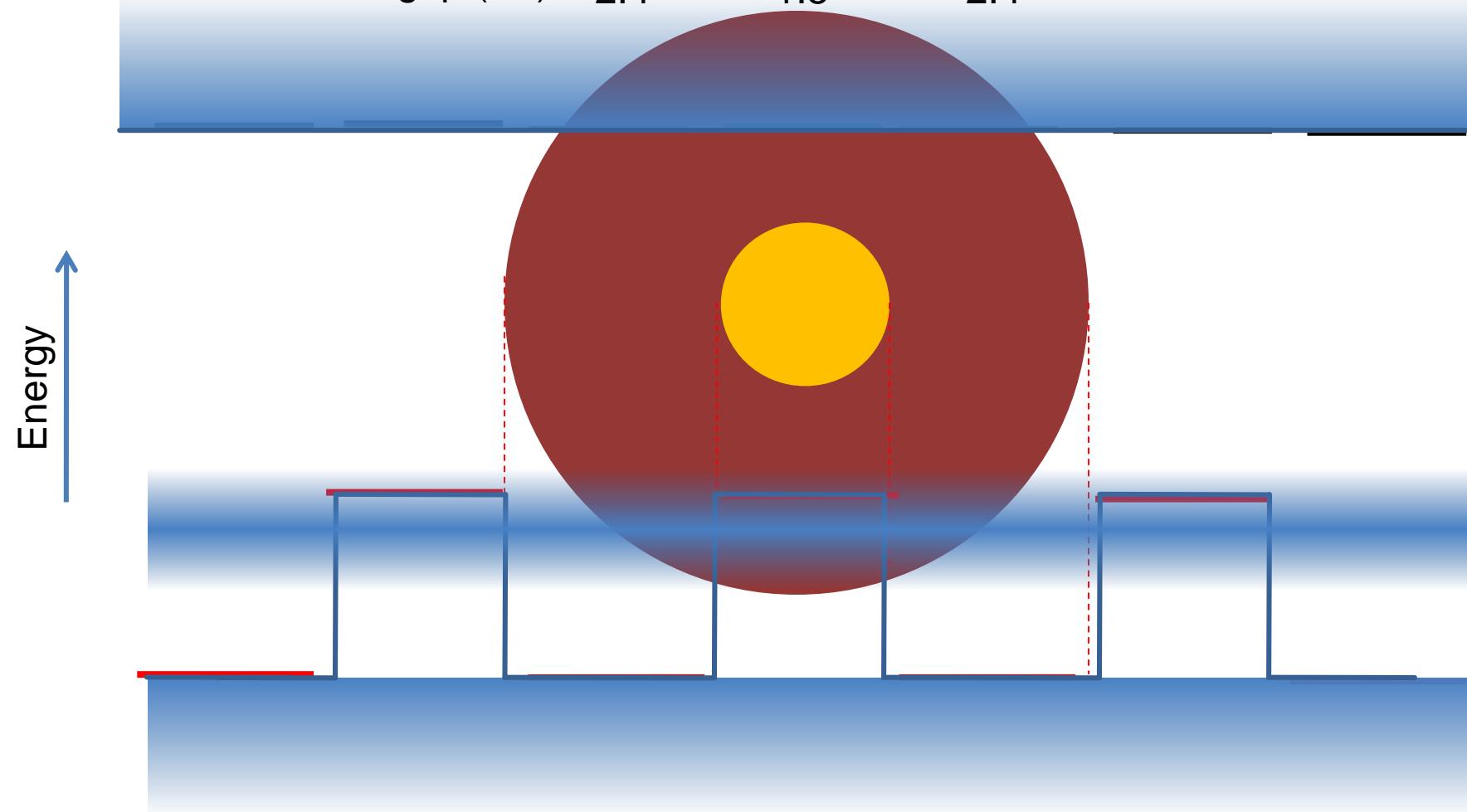
RK Swank, *Phys. Rev.* **153**, 844 (1967)

Goldberg Yu.A. *Handbook Series on Semiconductor Parameters*, vol.1, M. Levinshtein, S. Rumyantsev and M. Shur, ed., World Scientific, London, 1996.

S. Adachi, *Properties of Group IV, III-V and II-VI Semiconductors*, Wiley 2005

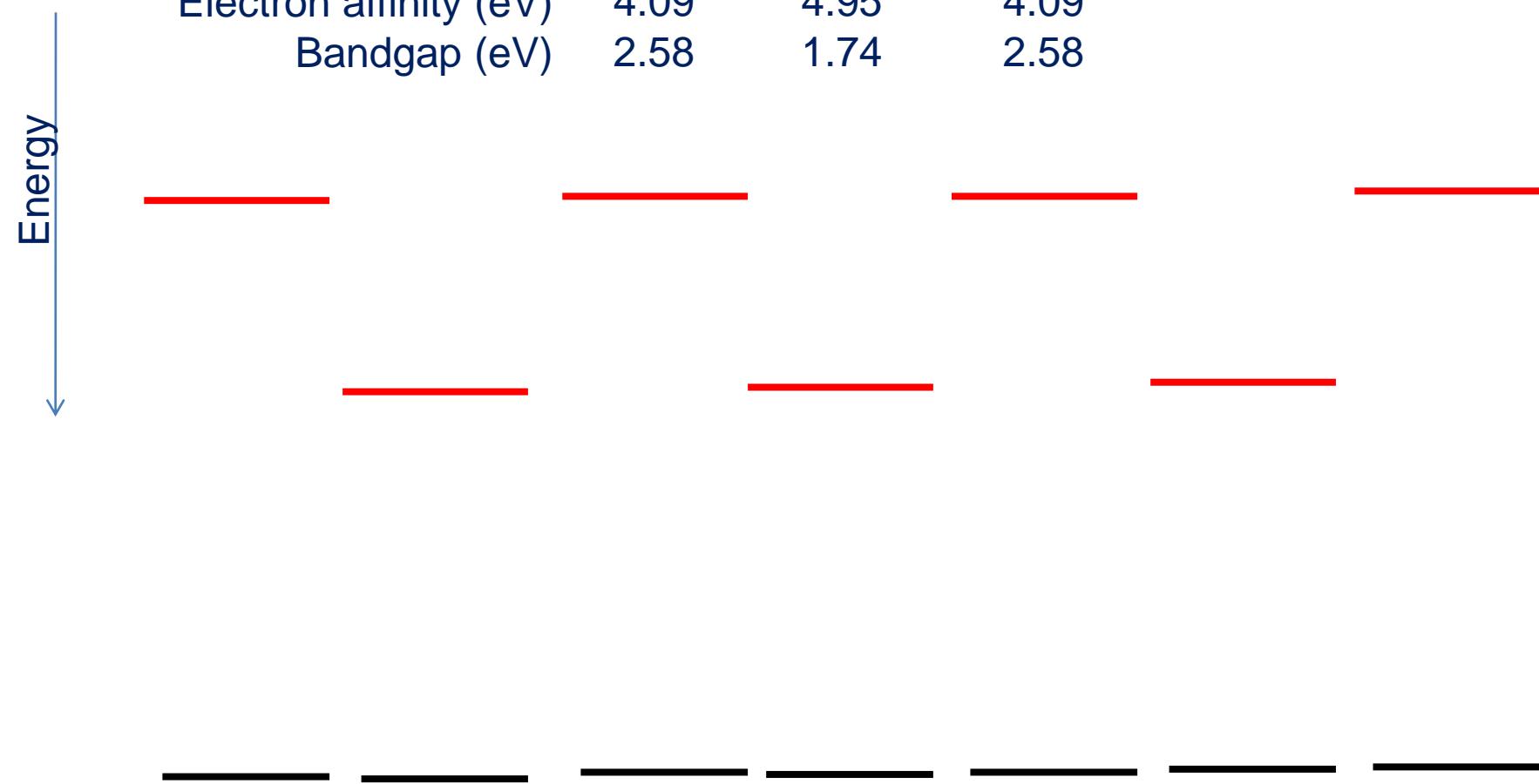
# Materials System Selection: Energy Level Alignment

	CdS	CdTe	CdS
Electron affinity (eV)	4.5	4.5	4.5
Bandgap (eV)	2.4	1.5	2.4

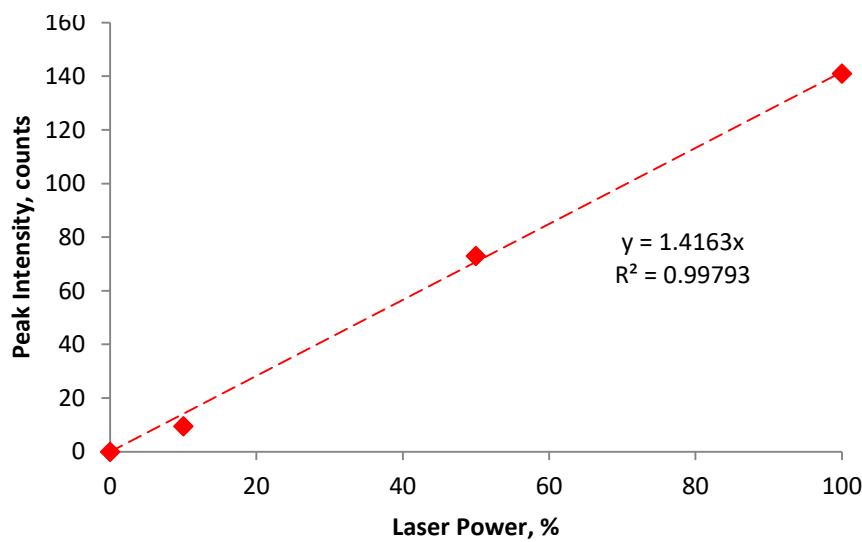
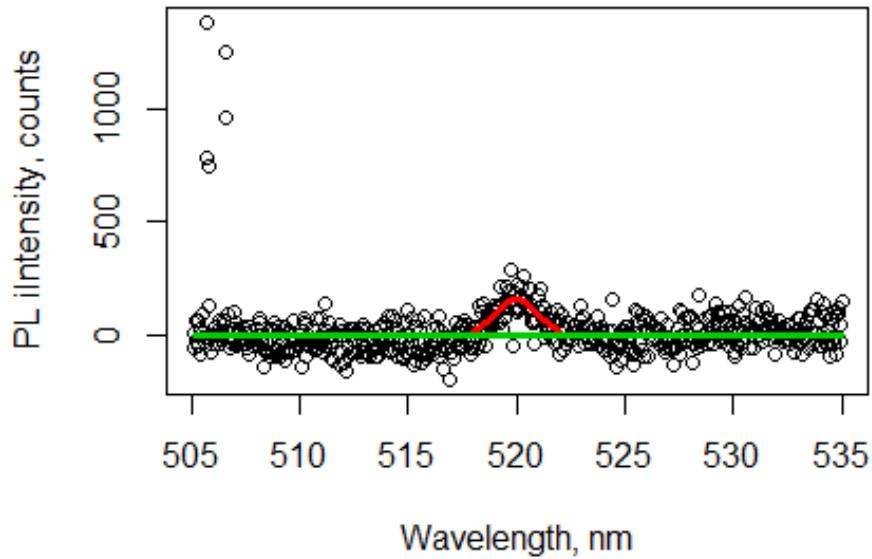


# Materials System Selection: Energy Level Alignment

	ZnSe	CdSe	ZnSe
Electron affinity (eV)	4.09	4.95	4.09
Bandgap (eV)	2.58	1.74	2.58

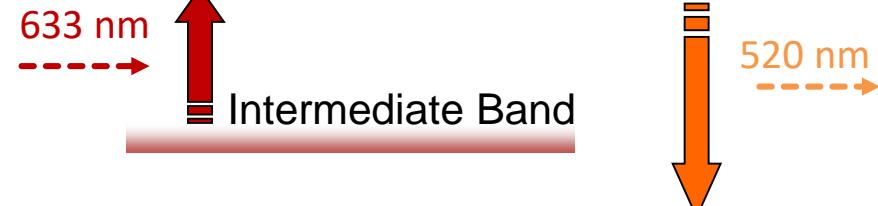


# Intermediate Band Materials: Evidence of Upconversion



CdSe@CdS heterosystem

Conduction Band



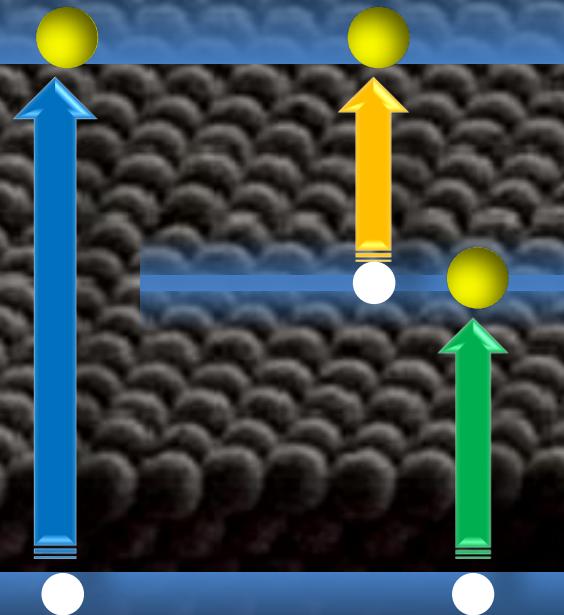
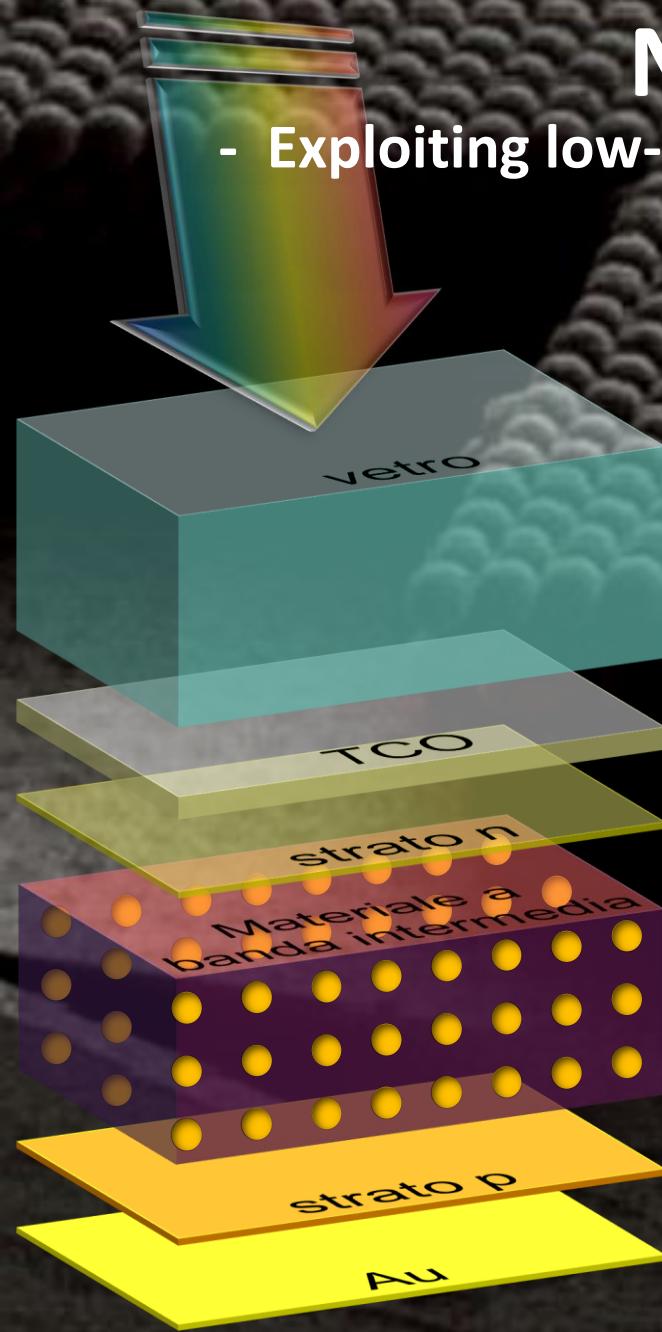
Valence Band

Slejko, PhD Thesis

Slejko, Lugh et al., in prep.

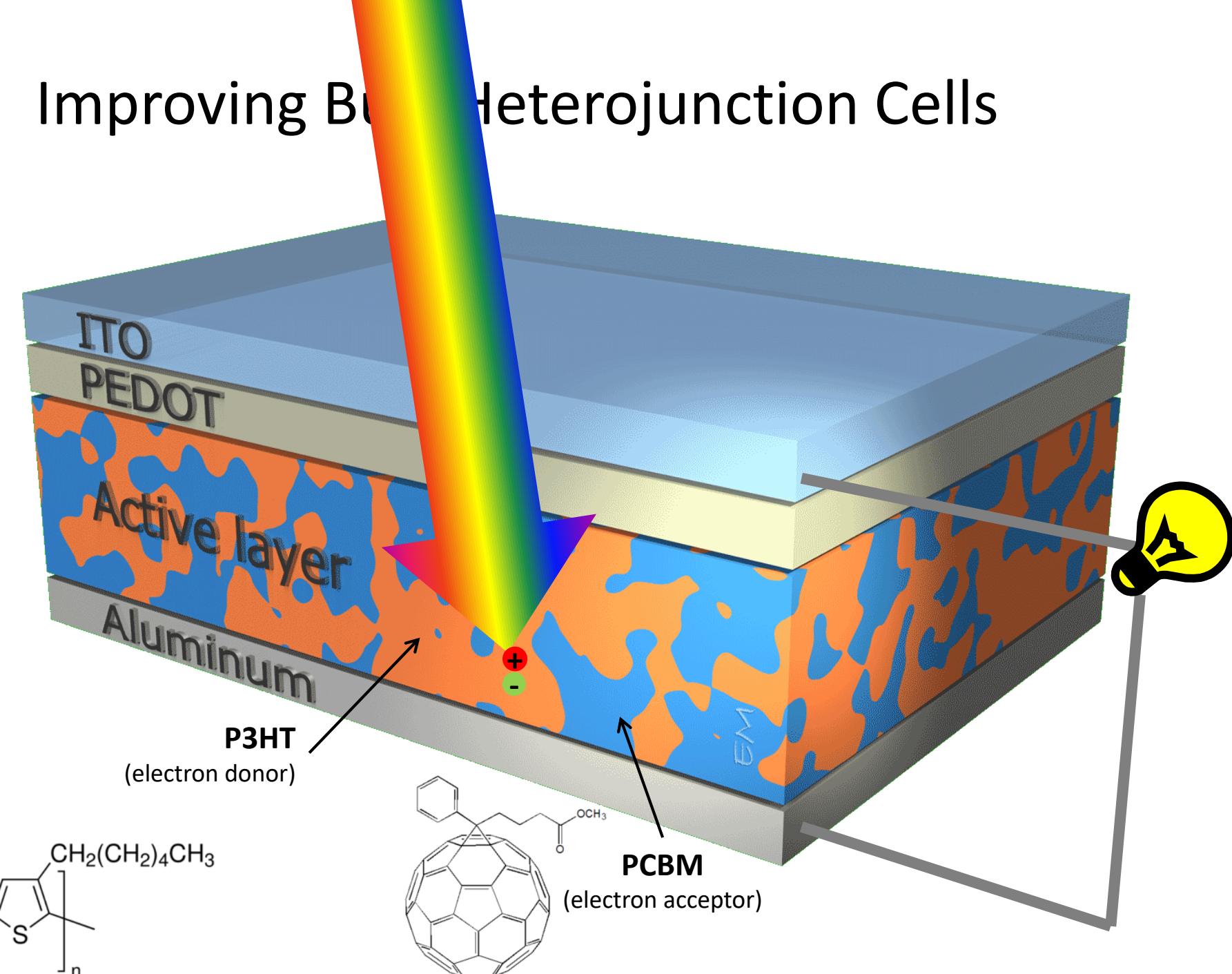
# Nanotech and Photovoltaics:

- Exploiting low-energy photons: Intermediate Electronic Band-

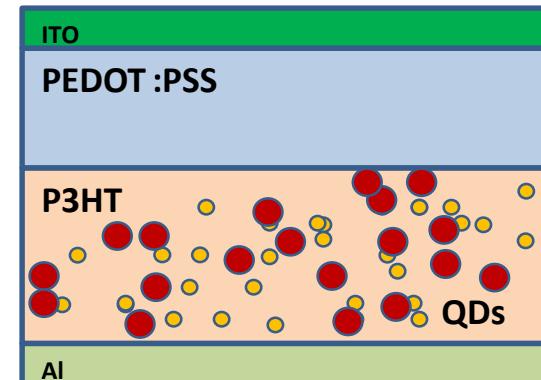
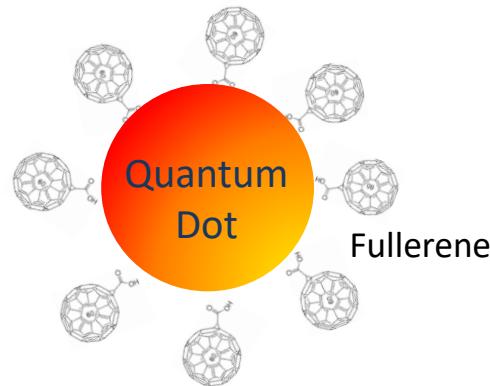
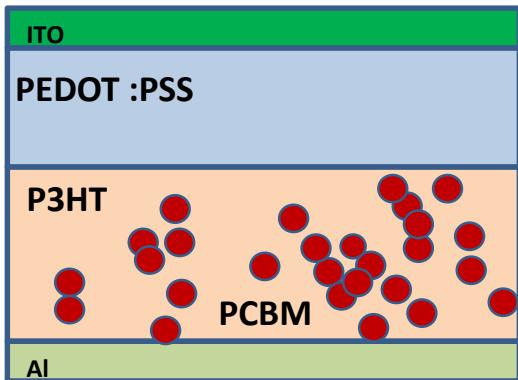


5  $\mu$ m

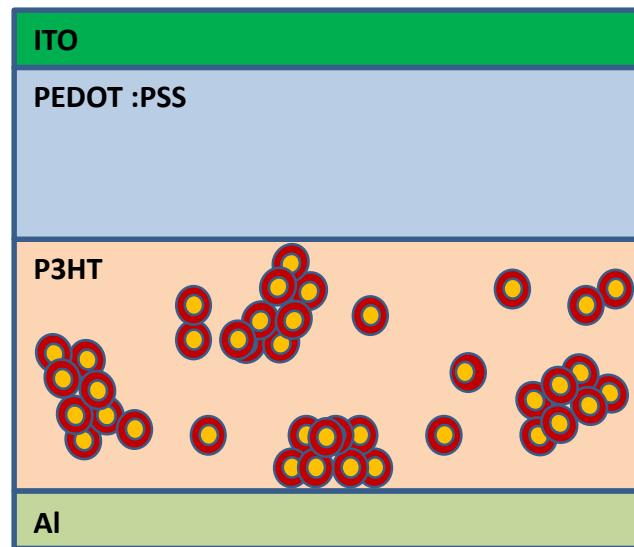
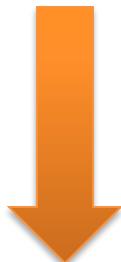
# Improving Bulk Heterojunction Cells



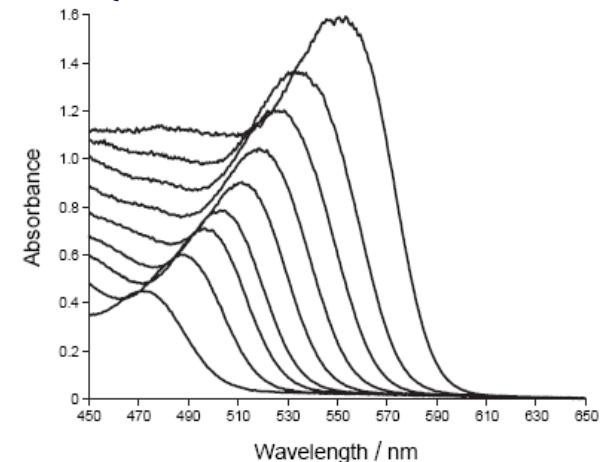
# State of the Art and Founding Idea



**Fullerenes**  
(e.g. PCBM)



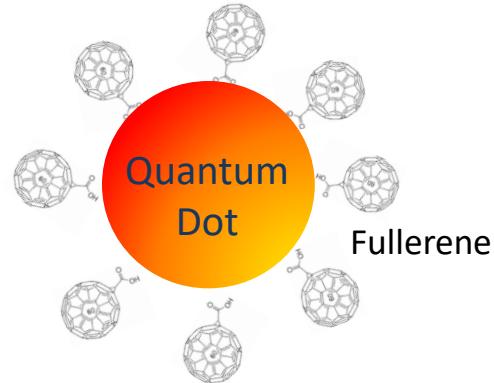
**Quantum dots**



**TRANSPORT**

**ENHANCED  
ABSORPTION**

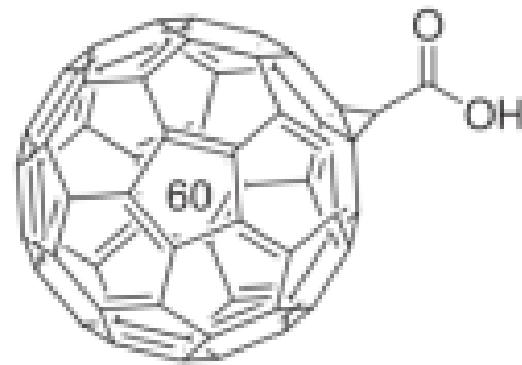
# Quantum dot + Fullerene Hybrid: CdSe@C<sub>61</sub>



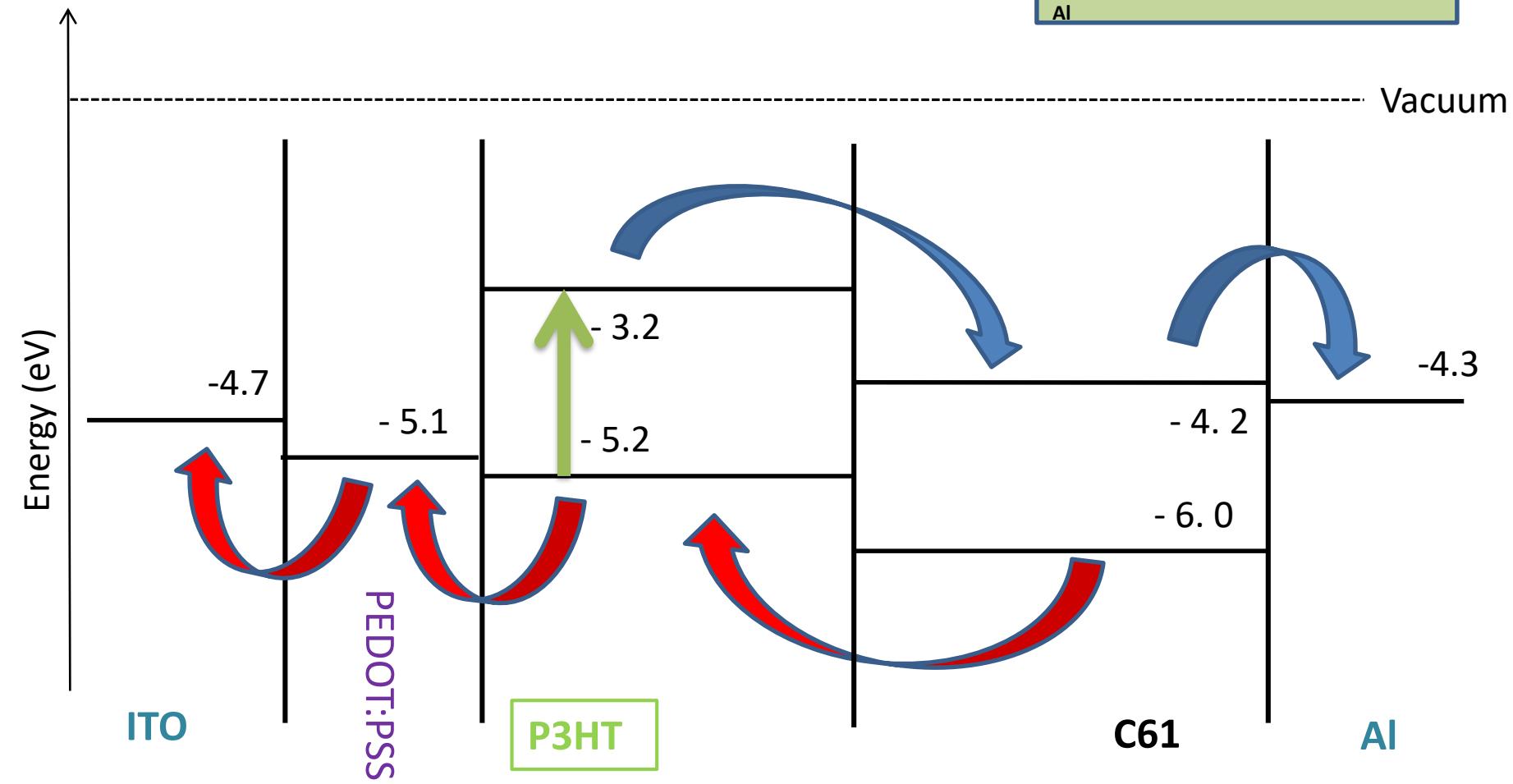
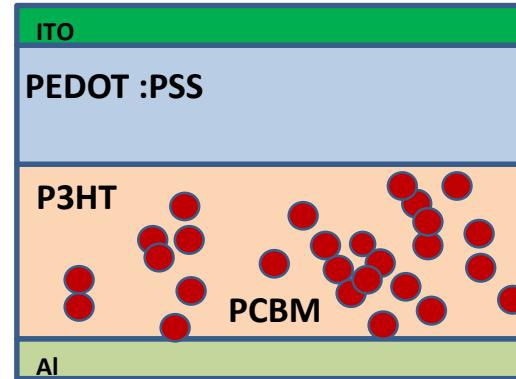
CdSe Quantum Dots

+

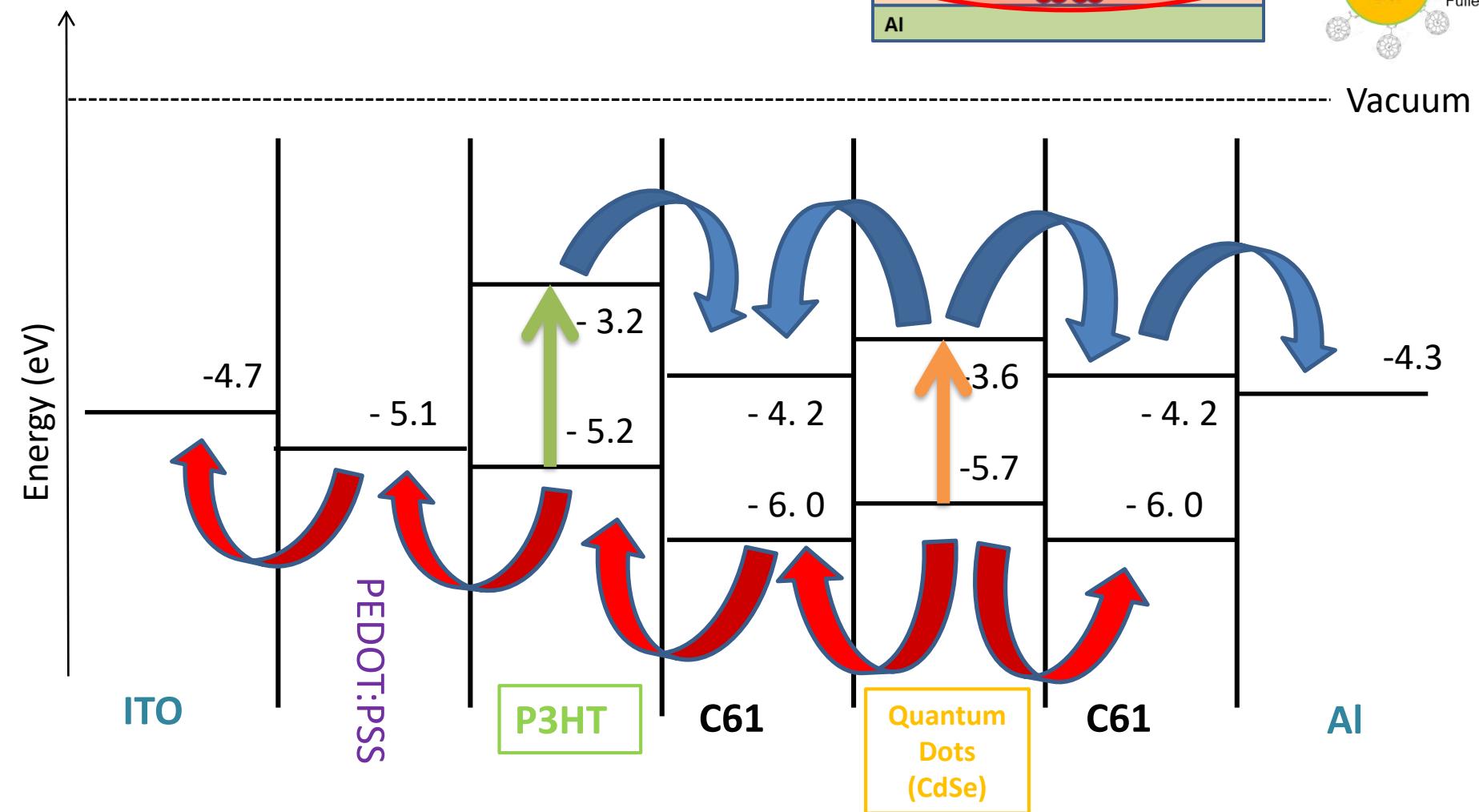
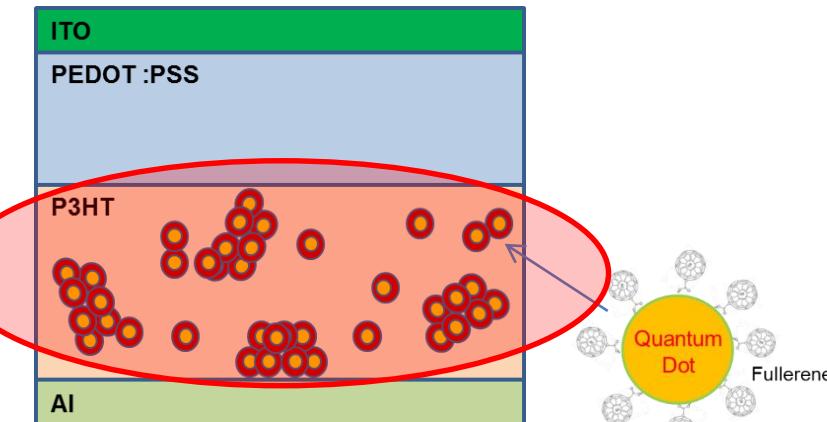
(1,2-Methanofullerene C<sub>60</sub>)-61-carboxylic acid



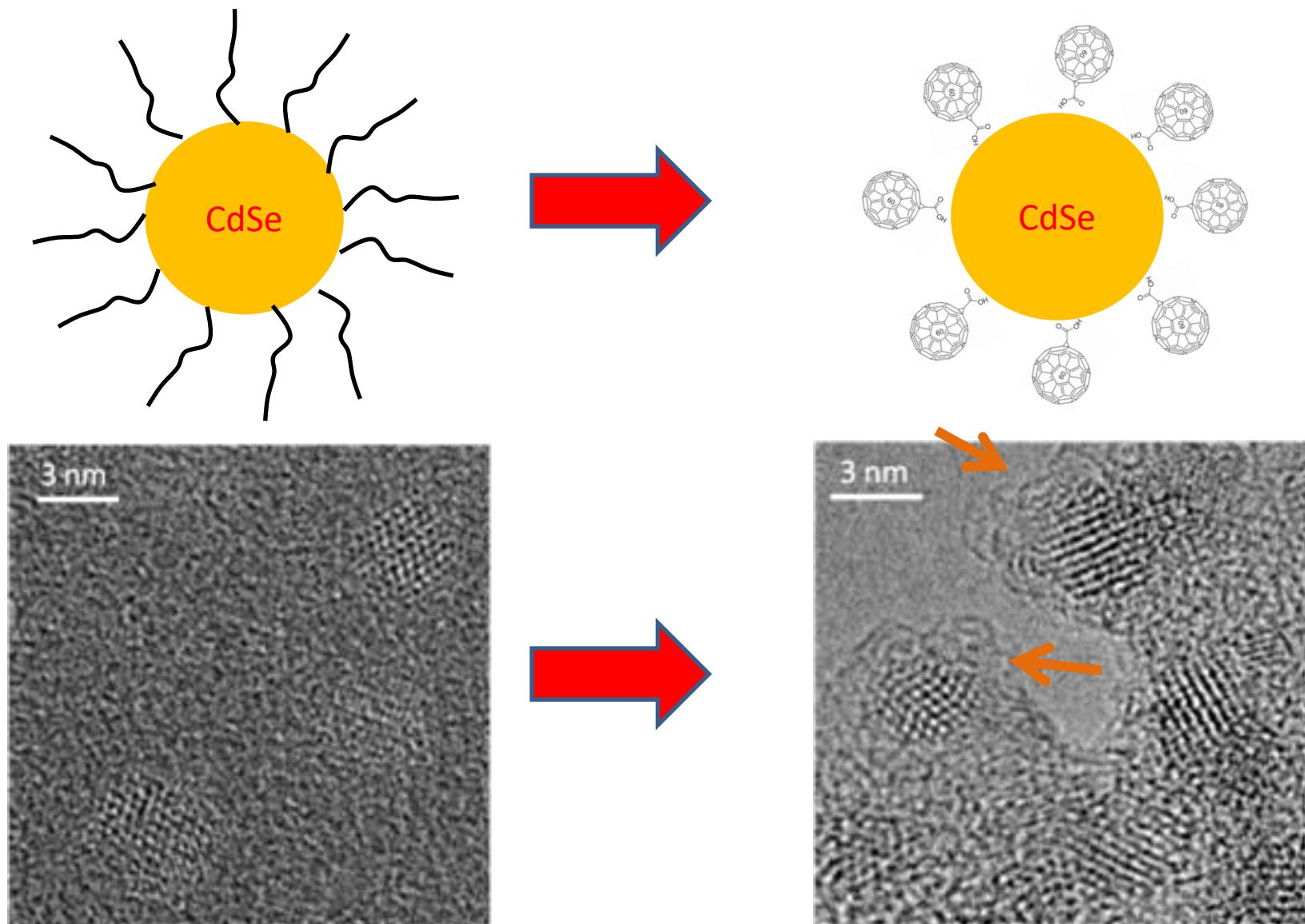
# Working principle: standard OPV cell



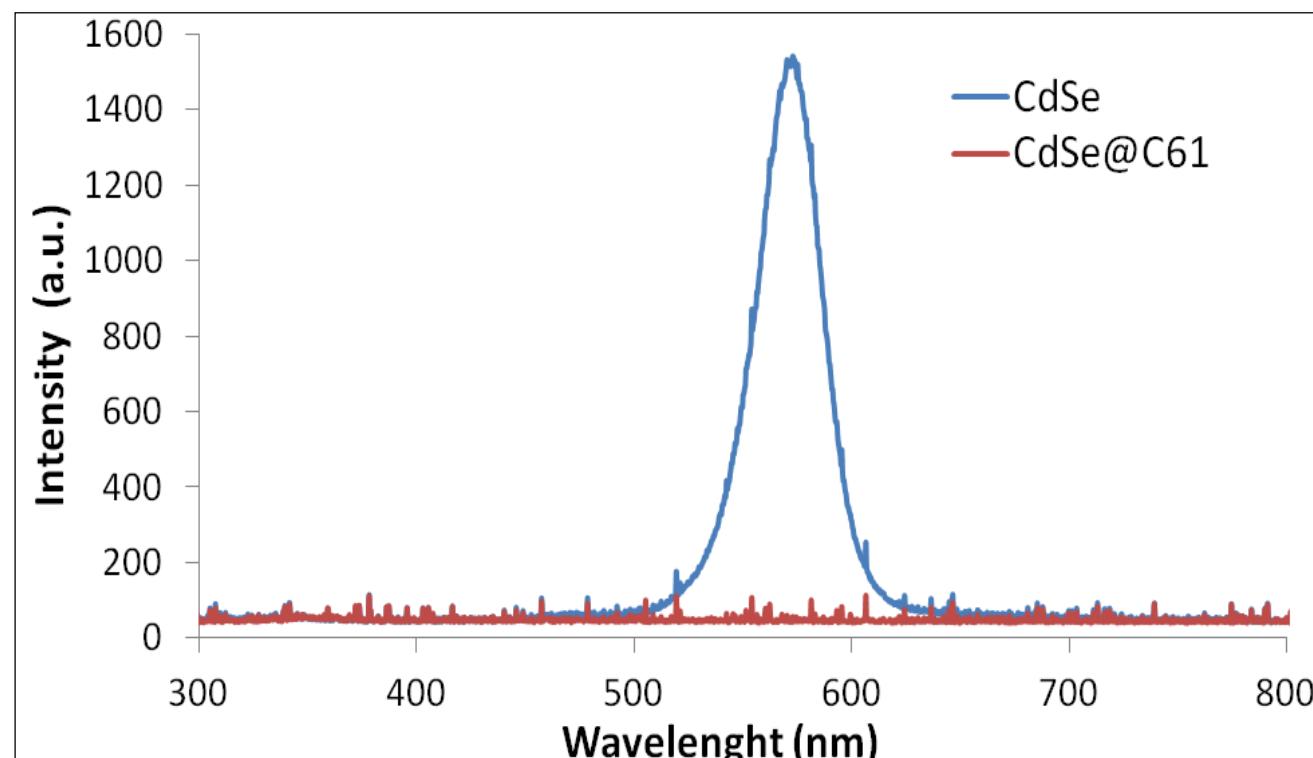
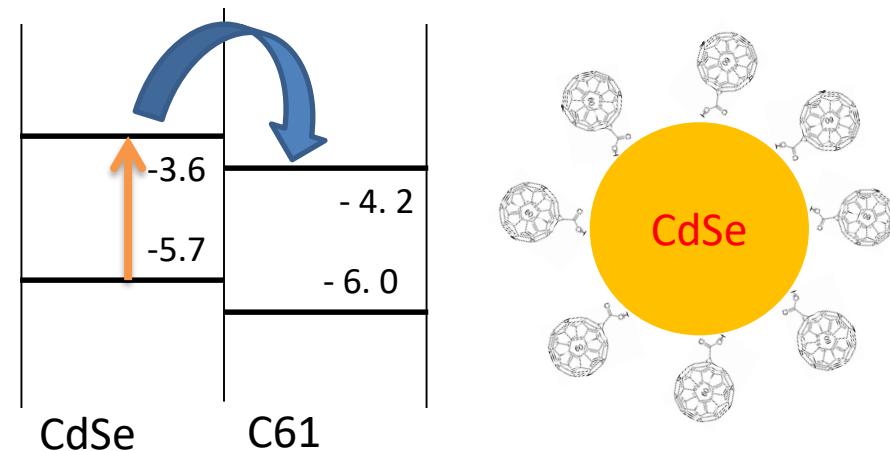
# Working principle: OPV cell with CdSe@C60



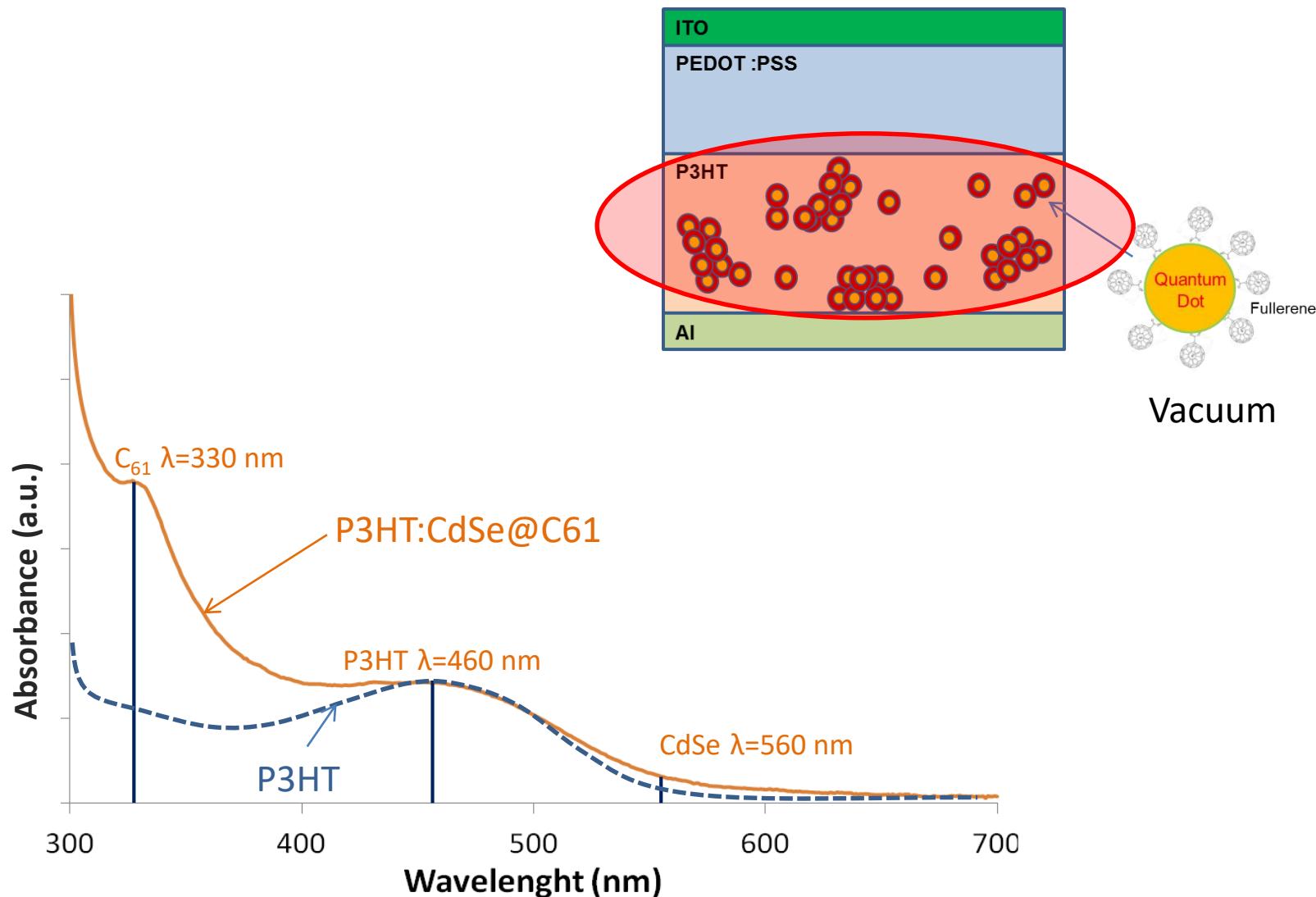
# CdSe@C<sub>6</sub>: Synthesis via Capping Exchange



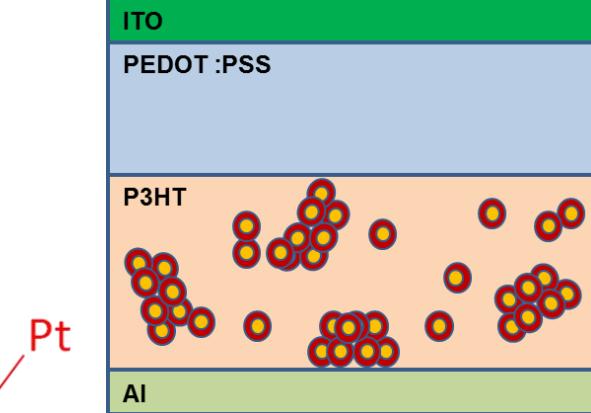
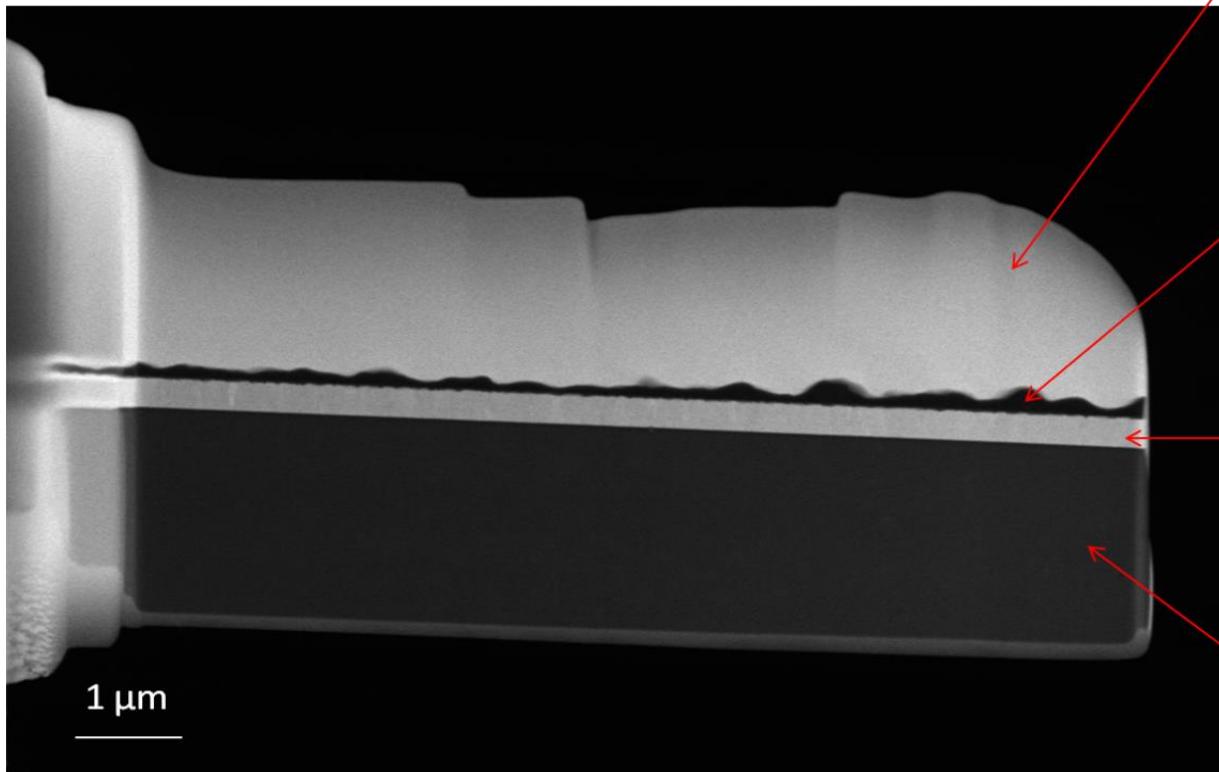
# Photoluminescence Quenching in CdSe@C61



# Absorption of P3HT:CdSe@C61 blend

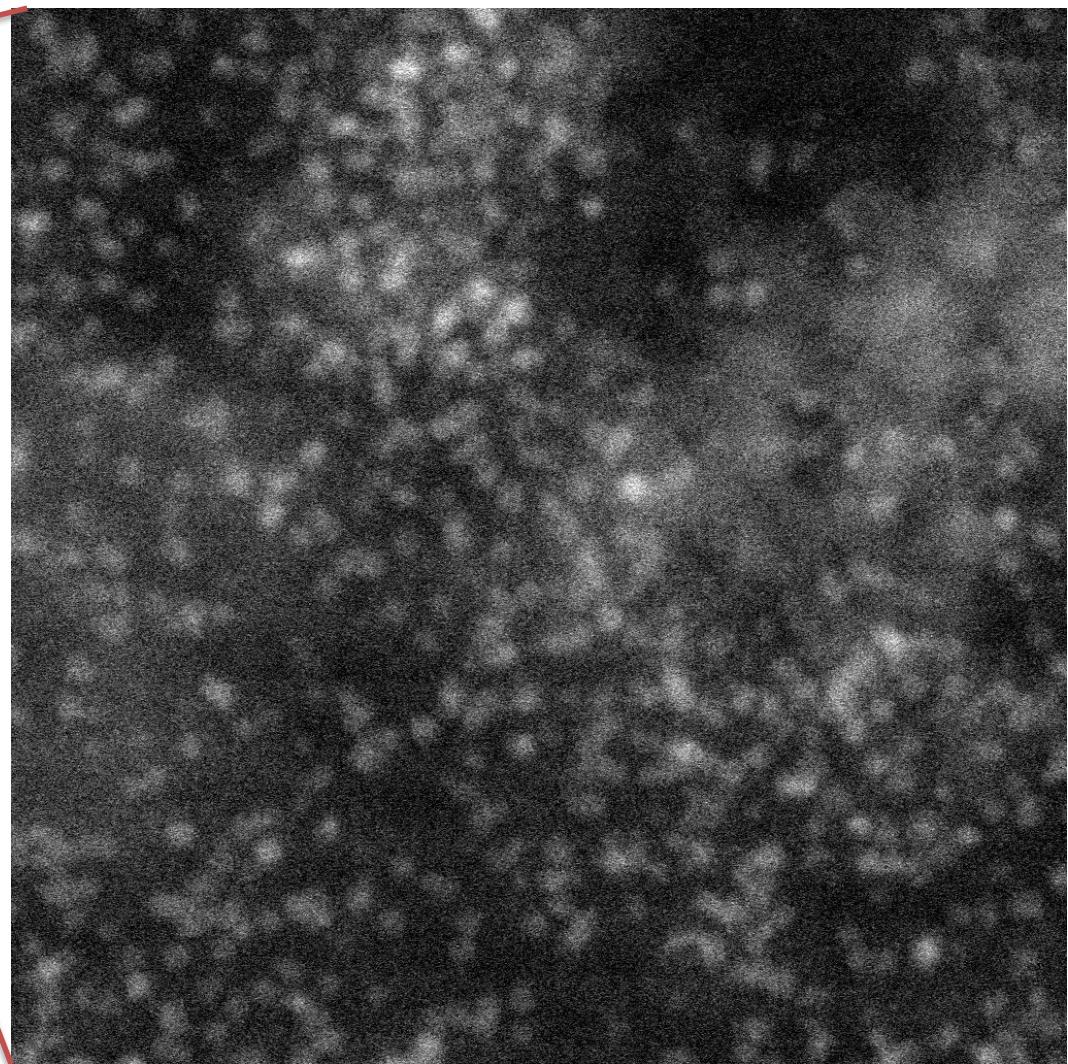
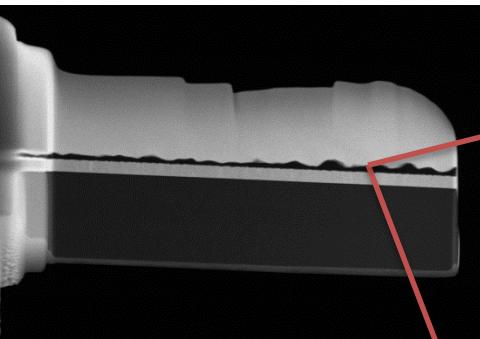


# Photovoltaic device



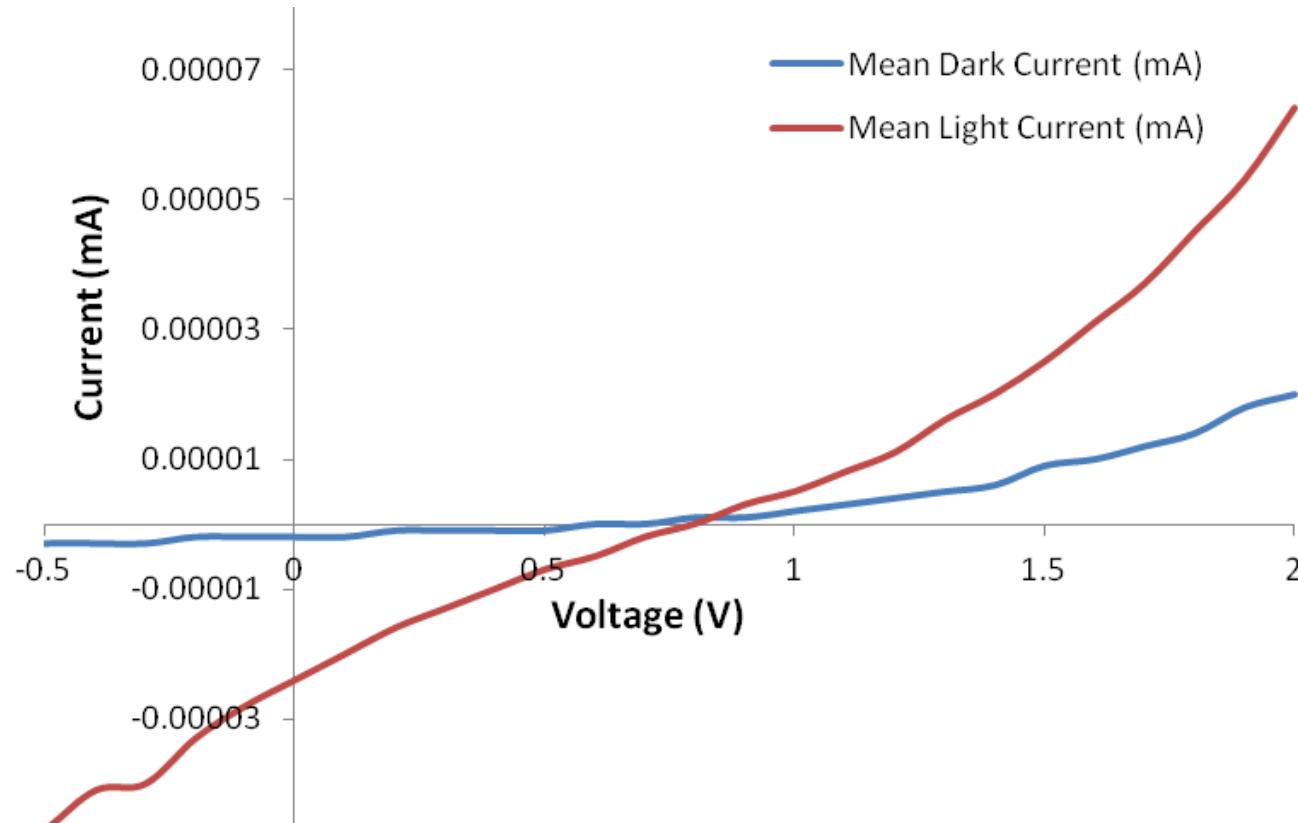
ITO	300 nm +- 3nm
TiO <sub>2</sub>	20 nm +- 2nm
Blend	140 nm +- 44 nm

# P3HT:CdSe@C61 blend



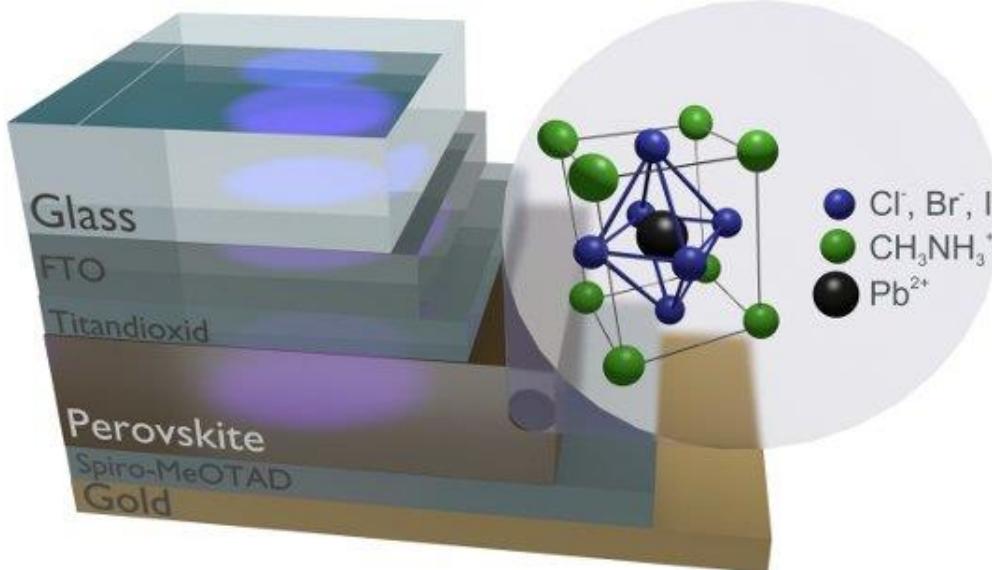
**GOOD DISPERSION !!!**

# I-V Characteristic

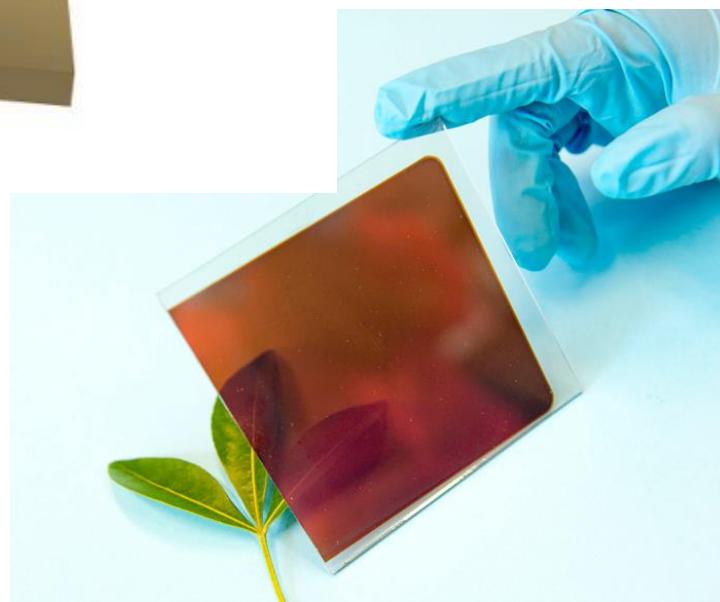


$V_{oc} \sim 0.8 \text{ V}$

# The latest frontier Perovskite-based solar cells



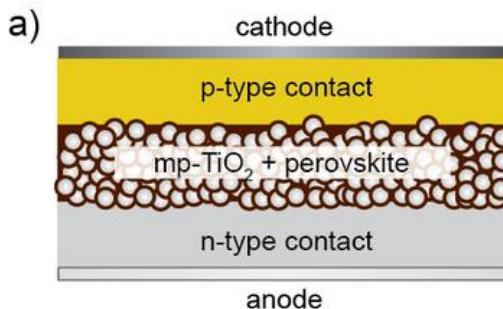
- Most promising thin film technology (high efficiency)
- Cheap, high-throughput manufacturing



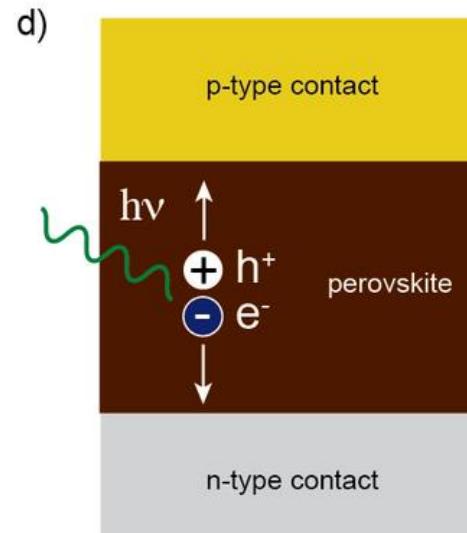
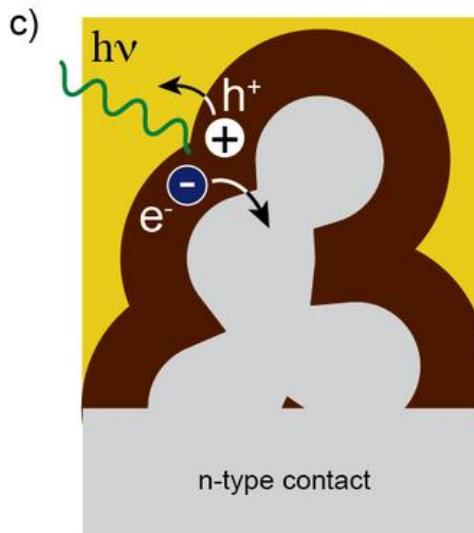
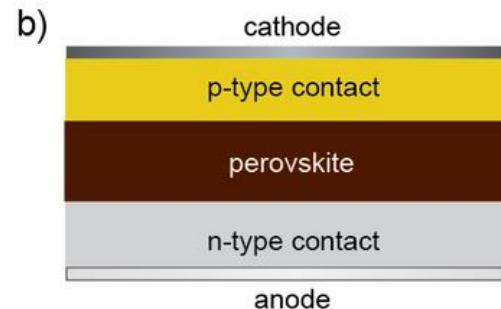
# The latest frontier

## Perovskite-based solar cells

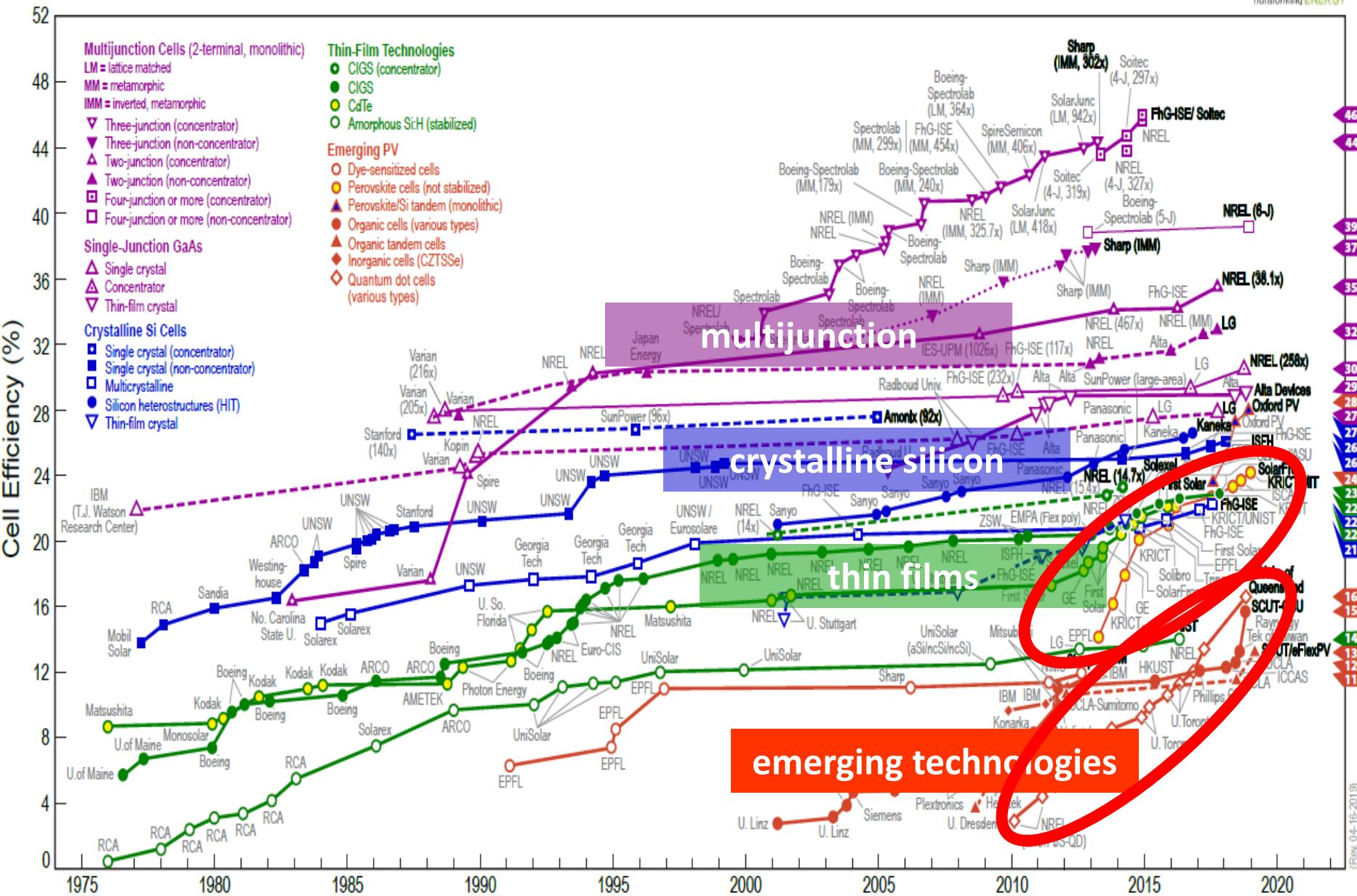
Sensitized perovskite  
solar cell



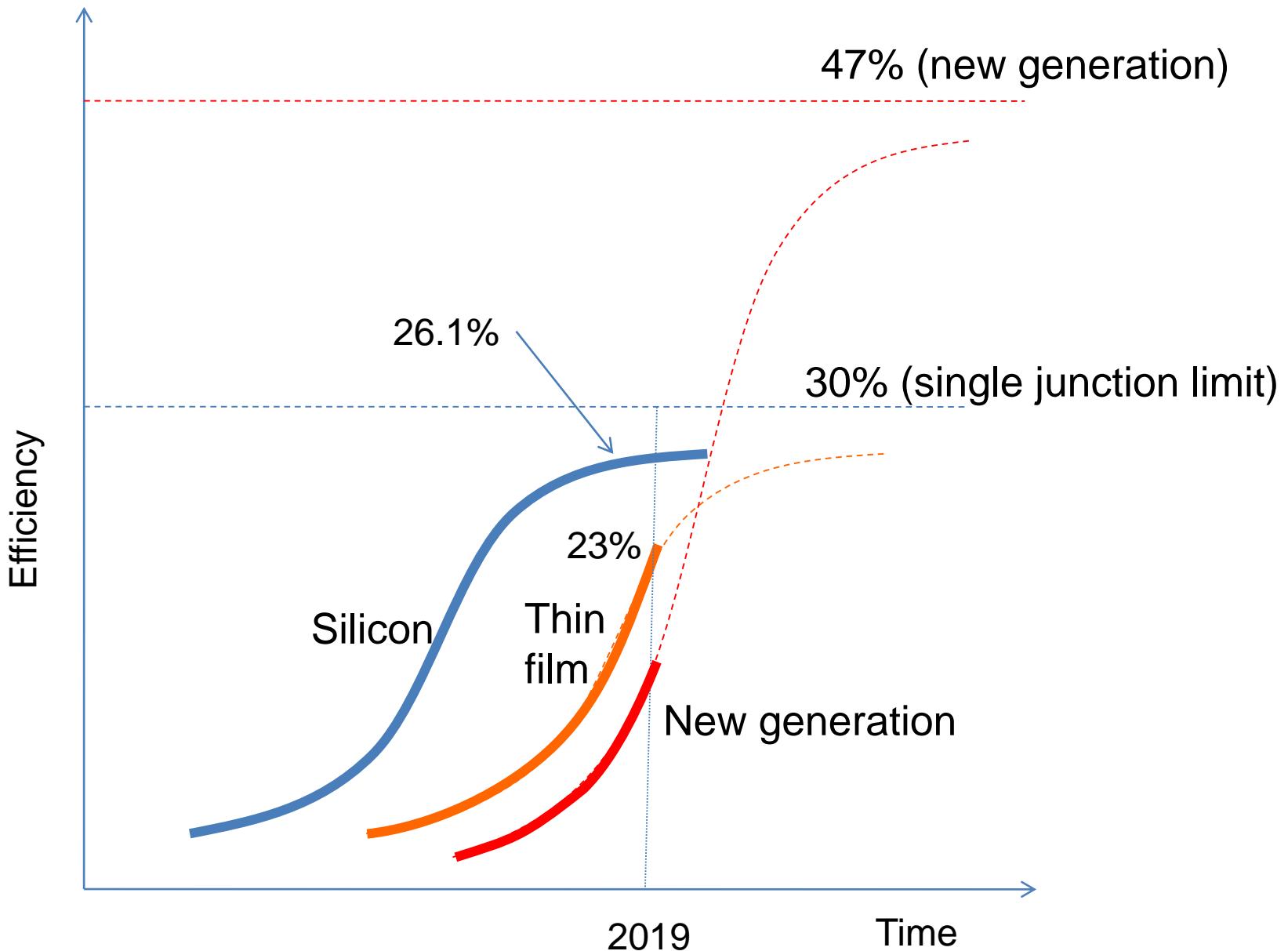
Thin-film perovskite  
solar cell



# Best Research-Cell Efficiencies

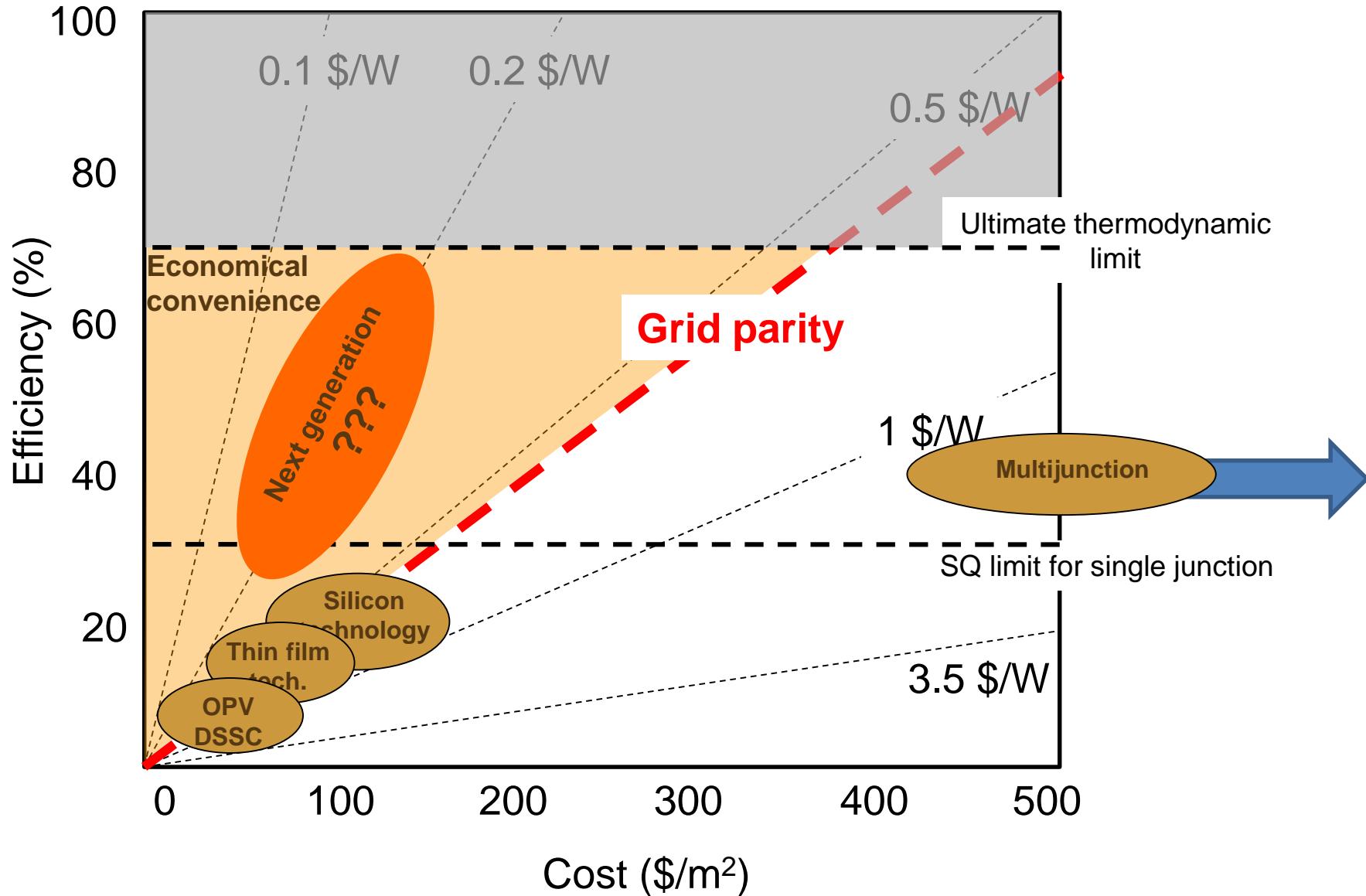


# Enhancement potential



# Next-generation solar cells

## - Techno-economic positioning -



# Concluding Remarks

- The cost reduction of the PV-kWh enabled attainment of grid parity in many Countries
- Most of the cost reduction has been driven by the economies of scale
- Nevertheless, technological innovation and breakthroughs are still important
- Current technologies have shown incremental, marginal improvements
- «Emerging» technologies such as Organic PV and DSSC need to prove robustness. They will hardly play a role in power generation
- The newest technologies (perovskites, quantum dot-based) have the chance to be a real breakthrough by combining high efficiency and extremely low cost